

Technical Data

System Basis Chip with CAN High Speed and LIN Interface

The 34903/4/5 is the second generation family of the System Basis Chip (SBC). It combines several features and enhances present module designs. The device works as an advanced power management unit for the MCU with additional integrated circuits such as sensors and CAN transceivers. It has a built-in enhanced high-speed CAN interface (ISO11898-2 and -5) with local and bus failure diagnostics, protection, and fail-safe operation modes. The SBC may include zero or one LIN 2.1 interface with LIN output pin switches. It includes up to four wake-up input pins that can also be configured as output drivers for flexibility. This device is powered by SMARTMOS technology.

This device implements multiple Low-power (LP) modes, with very low-current consumption. In addition, the device is part of a family concept where pin compatibility adds versatility to module design.

The 34903/4/5 also implements an innovative and advanced fail-safe state machine and concept solution.

Features

- Voltage regulator for MCU, 5.0 or 3.3 V, part number selectable, with possibility of usage external PNP to extend current capability and share power dissipation
- Voltage, current, and temperature protection
- · Extremely low quiescent current in LP modes
- · Fully-protected embedded 5.0 V regulator for the CAN driver
- Multiple undervoltage detections to address various MCU specifications and system operation modes (i.e. cranking)
- Auxiliary 5.0 or 3.3 V SPI configurable regulator, for additional ICs, with overcurrent detection and undervoltage protection
- MUX output pin for device internal analog signal monitoring and power supply monitoring
- Advanced SPI, MCU, ECU power supply, and critical pins diagnostics and monitoring.
- Multiple wake-up sources in LP modes: CAN or LIN bus, I/O transition, automatic timer, SPI message, and $\rm V_{\rm DD}$ overcurrent detection.
- ISO11898-5 high-speed CAN interface compatibility for baud rates of 40 kb/s to 1.0 Mb/s
- Scalable product family of devices ranging from 0 to 1 LIN, compatible to J2602-2 and LIN 2.1

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√RoHS

34903/4/5 Industrial

SYSTEM BASIS CHIP



Applications

- Industrial process control
- Automation
- Motor control
- Robotics

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SIMPLIFIED APPLICATION DIAGRAMS

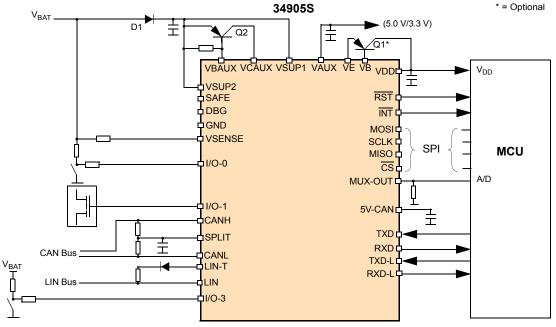


Figure 1. 34905S Simplified Application Diagram

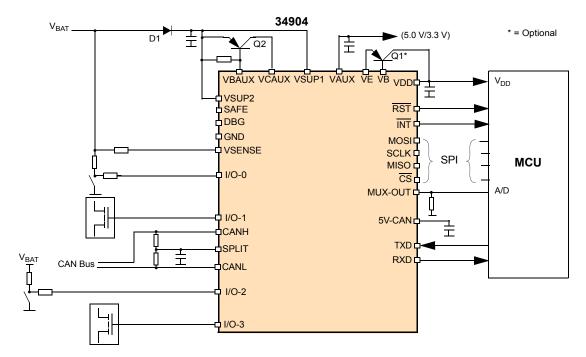
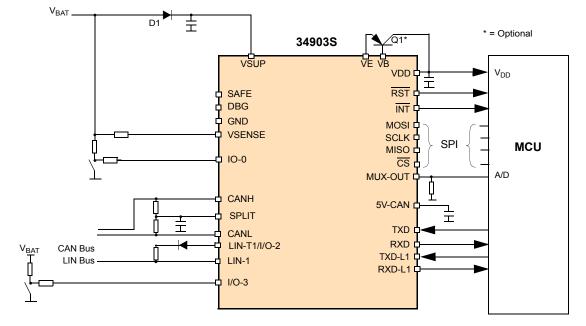


Figure 2. 34904 Simplified Application Diagram







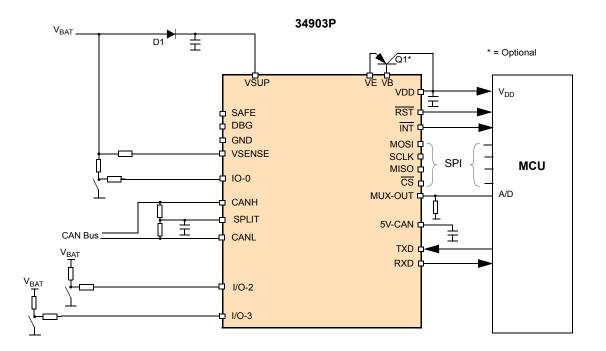


Figure 4. 34903P Simplified Application Diagram



DEVICE VARIATIONS

Table 1. MC34905 Device Variations - (All devices rated at T_A = -40 TO 125 °C)

Freescale Part Number	Version	V _{DD} Output Voltage	LIN Interface(s)	Wake-up Input / LIN Master Termination	Package	V _{AUX}	V _{SENSE}	MUX
MC34905S (Single LIN)								
MC34905CS3EK/R2	С	3.3 V		3 Wake-up + 1 LIN terms	SOIC 32 pin			
MC34905CS5EK/R2	С	5.0 V	1	or 4 Wake-up + no LIN terms	exposed pad	Yes	Yes	Yes

Table 2. MC34904 Device Variations - (All devices rated at $T_{\textrm{A}}$ = -40 TO 125 °C)

Freescale Part Number Version		sion V _{DD} Output LIN Wake-up Input / LIN Master Voltage Interface(s) Termination		Package	V _{AUX}	V _{SENSE}	MUX	
MC34904								
MC34904C3EK/R2	С	3.3 V	0	4 Wake up	SOIC 32 pin	Yes	Yes	Yes
MC34904C5EK/R2	С	5.0 V	U	4 Wake-up	exposed pad			162

Table 3. MC34903 Device Variations - (All devices rated at $T_{\rm A}$ = -40 TO 125 °C)

Freescale Part Number	Version	V _{DD} Output Voltage	LIN Interface(s)			V _{AUX}	V _{SENSE}	MUX		
MC34903S (Single LIN)										
MC34903CS3EK/R2	С	3.3 V				2 Wake-up + 1 LIN terms	SOIC 32 pin			
MC34903CS5EK/R2	С	5.0 V	1	or 3 Wake-up + no LIN terms	exposed pad	No	Yes	Yes		
MC34903P										
MC34903CP5EK/R2	0.0 V				SOIC 32 pin	No	Vaa	Vaa		
MC34903CP3EK/R2	С	3.3 V	0	3 Wake-up	exposed pad	INO	Yes	Yes		



INTERNAL BLOCK DIAGRAMS

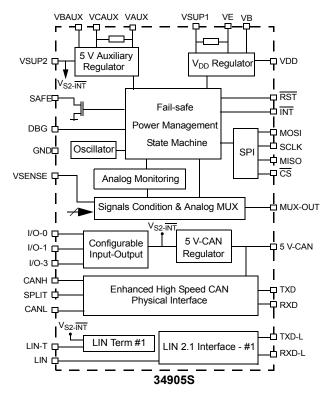


Figure 5. 34905 Internal Block Diagram

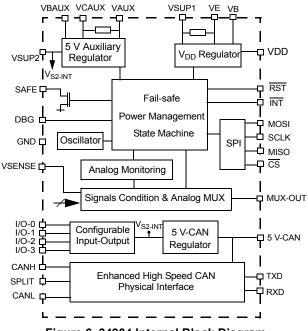


Figure 6. 34904 Internal Block Diagram



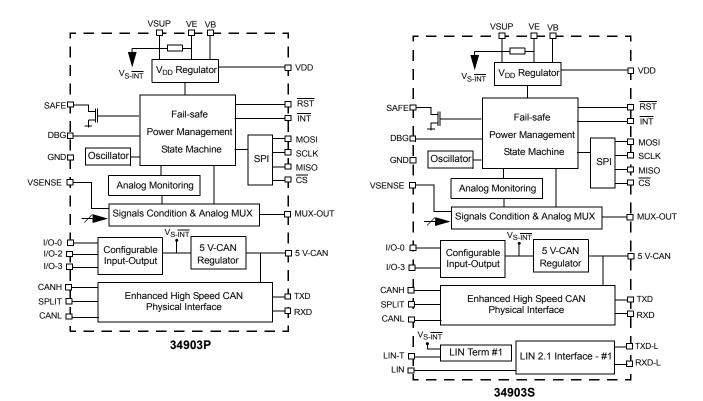
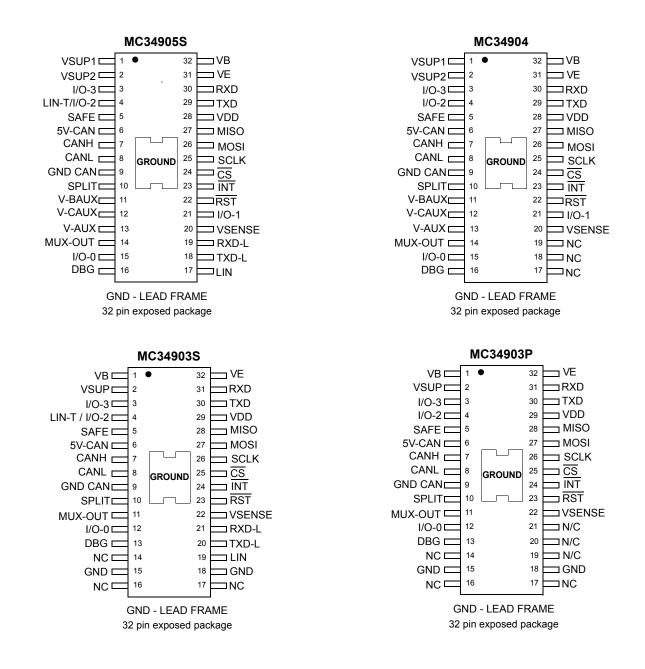


Figure 7. 34903 Internal Block Diagram



PIN CONNECTIONS



Note: MC34905D, MC34905S, MC34904 and MC34903 are footprint compatible,

Figure 8. MC34905S, MC34904 and MC34903 Pin Connections



PIN DEFINITIONS

A functional description of each pin can be found in the Functional Pin Description section beginning on page 31.

	Table 4.	34903/4/5 Pin Definitions
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32 Pin 34905S	32 Pin 34904	32 Pin 34903S	32 Pin 34903P	Pin Name	Pin Function	Formal Name	Definition		
N/A	17, 18, 19	N/A	N/A	N/C	No Connect	-	Connect to GND.		
N/A	N/A	14, 16, 17	14, 16, 17, 19- 21	N/C	No Connect		Do NOT connect the N/C pins to GND. Leave these pins Open.		
1	1	2	2	VSUP/1	Power	Battery Voltage Supply 1	Supply input for the device internal supplies, power on reset circuitry and the V_{DD} regulator. VSUP and VSUP1 supplies are internally connected on part number MC34903BDEK and MC34903BSEK		
2	2	N/A	N/A	VSUP2	Power	Battery Voltage Supply 2	Supply input for 5 V-CAN regulator, V_{AUX} regulator, I/O and LIN pins. VSUP1 and VSUP2 supplies are internally connected on part number MC34903BDEK and MC34903BSEK		
3	3	3	3	I/O-3	Output or Input/ Output	LIN Termination 2 or Input/Output 3	as a programmable Wake-up input in (LP) mode. When used a HS, no overtemperature protection is implemented. A basic		
4	4	4	4	LIN-T1 or LIN-T or I/O-2	Output or Input/ Output	LIN Termination 1 or Input/Output 2	Configurable pin as an input or HS output, for connection to external circuitry (switched or small load). The input can be used as a programmable Wake-up input in (LP) mode. When used as a HS, no overtemperature protection is implemented. A basic short to GND protection function, based on switch drain-source overvoltage detection, is available.		
5	5	5	5	SAFE	Output	Safe Output (Active LOW)	Output of the safe circuitry. The pin is asserted LOW if a fault event occurs (e.g.: software watchdog is not triggered, V_{DD} low, issue on the RST pin, etc.). Open drain structure.		
6	6	6	6	5 V-CAN	Output	5V-CAN	Output voltage for the embedded CAN interface. A capacitor must be connected to this pin.		
7	7	7	7	CANH	Output	CAN High	CAN high output.		
8	8	8	8	CANL	Output	CAN Low	CAN low output.		
9	9	9	9	GND-CAN	Ground	GND-CAN	Power GND of the embedded CAN interface		
10	10	10	10	SPLIT	Output	SPLIT Output	Output pin for connection to the middle point of the split CAN termination		
11	11	N/A	N/A	VBAUX	Output	VB Auxiliary	Output pin for external path PNP transistor base		
12	12	N/A	N/A	VCAUX	Output	VCOLLECT OR Auxiliary	Output pin for external path PNP transistor collector		
13	13	N/A	N/A	VAUX	Output	VOUT Auxiliary	Output pin for the auxiliary voltage.		
14	14	11	11	MUX-OUT	Output	Multiplex Output	Multiplexed output to be connected to an MCU A/D input. Selection of the analog parameter available at MUX-OUT is done via the SPI. A switchable internal pull-down resistor is integrated for V_{DD} current sense measurements.		



Table 4. 34903/4/5 Pin Definitions (continued)

32 Pin 34905S	32 Pin 34904	32 Pin 34903S	32 Pin 34903P	Pin Name	Pin Function	Formal Name	Definition		
15	15	12	12	I/O-0	Input/ Output	Input/Output 0	Configurable pin as an input or output, for connection to exter circuitry (switched or small load). The voltage level can be re by the SPI and via the MUX output pin. The input can be use a programmable Wake-up input in LP mode. In LP, when use an output, the High Side (HS) or Low Side (LS) can be active for a cyclic sense function.		
16	16	13	13	DBG	Input	Debug	Input to activate the Debug mode. In Debug mode, no watcher refresh is necessary. Outside of Debug mode, connection of resistor between DBG and GND allows the selection of Safe mode functionality.		
N/A	N/A	15, 18	15, 18	GND	Ground	Ground	Ground of the IC.		
17	N/A	19	N/A	LIN	Input/ Output	LIN bus	LIN bus input output connected to the LIN bus.		
18	N/A	20	N/A	TXD-L	Input	LIN Transmit Data	LIN bus transmit data input. Includes an internal pull-up resistor to VDD.		
19	N/A	21	N/A	RXD-L	Output	LIN Receive Data	LIN bus receive data output.		
20	20	22	22	VSENSE	Input	Sense input	Direct battery voltage input sense. A serial resistor is required to limit the input current during high voltage transients.		
21	21	N/A	N/A	I/O-1	Input/ Output	Input Output 1	Configurable pin as an input or output, for connection to external circuitry (switched or small load). The voltage level can be read by the SPI and the MUX output pin. The input can be used as a programmable Wake-up input in (LP) mode. It can be used in association with I/O-0 for a cyclic sense function in (LP) mode.		
22	22	23	23	RST	Output	Reset Output (Active LOW)	This is the device reset output whose main function is to reset the MCU. This pin has an internal pull-up to VDD. The reset input voltage is also monitored in order to detect external reset and safe conditions.		
23	23	24	24	INT	Output	Interrupt Output (Active LOW)	This output is asserted low when an enabled interrupt condition occurs. This pin is an open drain structure with an internal pull up resistor to VDD.		
24	24	25	25	CS	Input	Chip Select (Active LOW)	Chip select pin for the SPI. When the \overline{CS} is low, the device is selected. In (LP) mode with V _{DD} ON, a transition on \overline{CS} is a Wake-up condition		
25	25	26	26	SCLK	Input	Serial Data Clock	Clock input for the Serial Peripheral Interface (SPI) of the device		
26	26	27	27	MOSI	Input	Master Out/ Slave In	SPI data received by the device		
27	27	28	28	MISO	Output	Master In/ Slave Out	SPI data sent to the MCU. When the $\overline{\text{CS}}$ is high, MISO is high-impedance		
28	28	29	29	VDD	Output	Voltage Digital Drain	5.0 or 3.3 V output pin of the main regulator for the Microcontroller supply.		
29	29	30	30	TXD	Input	Transmit Data	CAN bus transmit data input. Internal pull-up to VDD		
30	30	31	31	RXD	Output	Receive Data	CAN bus receive data output		
31	31	32	32	VE		Voltage Emitter	Connection to the external PNP path transistor. This is an intermediate current supply source for the V_{DD} regulator		



Table 4. 34903/4/5 Pin Definitions (continued)

	32 Pin 34904				Pin Function	Formal Name	Definition
32	32	1	1	VB	Output	Voltage Base	Base output pin for connection to the external PNP pass transistor
EX PAD	EX PAD	EX PAD	EX PAD	GND	Ground	Ground	Ground



ELECTRICAL CHARACTERISTICS

MAXIMUM RATINGS

Table 5. Maximum Ratings

All voltages are referenced to ground unless otherwise noted. Exceeding these ratings may cause a malfunction or permanent damage to the device.

Ratings	Symbol	Value	Unit
ELECTRICAL RATINGS ⁽¹⁾			I
Supply Voltage at VSUP/1 and VSUP2			V
Normal Operation (DC)	V _{SUP1/2}	-0.3 to 28	
Transient Conditions (Load Dump)	V _{SUP1/2TR}	-0.3 to 40	
DC voltage on LIN/1			V
Normal Operation (DC)	V _{BUSLIN}	-28 to 28	
Transient Conditions (Load Dump)	V _{BUSLINTR}	-28 to 40	
DC voltage on CANL, CANH, SPLIT			V
Normal Operation (DC)	V _{BUS}	-28 to 28	
Transient Conditions (Load Dump)	V _{BUSTR}	-32 to 40	
DC Voltage at SAFE			V
Normal Operation (DC)	V _{SAFE}	-0.3 to 28	
Transient Conditions (Load Dump)	V _{SAFETR}	-0.3 to 40	
DC Voltage at I/O-0, I/O-1, I/O-2, I/O-3 (LIN-T Pins)			V
Normal Operation (DC)	V _{I/O}	-0.3 to 28	
Transient Conditions (Load Dump)	V _{I/OTR}	-0.3 to 40	
DC voltage on TXD-L, TXD-L1, RXD-L, RXD-L1	V _{DIGLIN}	-0.3 to V _{DD} +0.3	V
DC voltage on TXD, RXD ⁽³⁾	V _{DIG}	-0.3 to V _{DD} +0.3	V
DC Voltage at INT	VINT	-0.3 to 10	V
DC Voltage at RST	V _{RST}	-0.3 to V _{DD} +0.3	V
DC Voltage at MOSI, MSIO, SCLK and CS	V _{RST}	-0.3 to V _{DD} +0.3	V
DC Voltage at MUX-OUT	V _{MUX}	-0.3 to V _{DD} +0.3	V
DC Voltage at DBG	V _{DBG}	-0.3 to 10	V
Continuous current on CANH and CANL	ILH	200	mA
DC voltage at VDD, 5V-CAN, VAUX, VCAUX	V _{REG}	-0.3 to 5.5	V
DC voltage at VBASE ⁽²⁾ and VBAUX	V _{REG}	-0.3 to 40	V
DC voltage at VE ⁽³⁾	VE	-0.3 to 40	V
DC voltage at VSENSE	V _{SENSE}	-28 to 40	V

Notes

1. The voltage on non-VSUP pins should never exceed the V_{SUP} voltage at any time or permanent damage to the device may occur.

 If the voltage delta between VSUP/1/2 and VBASE is greater than 6.0 V, the external V_{DD} ballast current sharing functionality may be damaged.

3. Potential Electrical Over Stress (EOS) damage may occur if RXD is in contact with VE while the device is ON.



Table 5. Maximum Ratings (continued)

All voltages are referenced to ground unless otherwise noted. Exceeding these ratings may cause a malfunction or permanent damage to the device.

Ratings	Symbol	Value	Unit
ESD Capability			V
AECQ100 ⁽⁴⁾			
Human Body Model - JESD22/A114 (C_{ZAP} = 100 pF, R_{ZAP} = 1500 Ω) CANH and CANL. LIN1 Pins versus all GND pins all other Pins including CANH and CANL Charge Device Model - JESD22/C101 (C_{ZAP} = 4.0 pF) Corner Pins (Pins 1, 16, 17, and 32) All other Pins (Pins 2-15, 18-31) Tested per IEC 61000-4-2 (C_{ZAP} = 150 pF, R_{ZAP} = 330 Ω) Device unpowered, CANH and CANL pin without capacitor, versus GND Device unpowered, LIN, LIN1 pin, versus GND Device unpowered, VS1/VS2 (100 nF to GND), versus GND Tested per specific OEM EMC requirements for CAN and LIN with additional capacitor on VSUP/1/2 pins (See Typical Applications on page 85)	V _{ESD1-1} V _{ESD1-2} V _{ESD2-1} V _{ESD2-2} V _{ESD3-1} V _{ESD3-2} V _{ESD3-3}	$\pm 8000 \pm 2000 \pm 750 \pm 500 \pm 15000 \pm 15000 \pm 15000$	
CANH, CANL without bus filter LIN, LIN1 with and without bus filter I/O with external components (22 k - 10 nF)	V _{ESD4-1} V _{ESD4-2} V _{ESD4-3}	±9000 ±12000 ±7000	

THERMAL RATINGS

Junction temperature ⁽⁵⁾	TJ	150	°C
Ambient temperature	T _A	-40 to 125	°C
Storage temperature	T _{ST}	-50 to 150	°C
THERMAL RESISTANCE	·		

Thermal resistance junction to ambient ⁽⁸⁾	$R_{ extsf{ heta}JA}$	50 ⁽⁸⁾	°C/W
Peak package reflow temperature during reflow ^{(6), (7)}	T _{PPRT}	Note 7	°C

Notes

4. ESD testing is performed in accordance with the Human Body Model (HBM) (C_{ZAP} = 100 pF, R_{ZAP} = 1500 Ω), the Charge Device Model (CDM), and Robotic (C_{ZAP} = 4.0 pF).

5. To achieve high reliability over 10 years of continuous operation, the device's continuous operating junction temperature should not exceed 125 °C.

6. Pin soldering temperature limit is for 10 seconds maximum duration. Not designed for immersion soldering. Exceeding these limits may cause malfunction or permanent damage to the device.

7. Freescale's Package Reflow capability meets Pb-free requirements for JEDEC standard J-STD-020C. For Peak Package Reflow Temperature and Moisture Sensitivity Levels (MSL), Go to www.freescale.com, search by part number [e.g. remove prefixes/suffixes and enter the core ID to view all orderable parts. (i.e. MC34xxxD enter 34xxx), and review parametrics.

8. This parameter was measured according to Figure 9:



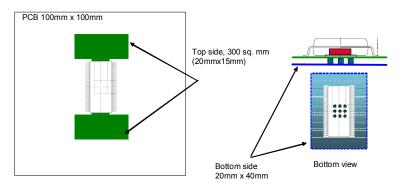


Figure 9. PCB with Top and Bottom Layer Dissipation Area (Dual Layer)



STATIC ELECTRICAL CHARACTERISTICS

Table 6. Static Electrical Characteristics

Characteristics noted under conditions 5.5 V \leq V_{SUP} \leq 28 V, -40 °C \leq T_A \leq 125 °C, unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25 °C under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Тур	Max	Unit
POWER INPUT	1		I	L	1
Nominal DC Voltage Range ⁽⁹⁾	V _{SUP1} /V _{SUP2}	5.5	-	28	V
Extended DC Low Voltage Range ⁽¹⁰⁾	V _{SUP1} /V _{SUP2}	4.0	-	5.5	V
Undervoltage Detector Thresholds, at the VSUP/1 pin,	V _{S1_LOW}				V
Low threshold (VSUP/1 ramp down) High threshold (VSUP/1 ramp up) Hysteresis		5.5 - 0.2	6.0 - 0.35	6.5 6.6 0.5	
Note: function not active in LP mode					
Undervoltage Detector Thresholds, at the VSUP2 pin:	V _{S2_LOW}				V
Low threshold (VSUP2 ramp down) High threshold (VSUP2 ramp up) Hysteresis Note: function not active in LP modes		5.5 - 0.2	6.0 - 0.35	6.5 6.6 0.5	
V_{SUP} Overvoltage Detector Thresholds, at the VSUP/1 pin:	N/	16 5	17	10 5	V
Not active in LP modes	V _{S_HIGH}	16.5	17	18.5	v
Battery loss detection threshold, at the VSUP/1 pin.	BATFAIL	2.0	2.8	4.0	V
VSUP/1 to turn V _{DD} ON, VSUP/1 rising	V _{SUP-TH1}	-	4.1	4.5	V
VSUP/1 to turn V _{DD} ON, hysteresis (Guaranteed by design)	V _{SUP-TH1HYST}	150	180		mV
Supply current ⁽¹¹⁾ , ⁽¹²⁾	I _{SUP1}				mA
- from VSUP/1 - from VSUP2, (5V-CAN V _{AUX} , I/O OFF)		-	2.0 0.05	4.0 0.85	
Supply current, I _{SUP1} + I _{SUP2} , Normal mode, V _{DD} ON - 5 V-CAN OFF, V _{AUX} OFF - 5 V-CAN ON, CAN interface in Sleep mode, V _{AUX} OFF - 5 V-CAN OFF, Vaux ON - 5 V-CAN ON, CAN interface in TXD/RXD mode, V _{AUX} OFF, I/O-x disabled	I _{SUP1+2}	- - -	2.8 - - -	4.5 5.0 5.5 8.0	mA
LP mode V _{DD} OFF. Wake-up from CAN, I/O-x inputs	I _{LPM_OFF}				μA
$V_{SUP} \le 18 \text{ V}, -40 \text{ to } 25 \text{ °C}$ $V_{SUP} \le 18 \text{ V}, 125 \text{ °C}$		-	15 -	35 50	
LP mode V _{DD} ON (5.0 V) with V _{DD} undervoltage and V _{DD} overcurrent monitoring, Wake-up from CAN, I/O-x inputs	I _{LPM_ON}	_			μΑ
$\begin{split} V_{SUP} &\leq 18 \text{ V}, -40 \text{ to } 25 \ ^\circ\text{C}, \ I_{DD} = 1.0 \ \mu\text{A} \\ V_{SUP} &\leq 18 \text{ V}, -40 \text{ to } 25 \ ^\circ\text{C}, \ I_{DD} = 100 \ \mu\text{A} \\ V_{SUP} &\leq 18 \text{ V}, \ 125 \ ^\circ\text{C}, \ I_{DD} = 100 \ \mu\text{A} \end{split}$		-	20 40 -	- 65 85	
LP mode, additional current for oscillator (used for: cyclic sense, forced Wake- up, and in LP V_{DD} ON mode cyclic interruption and watchdog)	l _{osc}				μΑ
$V_{SUP} \le 18 \text{ V}, -40 \text{ to } 125 ^\circ\text{C}$		-	5.0	9.0	
Debug mode DBG voltage range	V _{DBG}	8.0	-	10	V

Notes

9. All parameters in spec (ex: V_{DD} regulator tolerance).

10. Device functional, some parameters could be out of spec. V_{DD} is active, device is not in Reset mode if the lowest V_{DD} undervoltage reset threshold is selected (approx. 3.4 V). CAN and I/Os are not operational.

11. In Run mode, CAN interface in Sleep mode, 5 V-CAN and V_{AUX} turned OFF. I_{OUT} at V_{DD} < 50 mA. Ballast: turned OFF or not connected.

12. VSUP1 and VSUP2 supplies are internally connected on part number MC34903BDEK and MC34903BSEK. Therefore, I_{SUP1} and I_{SUP2} cannot be measured individually.

Characteristics noted under conditions 5.5 V \leq V_{SUP} \leq 28 V, -40 °C \leq T_A \leq 125 °C, unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25 °C under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Тур	Max	Unit
V _{DD} VOLTAGE REGULATOR, VDD PIN			l	l	
Output Voltage					V
V_{DD} = 5.0 V, V_{SUP} 5.5 to 28 V, I_{OUT} 0 to 150 mA	V _{OUT-5.0}	4.9	5.0	5.1	
V_{DD} = 3.3 V, V_{SUP} 5.5 to 28 V, I_{OUT} 0 to 150 mA	V _{OUT-3.3}	3.234	3.3	3.4	
Drop voltage without external PNP pass transistor ⁽¹³⁾	V _{DROP}				mV
$V_{DD} = 5.0 \text{ V}, \text{ I}_{OUT} = 100 \text{ mA}$		-	330	450	
$V_{DD} = 5.0 \text{ V}, \text{ I}_{OUT} = 150 \text{ mA}$		-	-	500	
Drop voltage with external transistor ⁽¹³⁾	V _{DROP-B}				mV
I _{OUT} = 200 mA (I_BALLAST + I_INTERNAL)		-	350	500	
VSUP/1 to maintain V_{DD} within $V_{OUT-3.3}$ specified voltage range	V _{SUP1-3.3}				V
$V_{DD} = 3.3 \text{ V}, \text{ I}_{OUT} = 150 \text{ mA}$		4.0	-	-	
V_{DD} = 3.3 V, I_{OUT} = 200 mA, external transistor implemented		4.0	-	-	
External ballast versus internal current ratio (I_BALLAST = K x Internal current)	к	1.5	2.0	2.5	
Output Current limitation, without external transistor	I _{LIM}	150	350	550	mA
Temperature pre-warning (Guaranteed by design)	T _{PW}	-	140	-	°C
Thermal shutdown (Guaranteed by design)	T _{SD}	160	-	-	°C
Range of decoupling capacitor (Guaranteed by design) ⁽¹⁴⁾	C _{EXT}	4.7	-	100	μF
LP mode V_{DD} ON, $I_{OUT} \le 50$ mA (time limited)	V _{DDLP}				V
$V_{DD} = 5.0 \text{ V}, 5.6 \text{ V} \le V_{SUP} \le 28 \text{ V}$		4.75	5.0	5.25	
$V_{DD} = 3.3 \text{ V}, 5.6 \text{ V} \le V_{SUP} \le 28 \text{ V}$		3.135	3.3	3.465	
LP mode V_{DD} ON, dynamic output current capability (Limited duration. Ref. to device description).	L _{P-IOUTDC}	-	-	50	mA
LP V _{DD} ON mode:	L _{P-ITH}				mA
Overcurrent Wake-up threshold.		1.0	3.0	-	
Hysteresis		0.1	1.0	-	
LP mode V_{DD} ON, drop voltage, at I_{OUT} = 30 mA (Limited duration. Ref. to device description) $^{\rm (13)}$	L _{P-VDROP}	-	200	400	mV
LP mode V_{DD} ON, min V_{SUP} operation (Below this value, a $V_{DD},$ undervoltage reset may occur)	L _{P-MINVS}	5.5	-	-	V
V_{DD} when V_{SUP} < $V_{SUP-TH1},$ at I_V_DD \leq 10 μA (Guaranteed by design)	V _{DD_OFF}	-	-	0.3	V
V_{DD} when $V_{SUP} \geq V_{SUP-TH1},$ at I_V_DD \leq 40 mA (Guaranteed with parameter $V_{SUP-TH1}$	V _{DD_START} UP	3.0	-	-	V

Notes

For 3.3 V V_{DD} devices, the drop-out voltage test condition leads to a V_{SUP} below the min V_{SUP} threshold (4.0 V). As a result, the dropout voltage parameter cannot be specified.

14. The regulator is stable without an external capacitor. Usage of an external capacitor is recommended for AC performance.



Characteristics noted under conditions 5.5 V \leq V_{SUP} \leq 28 V, -40 °C \leq T_A \leq 125 °C, unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25 °C under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Тур	Мах	Unit
VOLTAGE REGULATOR FOR CAN INTERFACE SUPPLY, 5.0 V-CAN PIN	1			l	
Output voltage, V _{SUP/2} = 5.5 to 40 V					V
I _{OUT} 0 to 160 mA	5V _{-C OUT}	4.75	5.0	5.25	
Output Current limitation (15)	5V _{-C ILIM}	160	280	-	mA
Undervoltage threshold	5V _{-C UV}	4.1	4.5	4.7	V
Thermal shutdown (Guaranteed by design)	5V _{-CTS}	160	-	-	°C
External capacitance (Guaranteed by design)	C _{EXT-CAN}	1.0	-	100	μF
VAUXILIARY OUTPUT, 5.0 AND 3.3 V SELECTABLE PIN VB-AUX, VC-A	UX, VAUX				I
VAUX output voltage	V _{AUX}				V
V_{AUX} = 5.0 V, V_{SUP} = V_{SUP2} 5.5 to 40 V, I_{OUT} 0 to 150 mA		4.75	5.0	5.25	
V_{AUX} = 3.3 V, V_{SUP} = V_{SUP2} 5.5 to 40 V, I_{OUT} 0 to 150 mA		3.135	3.3	3.465	
VAUX undervoltage detector (VAUX configured to 5.0 V)	V _{AUX-UVTH}				V
Low Threshold		4.2	4.5	4.70	
Hysteresis		0.06	-	0.12	
VAUX undervoltage detector (VAUX configured to 3.3 V, default value)		2.75	3.0	3.135	
VAUX overcurrent threshold detector	V _{AUX-ILIM}				mA
V _{AUX} set to 3.3 V		250	360	450	
V _{AUX} set to 5.0 V		230	330	430	
External capacitance (Guaranteed by design)	V _{AUX CAP}	2.2	-	100	μF
UNDERVOLTAGE RESET AND RESET FUNCTION, RST PIN					I
V_{DD} undervoltage threshold down - 90% V_{DD} (V_{DD} 5.0 V) ^{(16), (18)}	V _{RST-TH1}	4.5	4.65	4.85	V
V_{DD} undervoltage threshold up - 90% V_{DD} (V_{DD} 5.0 V)		-	-	4.90	
$ m V_{DD}$ undervoltage threshold down - 90% $ m V_{DD}$ ($ m V_{DD}$ 3.3 V) ^{(16), (18)}		2.75	3.0	3.135	
V_{DD} undervoltage threshold up - 90% V_{DD} (V_{DD} 3.3 V)		-	-	3.135	
V_{DD} undervoltage reset threshold down - 70% V_{DD} (V_{DD} 5.0 V) ^{(17), (18)}	V _{RST-TH2-5}	2.95	3.2	3.45	V
Hysteresis	V _{RST-HYST}				mV
for threshold 90% V_{DD} , 5.0 V device		20	-	150	
for threshold 70% V_{DD} , 5.0 V device		10	-	150	
Hysteresis 3.3 V V _{DD}					
for threshold 90% $V_{\text{DD}},3.3$ V device		10	-	150	
V_{DD} undervoltage reset threshold down - LP V_{DD} ON mode	V _{RST-LP}		<u></u>		V
(Note: device change to Normal Request mode). V_{DD} 5.0 V	-	4.0	4.5	4.85	
(Note: device change to Normal Request mode). V _{DD} 3.3 V		2.75	3.0	3.135	

Notes

15. Current limitation will be reported by setting a flag.

16. Generate a Reset or an INT. SPI programmable

17. Generate a Reset

18. In Non-LP modes



Characteristics noted under conditions 5.5 V \leq V_{SUP} \leq 28 V, -40 °C \leq T_A \leq 125 °C, unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25 °C under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Тур	Max	Unit
UNDERVOLTAGE RESET AND RESET FUNCTION, RST PIN (CONTINUE	D)			1	
Reset V _{OL} @ 1.5 mA, V _{SUP} 5.5 to 28 V	V _{OL}	-	300	500	mV
Current limitation, Reset activated, V _{RESET} = 0.9 x V _{DD}	IRESET LOW	2.5	7.0	10	mA
Pull-up resistor (to VDD pin)	R _{PULL-UP}	8.0	11	15	kΩ
V _{SUP} to guaranteed reset low level ⁽¹⁹⁾	V _{SUP-RSTL}	2.5	-	-	V
Reset input threshold	V _{RST-VTH}				V
Low threshold, V_{DD} = 5.0 V		1.5	1.9	2.2	
High threshold, V_{DD} = 5.0 V		2.5	3.0	3.5	
Low threshold, V_{DD} = 3.3 V		0.99	1.17	1.32	
High threshold, V_{DD} = 3.3 V		1.65	2.0	2.31	
Reset input hysteresis	V _{HYST}	0.5	1.0	1.5	V
I/O PINS WHEN FUNCTION SELECTED IS OUTPUT			1		
I/O-0 HS switch drop @ I = -12 mA, V_{SUP} = 10.5 V	VI/O-0 HSDRP	-	0.5	1.4	V
I/O-2 and I/O-3 HS switch drop @ I = -20 mA, V_{SUP} = 10.5 V	VI/O-2-3 HSDRP	-	0.5	1.4	V
I/O-1, HS switch drop @ I = -400 μ A, V _{SUP} = 10.5 V	V _{I/O-1 HSDRP}	-	0.4	1.4	V
I/O-0, I/O-1 LS switch drop @ I = 400 μ A, V _{SUP} = 10.5 V	VI/O-01 LSDRP	-	0.4	1.4	V
Leakage current, I/O-x \leq V _{SUP}	I _{I/O_LEAK}	-	0.1	3.0	μA
I/O PINS WHEN FUNCTION SELECTED IS INPUT				I	
Negative threshold	V _{I/O_NTH}	1.4	2.0	2.9	V
Positive threshold	V _{I/O_PTH}	2.1	3.0	3.8	V
Hysteresis	V _{I/O_HYST}	0.2	1.0	1.4	V
Input current, I/O \leq VSUP/2		-5.0	1.0	5.0	μA
I/O-0 and I/O-1 input resistor. I/O-0 (or I/O-1) selected in	R _{I/O-X}	-	100	-	kΩ
register, 2.0 V < $V_{I/O-X}$ <16 V (Guaranteed by design).	<i></i>				
VSENSE INPUT	I I				
VSENSE undervoltage threshold (Not active in LP modes)	V _{SENSE_TH}				V
Low Threshold		8.1	8.6	9.0	
High threshold		-	-	9.1	
Hysteresis		0.1	0.25	0.5	
Input resistor to GND. In all modes except in LP modes. (Guaranteed by design).	R _{VSENSE}	-	125	-	kΩ

Notes

19. Reset must be kept low



Characteristics noted under conditions 5.5 V \leq V_{SUP} \leq 28 V, -40 °C \leq T_A \leq 125 °C, unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25 °C under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Тур	Мах	Unit
ANALOG MUX OUTPUT					
Output Voltage Range, with external resistor to GND >2.0 k Ω	V _{OUT_MAX}	0.0	-	V _{DD} - 0.5	V
Internal pull-down resistor for regulator output current sense	R _{MI}	0.8	1.9	2.8	kΩ
External capacitor at MUX OUTPUT ⁽²⁰⁾ (Guaranteed by design)	C _{MUX}	-	-	1.0	nF
Chip temperature sensor coefficient (Guaranteed by design and device characterization)	TEMP _{-COEFF}				mv/°(
V _{DD} = 5.0 V		20	21	22	
V _{DD} = 3.3 V		13.2	13.9	14.6	
Chip temperature: MUX-OUT voltage	V _{TEMP}				V
V _{DD} = 5.0 V, T _A = 125 °C		3.6	3.75	3.9	
V _{DD} = 3.3 V, T _A = 125 °C		2.45	2.58	2.65	
Chip temperature: MUX-OUT voltage (guaranteed by design and characterization)	V _{TEMP(GD)}				V
T _A = -40 °C, V _{DD} = 5.0 V		0.12	0.30	0.48	
T _A = 25 °C, V _{DD} = 5.0 V		1.5	1.65	1.8	
T _A = -40 °C, V _{DD} = 3.3 V		0.07	0.19	0.3	
T _A = 25 °C, V _{DD} = 3.3 V		1.08	1.14	1.2	
Gain for V _{SENSE} , with external 1.0 k 1% resistor	V _{SENSE} GAIN				
$V_{DD} = 5.0 V$	SENSE -	5.42	5.48	5.54	
V _{DD} = 3.3 V		8.1	8.2	8.3	
Offset for V _{SENSE} , with external 1.0 k 1% resistor	V _{SENSE} OFFSET	-20	-	20	mV
Divider ratio for V _{SUP/1}	V _{SUP/1} RATIO				
V _{DD} = 5.0 V		5.335	5.5	5.665	
V _{DD} = 3.3 V		7.95	8.18	8.45	
Attenuation/Gain ratio for I/O-0 and I/O-1 actual voltage:	VI/O RATIO				
V _{DD} = 5.0 V, I/O = 16 V (Attenuation, MUX-OUT register bit 3 set to 1)		3.8	4.0	4.2	
V _{DD} = 5.0 V, (Gain, MUX-OUT register bit 3 set to 0)		-	2.0	-	
V _{DD} = 3.3 V, I/O = 16 V (Attenuation, MUX-OUT register bit 3 set to 1)		5.6	5.8	6.2	
V _{DD} = 3.3 V, (Gain, MUX-OUT register bit 3 set to 0)		-	1.3	-	
Internal reference voltage	V _{REF}				V
V _{DD} = 5.0 V		2.45	2.5	2.55	
V _{DD} = 3.3 V		1.64	1.67	1.7	
Current ratio between VDD output & I _{OUT} at MUX-OUT	I _{DD RATIO}				
(I _{OUT} at MUX-OUT = I _{DD} out / I _{DD} RATIO)	55-10110				
At $I_{OUT} = 50 \text{ mA}$		80	97	115	
I_ _{OUT} from 25 to 150 mA		62.5	97	117	
SAFE OUTPUT			l	1	
SAFE low level, at I = 500 μA	V _{OL}	0.0	0.2	1.0	V
				1	

20. When C is higher than CMUX, a serial resistor must be inserted



Characteristics noted under conditions 5.5 V \leq V_{SUP} \leq 28 V, -40 °C \leq T_A \leq 125 °C, unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25 °C under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Тур	Мах	Unit
INTERRUPT	1	I			
Output low voltage, I _{OUT} = 1.5 mA	V _{OL}	-	0.2	1.0	V
Pull-up resistor	R _{PU}	6.5	10	14	kΩ
Output high level in LP V_{DD} ON mode (Guaranteed by design)	V _{OH-LPVDDON}	3.9	4.3		V
Leakage current INT voltage = 10 V (to allow high-voltage on MCU INT pin)	V _{MAX}	-	35	100	μA
Sink current, $V_{\overline{INT}} > 5.0 \text{ V}$, \overline{INT} low state	I _{SINK}	2.5	6.0	10	mA
MISO, MOSI, SCLK, CS PINS	1	I			
Output low voltage, I _{OUT} = 1.5 mA (MISO)	V _{OL}	-	-	1.0	V
Output high voltage, I _{OUT} = -0.25 mA (MISO)	V _{OH}	V _{DD} -0.9	-		V
Input low voltage (MOSI, SCLK, CS)	V _{IL}	-	-	0.3 x V _{DD}	V
Input high voltage (MOSI, SCLK, CS)	V _{IH}	0.7 x V _{DD}	-	-	V
Tri-state leakage current (MISO)	I _{HZ}	-2.0	-	2.0	μA
Pull-up current (CS)	I _{PU}	200	370	500	μA
CAN LOGIC INPUT PINS (TXD)	l	H			
High Level Input Voltage	V _{IH}	0.7 x V _{DD}	-	V _{DD} + 0.3	V
Low Level Input Voltage	V _{IL}	-0.3	-	0.3 x V _{DD}	V
Pull-up Current, TXD, V _{IN} = 0 V	I _{PDWN}				μA
V _{DD} =5.0 V		-850	-650	-200	
V _{DD} =3.3 V		-500	-250	-175	
CAN DATA OUTPUT PINS (RXD)	I	1 1			
Low Level Output Voltage	VOUTLOW				V
I _{RXD} = 5.0 mA		0.0	-	0.3 x V _{DD}	
High Level Output Voltage	VOUT _{HIGH}				V
I _{RX} = -3.0 mA		0.7 x V _{DD}	-	V _{DD}	
High Level Output Current	IOUT _{HIGH}				mA
$V_{RXD} = V_{DD} - 0.4 V$		2.5	5.0	9.0	
Low Level Input Current	IOUT _{LOW}				mA
$V_{RXD} = 0.4 V$	2011	2.5	5.0	9.0	



Characteristics noted under conditions 5.5 V \leq V_{SUP} \leq 28 V, -40 °C \leq T_A \leq 125 °C, unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25 °C under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Тур	Max	Unit
CAN OUTPUT PINS (CANH, CANL)	11		I		1
Bus pins common mode voltage for full functionality	V _{COM}	-12	-	12	V
Differential input voltage threshold	V _{CANH-VCANL}	500	-	900	mV
Differential input hysteresis	V _{DIFF-HYST}	50	-	-	mV
Input resistance	R _{IN}	5.0	-	50	kΩ
Differential input resistance	R _{IN-DIFF}	10	-	100	kΩ
Input resistance matching	R _{IN-MATCH}	-3.0	0.0	3.0	%
CANH output voltage (45 Ω < R _{BUS} < 65 Ω)	V _{CANH}				V
TXD dominant state		2.75	3.5	4.5	
TXD recessive state		2.0	2.5	3.0	
CANL output voltage (45 Ω < R _{BUS} < 65 Ω)	V _{CANL}				V
TXD dominant state		0.5	1.5	2.25	
TXD recessive state		2.0	2.5	3.0	
Differential output voltage (45 Ω < R _{BUS} < 65 Ω)	V _{OH} -V _{OL}				V
TXD dominant state		1.5	2.0	3.0	
TXD recessive state		-0.5	0.0	0.05	
CAN H output current capability - Dominant state	I _{CANH}	-	-	-30	mA
CAN L output current capability - Dominant state	I _{CANL}	30	-	-	mA
CANL overcurrent detection - Error reported in register	I _{CANL-OC}	75	120	195	mA
CANH overcurrent detection - Error reported in register	I _{CANH-OC}	-195	-120	-75	mA
CANH, CANL input resistance to GND, device supplied, CAN in Sleep mode, V_CANH, V_CANL from 0 to 5.0 V	R _{INSLEEP}	5.0	-	50	kΩ
CANL, CANH output voltage in LP V_{DD} OFF and LP V_{DD} ON modes	V _{CANLP}	-0.1	0.0	0.1	V
CANH, CANL input current, VCANH, VCANL = 0 to 5.0 V, device unpowered (VSUP, VDD, 5V-CAN: open). ⁽²¹⁾	ICAN-UN_SUP1	-	3.0	10	μA
CANH, CANL input current, VCANH, VCANL = -2.0 to 7.0 V, device unpowered (VSUP, VDD, 5V-CAN: open). ⁽²¹⁾	ICAN-UN_SUP2	-	-	250	μΑ
Differential voltage for recessive bit detection in LP mode ⁽²²⁾	V _{DIFF-R-LP}	-	-	0.4	V
Differential voltage for dominant bit detection in LP mode ⁽²²⁾	V _{DIFF-D-LP}	1.15	-	-	V
CANH AND CANL DIAGNOSTIC INFORMATION	1 1		1		1
CANL to GND detection threshold	V _{LG}	1.6	1.75	2.0	V
CANH to GND detection threshold	V _{HG}	1.6	1.75	2.0	V
	-				

V _{HG}	1.6	1.75	2.0	V
V _{LVB}	-	V _{SUP} -2.0	-	V
V _{HVB}	-	V _{SUP} -2.0	-	V
V_{L5}	4.0	V _{DD} -0.43	-	V
V _{H5}	4.0	V _{DD} -0.43	-	V
	V _{LVB} V _{HVB} V _{L5}	V _{LVB} - V _{HVB} - V _{L5} 4.0	V _{LVB} - V _{SUP} -2.0 V _{HVB} - V _{SUP} -2.0 V _{L5} 4.0 V _{DD} -0.43	VLVB - VSUP - 2.0 - VHVB - VSUP - 2.0 - VL5 4.0 VDD - 0.43 -

Notes

21. VSUP, VDD, 5V-CAN: shorted to GND, or connected to GND via a 47 k resistor instances are guaranteed by design and device characterization.

22. Guaranteed by design and device characterization.



Characteristics noted under conditions 5.5 V \leq V_{SUP} \leq 28 V, -40 °C \leq T_A \leq 125 °C, unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25 °C under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Тур	Max	Unit
SPLIT	I		ı	<u> </u>	
Output voltage	V _{SPLIT}				V
Loaded condition I_{SPLIT} = ±500 µA	0. 2	0.3 x V _{DD}	0.5 x V _{DD}	0.7 x V _{DD}	
Unloaded condition Rmeasure > 1.0 $M\Omega$		0.45 x V _{DD}	0.5 x V _{DD}	0.55 x V _{DD}	
Leakage current	I _{LSPLIT}				μA
-12 V < V _{SPLIT} < +12 V		-	0.0	5.0	
-22 to -12 V < V _{SPLIT} < +12 to +35 V		-	-	200	
LIN TERMINALS (LIN-T/1)			I	II	
LIN-T1 HS switch drop @ I = -20 mA, V _{SUP} > 10.5 V	V _{LT_HSDRP}	-	1.0	1.4	V
LIN1 34903D/5D PIN - LIN 34903S/5S PIN (Parameters guaranteed for V _{SUI}	1	≤ V _{SUP} ≤ 18	B V)	I I	
Operating Voltage Range	V _{BAT}	8.0	-	18	V
Supply Voltage Range	V _{SUP}	7.0	-	18	V
Current Limitation for Driver Dominant State	I _{BUS_LIM}				mA
Driver ON, V _{BUS} = 18 V		40	90	200	
Input Leakage Current at the receiver	I _{BUS PAS DOM}				mA
Driver off; V_{BUS} = 0 V; V_{BAT} = 12 V		-1.0	-	-	
Leakage Output Current to GND	I _{BUS PAS REC}				μA
Driver Off; 8.0 V < V _{BAT} < 18 V; 8.0 V < V _{BUS} < 18 V; V _{BUS} \ge V _{BAT}		-	-	20	
Control unit disconnected from ground (Loss of local ground must not affect communication in the residual network) $GND_{DEVICE} = V_{SUP}$; $V_{BAT} = 12 V$; $0 < V_{BUS} < 18 V$ (Guaranteed by design)	I _{BUS_NO_GND}	-1.0	-	1.0	mA
V_{BAT} Disconnected; V_{SUP_DEVICE} = GND; 0 < V_{BUS} < 18 V (Node has to sustain the current that can flow under this condition. Bus must remain operational under this condition). (Guaranteed by design)	I _{BUSNO_BAT}	-	-	100	μA
Receiver Dominant State	V _{BUSDOM}				V _{SUF}
		-	-	0.4	
Receiver Recessive State	V _{BUSREC}	0.6	-	-	V _{SUF}
Receiver Threshold Center	V _{BUS_CNT}				V _{SUF}
(V _{TH_DOM} + V _{TH_REC})/2	_	0.475	0.5	0.525	
Receiver Threshold Hysteresis	V _{HYS}				V _{SUF}
(V _{TH_REC} - V _{TH_DOM})		-	-	0.175	
LIN Wake-up threshold from LP V_{DD} ON or LP V_{DD} OFF mode	V _{BUSWU}	-	5.3	5.8	V
LIN Pull-up Resistor to V _{SUP}	R _{SLAVE}	20	30	60	kΩ
Overtemperature Shutdown (Guaranteed by design)	T _{LINSD}	140	160	180	°C
Overtemperature Shutdown Hysteresis (Guaranteed by design)	T _{LINSD_HYS}	-	10	_	°C



DYNAMIC ELECTRICAL CHARACTERISTICS

Table 7. Dynamic Electrical Characteristics

Characteristics noted under conditions 5.5 V \leq V_{SUP} \leq 28 V, -40 °C \leq T_A \leq 125 °C, GND = 0 V, unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25 °C under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Тур	Мах	Unit
SPI TIMING					
SPI Operation Frequency (MISO cap = 50 pF)	FREQ	0.25	-	4.0	MHz
SCLK Clock Period	t _{PCLK}	250	-	N/A	ns
SCLK Clock High Time	t _{WSCLKH}	125	-	N/A	ns
SCLK Clock Low Time	t _{WSCLKL}	125	-	N/A	ns
Falling Edge of \overline{CS} to Rising Edge of SCLK	t _{LEAD}				ns
"C" version All others		30 550	-	N/A N/A	
Falling Edge of SCLK to Rising Edge of CS	t _{LAG}	30	-	N/A	ns
MOSI to Falling Edge of SCLK	t _{sisu}	30	-	N/A	ns
Falling Edge of SCLK to MOSI	t _{SIH}	30	-	N/A	ns
MISO Rise Time (CL = 50 pF)	t _{RSO}	-	-	30	ns
MISO Fall Time (CL = 50 pF)	t _{FSO}	-	-	30	ns
Time from Falling to MISO Low-impedance	t _{SOEN}	-	-	30	ns
Time from Rising to MISO High-impedance	t _{SODIS}	-	-	30	
Time from Rising Edge of SCLK to MISO Data Valid	t _{VALID}	-	-	30	ns
Delay between falling and rising edge on \overline{CS}	t _{CSLOW}				μs
"C" version All others		1.0 5.5	-	N/A N/A	
CS Chip Select Low Timeout Detection	t сs -то	2.5	-	-	ms
SUPPLY, VOLTAGE REGULATOR, RESET	· · ·				
V_{SUP} undervoltage detector threshold deglitcher	t _{VS_LOW1/} 2_DGLT	30	50	100	μs
Rise time at turn ON. V_{DD} from 1.0 to 4.5 $\mu V.$ 2.2 μF at the VDD pin.	t _{RISE-ON}	50	250	800	μs
Deglitcher time to set \overline{RST} pin low	t _{RST-DGLT}	20	30	40	μs
RESET PULSE DURATION					
V _{DD} undervoltage (SPI selectable)	t _{RST-PULSE}				ms
short, default at power on when BATFAIL bit set medium medium long		0.9 4.0	1.0 5.0	1.4 6.5 12	
long		8.5 17	10 20	24	
Watchdog reset	t _{RST-WD}	0.9	1.0	1.4	ms
I/O INPUT	1 1		ı	1	
Deglitcher time (Guaranteed by design)	t _{IODT}	19	30	41	μs
VSENSE INPUT			I	1	1
Undervoltage deglitcher time	t _{BFT}	30	-	100	μs



Table 7. Dynamic Electrical Characteristics

Characteristics noted under conditions 5.5 V \leq V_{SUP} \leq 28 V, -40 °C \leq T_A \leq 125 °C, GND = 0 V, unless otherwise noted. Typical values noted reflect the approximate parameter means at T_{A =} 25 °C under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Тур	Max	Unit
NTERRUPT	II				
INT pulse duration (refer to SPI for selection. Guaranteed by design)					μs
short (25 to 125 °C)		20	25	35	
short (-40 °C)		20	25	40	
long (25 to 125 °C)		90	100	130	
long (-40 °C)		90	100	140	
STATE DIGRAM TIMINGS					
Delay for SPI Timer A, Timer B or Timer C write command after entering Normal mode	t _{D_NM}	60	-	-	μs
(No command should occur within t _{D_NM} .					
t_{D_NM} delay definition: from \overline{CS} rising edge of "Go to Normal mode (i.e. 0x5A00)" command to \overline{CS} falling edge of "Timer write" command)					
Tolerance for: watchdog period in all modes, FWU delay, Cyclic sense period and active time, Cyclic Interrupt period, LP mode overcurrent (unless otherwise noted) ⁽²⁶⁾	t _{TIMING-ACC}	-10	-	10	%
CAN DYNAMIC CHARACTERISTICS	II				
TXD Dominant State Timeout	t _{DOUT}	300	600	1000	μs
Bus dominant clamping detection	t _{DOM}	300	600	1000	μs
Propagation loop delay TXD to RXD, recessive to dominant (Fast slew rate)	t _{LRD}	60	120	210	ns
Propagation delay TXD to CAN, recessive to dominant	t _{TRD}	-	70	110	ns
Propagation delay CAN to RXD, recessive to dominant	t _{RRD}	-	45	140	ns
Propagation loop delay TXD to RXD, dominant to recessive (Fast slew rate)	t _{LDR}	100	120	200	ns
Propagation delay TXD to CAN, dominant to recessive	t _{TDR}	-	75	150	ns
Propagation delay CAN to RXD, dominant to recessive	t _{RDR}	-	50	140	ns
Loop time TXD to RXD, Medium Slew Rate (Selected by SPI)	t _{LOOP-MSL}				ns
Recessive to Dominant		-	200	-	
Dominant to Recessive		-	200	-	
Loop time TXD to RXD, Slow Slew Rate (Selected by SPI)	t _{LOOP-SSL}				ns
Recessive to Dominant		-	300	-	
Dominant to Recessive		-	300	-	
CAN Wake-up filter time, single dominant pulse detection ⁽²³⁾ (See Figure 31)	t _{CAN-WU1-F}	0.5	2.0	5.0	μs
CAN Wake-up filter time, 3 dominant pulses detection ⁽²⁴⁾	t _{CAN-WU3-F}	300	-	-	ns
CAN Wake-up filter time, 3 dominant pulses detection timeout ⁽²⁵⁾ (See Figure 32)	t _{CAN-WU3-TO}	-	-	120	μs

Notes

23. No Wake-up for single pulse shorter than $t_{CAN-WU1}$ min. Wake-up for single pulse longer than $t_{CAN-WU1}$ max.

24. Each pulse should be greater than t_{CAN-WU3-F} min. Guaranteed by design, and device characterization.

25. The 3 pulses should occur within $t_{CAN-WU3-TO}$. Guaranteed by design, and device characterization.

26. Guaranteed by design.

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Table 7. Dynamic Electrical Characteristics

Characteristics noted under conditions 5.5 V \leq V_{SUP} \leq 28 V, -40 °C \leq T_A \leq 125 °C, GND = 0 V, unless otherwise noted. Typical values noted reflect the approximate parameter means at T_{A =} 25 °C under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Тур	Max	Unit
LIN PHYSICAL LAYER: DRIVER CHARACTERISTICS FOR NORMAL SLE LAYER SPECIFICATION BUS LOAD R _{BUS} AND C _{BUS} 1.0 NF / 1.0 K Ω , 6.8 NF / 660 Ω , 10 NF / 500 Ω		-	CCORDING	G TO LIN PH	YSICAL
Duty Cycle 1:	D1				
$TH_{REC(MAX)} = 0.744 * V_{SUP}$					
$TH_{DOM(MAX)} = 0.581 * V_{SUP}$					
D1 = $t_{BUS_{REC(MIN)}}/(2 \times t_{BIT})$, t_{BIT} = 50 µs, 7.0 V \leq V _{SUP} \leq 18 V		0.396	-	-	
Duty Cycle 2:	D2				
$TH_{REC(MIN)} = 0.422 * V_{SUP}$	22				
$TH_{DOM(MIN)} = 0.284 * V_{SUP}$					
D2 = $t_{BUS_{REC(MAX)}}/(2 \times t_{BIT})$, t_{BIT} = 50 µs, 7.6 V \leq V _{SUP} \leq 18 V		-	-	0.581	
LIN PHYSICAL LAYER: DRIVER CHARACTERISTICS FOR SLOW SLEW F	ATE - 10.4 KBIT/	SEC ACCO	DRDING TO	LIN PHYSIC	AL LAY
BUS LOAD R _{BUS} AND C _{BUS} 1.0 NF / 1.0 K Ω , 6.8 NF / 660 Ω , 10 NF / 500 Ω	2. MEASUREMEN	IT THRESH	IOLDS. SEI	E <u>Figure 15</u> , I	PAGE 2
Duty Cycle 3:	D3				
$TH_{REC(MAX)} = 0.778 * V_{SUP}$					
$TH_{DOM(MAX)} = 0.616 * V_{SUP}$					
D3 = $t_{BUS_REC(MIN)}/(2 \times t_{BIT})$, t_{BIT} = 96 µs, 7.0 V \leq V _{SUP} \leq 18 V		0.417	-	-	
Duty Cycle 4:	D4				
TH _{REC(MIN)} = 0.389 * V _{SUP}					
$TH_{DOM(MIN)} = 0.251 * V_{SUP}$					
D4 = $t_{BUS_REC(MAX)}/(2 \text{ x } t_{BIT})$, t_{BIT} = 96 µs, 7.6 V \leq V $_{SUP} \leq$ 18 V		-	-	0.590	
LIN PHYSICAL LAYER: DRIVER CHARACTERISTICS FOR FAST SLEW F	ATE				
LIN Fast Slew Rate (Programming Mode)	SR _{FAST}	-	20	-	V/µs
LIN PHYSICAL LAYER: CHARACTERISTICS AND WAKE-UP TIMINGS V_{SUP} FROM 7.0 TO 18 V, BUS LOAD R _{BUS} AND C _{BUS} 1.0 NF / 1.0 K Ω , 6.8	 	F / 500 Ω. :	SEE <u>Figure</u>	14, PAGE <u>28</u>	<u>.</u>
Propagation Delay and Symmetry (See Figure 14, page 27 and Figure 15, page 29)					μs
Propagation Delay of Receiver, t _{REC_PD} = MAX (t _{REC_PDR} , t _{REC_PDF})	t _{REC_PD}	-	4.2	6.0	
Symmetry of Receiver Propagation Delay, $t_{REC_PDF} - t_{REC_PDR}$	t _{REC_SYM}	-2.0	-	2.0	
Bus Wake-up Deglitcher (LP V_{DD} OFF and LP V_{DD} ON modes) (See <u>Figure 1</u> page <u>28</u> for LP V_{DD} OFF mode and <u>Figure 17</u> , page <u>29</u> for LP mode)	<u>6</u> , t _{PROPWL}	42	70	95	μs
Bus Wake-up Event Reported					μs
From LP V _{DD} OFF mode	t _{WAKE_LPVDD} OFF	-	-	1500	
From LP V _{DD} ON mode	t _{WAKE_LPVDD} ON	1.0	-	12	
TXD Permanent Dominant State Delay (Guaranteed by design)	t _{TXDDOM}	0.65	1.0	1.35	s



TIMING DIAGRAMS

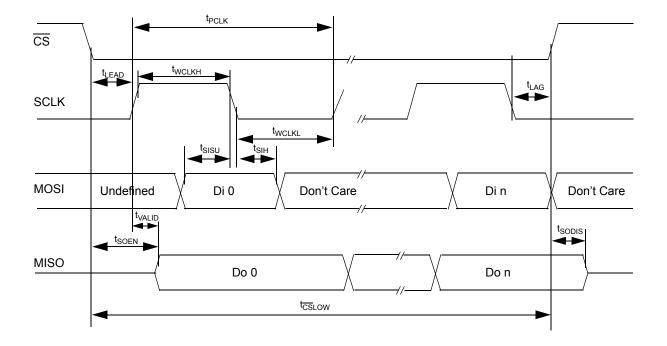


Figure 10. SPI Timings

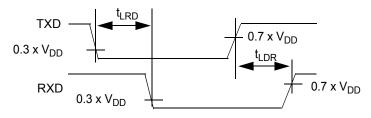


Figure 11. CAN Signal Propagation Loop Delay TXD to RXD



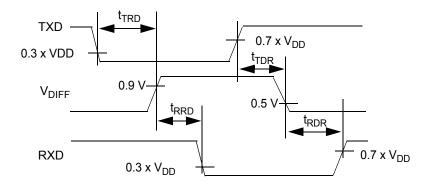


Figure 12. CAN Signal Propagation Delays TXD to CAN and CAN to RXD

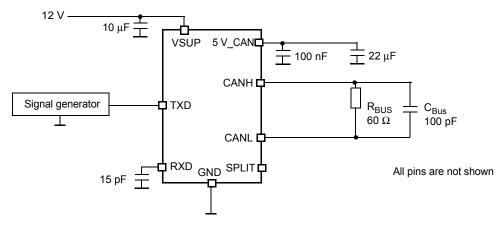


Figure 13. Test Circuit for CAN Timing Characteristics



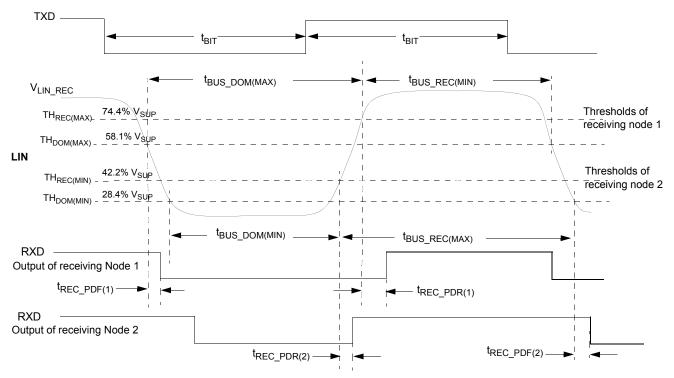


Figure 14. LIN Timing Measurements for Normal Slew Rate



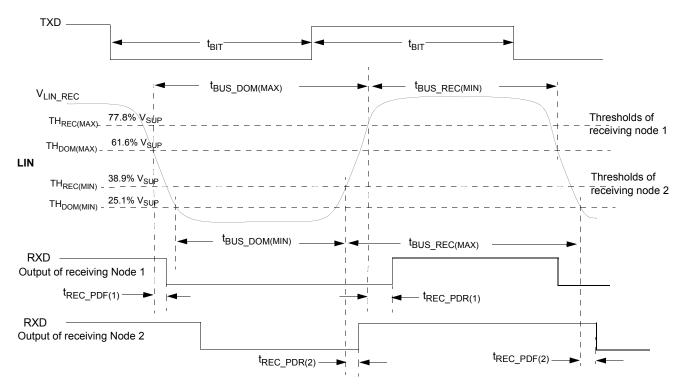


Figure 15. LIN Timing Measurements for Slow Slew Rate

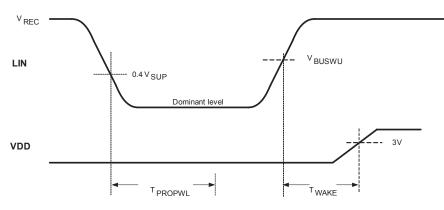
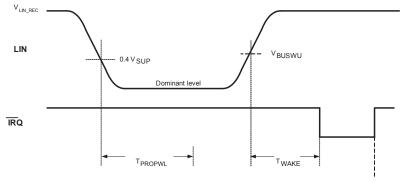


Figure 16. LIN Wake-up LP V_{DD} OFF Mode Timing





IRQ stays low until SPI reading command

Figure 17. LIN Wake-up LP V_{DD} ON Mode Timing

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FUNCTIONAL DESCRIPTION

INTRODUCTION

The MC34903_4_5 is the second generation of System Basis Chip, combining:

- Advanced power management unit for the MCU, the integrated CAN interface and for the additional ICs such as sensors, CAN transceiver.

- Built in enhanced high speed CAN interface (ISO11898-2 and -5), with local and bus failure diagnostic, protection, and fail-safe operation mode.

POWER SUPPLY (VSUP/1 AND VSUP2)

Note: VSUP1 and VSUP2 supplies are externally available on all devices except the 34903D, 34903S, and 34903P, where these are connected internally.

VSUP1 is the input pin for the internal supply and the VDD regulator. VSUP2 is the input pin for the 5 V-CAN regulator, LIN's interfaces and I/O functions. The VSUP block includes over and undervoltage detections which can generate interrupt. The device includes a loss of battery detector connected to VSUP/1.

Loss of battery is reported through a bit (called BATFAIL). This generates a POR (Power On Reset).

VDD VOLTAGE REGULATOR (VDD)

The regulator has two main modes of operation (Normal mode and LP mode). It can operate with or without an external PNP transistor.

In Normal mode, without external PNP, the max DC capability is 150 mA. Current limitation, temperature prewarning flag and overtemperature shutdown features are included. When V_{DD} is turned ON, rise time from 0 to 5.0 V is controlled. Output voltage is 5.0 V. A 3.3 V option is available via dedicated part number.

If current higher than 150 mA is required, an external PNP transistor must be connected to VE (PNP emitter) and VB (PNP base) pins, in order to increase total current capability and share the power dissipation between internal VDD transistor and the external transistor. See External Transistor Q1 (VE and VB). The PNP can be used even if current is less than 150 mA, depending upon ambient temperature, maximum supply and thermal resistance. Typically, above 100-200 mA, an external ballast transistor is recommended.

VDD REGULATOR IN LP MODE

When the device is set in LP V_{DD} ON mode, the V_{DD} regulator is able to supply the MCU with a DC current below typically 1.5 mA (L_{P-ITH}). Transient current can also be supplied up to a tenth of a mA. Current in excess of 1.5 mA is detected, and this event is managed by the device logic

- Built in LIN interface, compliant to LIN 2.1 and J2602-2 specification, with local and bus failure diagnostic and protection.

- Innovative hardware configurable fail-safe state machine solution.

- Multiple LP modes, with low current consumption.

- Family concept with pin compatibility; with and without LIN interface devices.

FUNCTIONAL PIN DESCRIPTION

(Wake-up detection, timer start for overcurrent duration monitoring or watchdog refresh).

EXTERNAL TRANSISTOR Q1 (VE AND VB)

The device has a dedicated circuit to allow usage of an external "P" type transistor, with the objective to share the power dissipation between the internal transistor of the V_{DD} regulator and the external transistor. The recommended bipolar PNP transistor is MJD42C or BCP52-16.

When the external PNP is connected, the current is shared between the internal path transistor and the external PNP, with the following typical ratio: 1/3 in the internal transistor and 2/3 in the external PNP. The PNP activation and control is done by SPI.

The device is able to operate without an external transistor. In this case, the VE and VB pins must remain open.

5 V-CAN VOLTAGE REGULATOR FOR CAN AND ANALOG MUX

This regulator is supplied from the VSUP/2 pin. A capacitor is required at 5 V-CAN pin. Analog MUX and part of the LIN interfaces are supplied from 5 V-CAN. Consequently, the 5 V-CAN must be ON in order to have Analog MUX operating and to have the LIN interface operating in TXD/RXD mode.

The 5 V-CAN regulator is OFF by default and must be turned ON by SPI. In Debug mode, the 5 V-CAN is ON by default.

V AUXILIARY OUTPUT, 5.0 AND 3.3 V SELECTABLE (VB-AUX, VC-AUX, AND VCAUX) -Q2

The VAUX block is used to provide an auxiliary voltage output, 5.0 or 3.3 V, selectable by the SPI. It uses an external PNP pass transistor for flexibility and power dissipation constraints. The external recommended bipolar transistors are MJD42C or BCP52-16.

An overcurrent and undervoltage detectors are provided.



 V_{AUX} is controlled via the SPI, and can be turned ON or OFF. V_{AUX} low threshold detection and overcurrent information will disable V_{AUX} , and are reported in the SPI and can generate \overline{INT} .

V_{AUX} is OFF by default and must be turned ON by the SPI.

UNDERVOLTAGE RESET AND RESET FUNCTION (RST)

The $\overline{\text{RST}}$ pin is an open drain structure with an internal pull-up resistor. The LS driver has limited current capability when asserted low, in order to tolerate a short to 5.0 V. The $\overline{\text{RST}}$ pin voltage is monitored in order to detect failure (e.g. $\overline{\text{RST}}$ pin shorted to 5.0 V or GND).

The $\overline{\text{RST}}$ pin reports an undervoltage condition to the MCU at the VDD pin, as a $\overline{\text{RST}}$ failure in the watchdog refresh operation. V_{DD} undervoltage reset also operates in LP V_{DD} ON mode.

Two V_{DD} undervoltage thresholds are included. The upper (typically 4.65 V, R_{ST-TH1-5}) can lead to a Reset or an Interrupt. This is selected by the SPI. When "R_{ST-TH2-5}" is selected, in Normal mode, an INT is asserted when VDD falls below "R_{ST-TH1-5}", then, when V_{DD} falls below "R_{ST-TH2-5}" a Reset will occur. This will allow the MCU to operate in a degraded mode (i.e., with 4.0 V V_{DD}).

I/O PINS (I/O-0: I/O-3)

I/Os are configurable input/output pins. They can be used for small loads or to drive external transistors. When used as output drivers, the I/Os are either a HS or LS type. They can also be set to high-impedance. I/Os are controlled by the SPI and at power on, the I/Os are set as inputs. They include overload protection by temperature or excess of a voltage drop.

When I/O-0/-1/-2/-3 voltage is greater than VSUP/2 voltage, the leakage current (I_{I/O_LEAK}) parameter is not applicable

- I/O-0 and I/O-1 will have current flowing into the device through three diodes limited by an 80 kOhm resistor (in series).
- I/O-2 and I/O-3 will have unlimited current flowing into the device through one diode.

In LP mode, the state of the I/O can be turned ON or OFF, with extremely low power consumption (except when there is a load). Protection is disabled in LP mode.

When cyclic sense is used, I/O-0 is the HS/LS switch, I/O-1, -2 and -3 are the wake inputs.

I/O-2 and I/O-3 pins share the LIN Master pin function.

VSENSE INPUT (VSENSE)

This pin can be connected to the battery line (before the reverse battery protection diode), via a serial resistor and a capacitor to GND. It incorporates a threshold detector to sense the battery voltage and provide a battery early warning. It also includes a resistor divider to measure the V_{SENSE} voltage via the MUX-OUT pin.

MUX-OUTPUT (MUXOUT)

The MUX-OUT pin (Figure 18) delivers an analog voltage to the MCU A/D input. The voltage to be delivered to MUX-OUT is selected via the SPI, from one of the following functions: $V_{SUP/1}$, V_{SENSE} , I/O-0, I/O-1, Internal 2.5 V reference, die temperature sensor, V_{DD} current copy.

Voltage divider or amplifier is inserted in the chain, as shown in Figure 18.

For the V_{DD} current copy, a resistor must be added to the MUX-OUT pin, to convert current into voltage. Device includes an internal 2.0 k resistor selectable by the SPI.

Voltage range at MUX-OUT is from GND to VDD. It is automatically limited to V_{DD} (max 3.3 V for 3.3 V part numbers).

The MUX-OUT buffer is supplied from 5 V-CAN regulator, so the 5 V-CAN regulator must be ON in order to have:

1) MUX-OUT functionality and

2) SPI selection of the analog function.

If the 5 V-CAN is OFF, the MUX-OUT voltage is near GND and the SPI command that selects one of the analog inputs is ignored.

Delay must be respected between SPI commands for 5 V-CAN turned ON and SPI to select MUX-OUT function. The delay depends mainly upon the 5 V-CAN capacitor and load on 5 V-CAN.

The delay can be estimated using the following formula: delay = C(5 V-CAN) x U (5.0 V) / I_lim 5 V-CAN.

C = cap at 5 V-CAN regulator, U = 5.0 V,

 $I_{LIM} 5 V$ -CAN = min current limit of 5 V-CAN regulator (parameter 5 V_{-C ILIM}).

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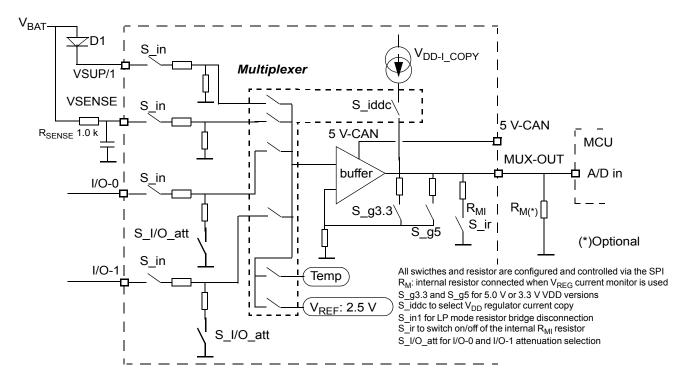


Figure 18. Analog Multiplexer Block Diagram

DGB (DGB) AND DEBUG MODE

Primary Function

It is an input used to set the device in Debug mode. This is achieved by applying a voltage between 8.0 and 10 V at the DEBUG pin and then, powering up the device (See State Diagram). When the device leaves the INIT Reset mode and enters into INIT mode, it detects the voltage at the DEBUG pin to be between a range of 8.0 to 10 V, and activates the Debug mode.

When Debug mode is detected, no Watchdog SPI refresh commands are necessary. This allows an easy debug of the hardware and software routines (i.e. SPI commands).

When the device is in Debug mode it is reported by the SPI flag. While in Debug mode, and the voltage at DBG pin falls below the 8.0 to 10 V range, the Debug mode is left, and the device starts the watchdog operation, and expects the proper watchdog refresh. The Debug mode can be left by SPI. This is recommended to avoid staying in Debug mode when an unwanted Debug mode selection (FMEA pin) is present. The SPI command has a higher priority than providing 8.0 to 10 V at the DEBUG pin.

Secondary Function

The resistor connected between the DBG pin and the GND selects the Fail-Safe mode operation. DBG pin can also be connected directly to GND (this prevents the usage of Debug mode).

Flexibility is provided to select SAFE output operation via a resistor at the DBG pin or via a SPI command. The SPI command has higher priority than the hardware selection via Debug resistor.

When the Debug mode is selected, the SAFE modes cannot be configured via the resistor connected at DBG pin.

SAFE

Safe Output Pin

This pin is an output and is asserted low when a fault event occurs. The objective is to drive electrical safe circuitry and set the ECU in a known state, independent of the MCU and SBC, once a failure has been detected.

The SAFE output structure is an open drain, without a pullup.

INTERRUPT (INT)

The INT output pin is asserted low or generates a low pulse when an interrupt condition occurs. The INT condition is enabled in the INT register. The selection of low level or pulse and pulse duration are selected by SPI.

No current will flow inside the \overline{INT} structure when V_{DD} is low, and the device is in LP V_{DD} OFF mode. This allows the connection of an external pull-up resistor and connection of an \overline{INT} pin from other ICs without extra consumption in unpowered mode.



 $\overline{\text{INT}}$ has an internal pull-up structure to V_{DD} . In LP V_{DD} ON mode, a diode is inserted in series with the pull-up, so the high level is slightly lower than in other modes.

CANH, CANL, SPLIT, RXD, TXD

These are the pins of the high speed CAN physical interface, between the CAN bus and the micro controller. A detail description is provided in the document.

LIN, LIN-T, TXDL AND RXDL

These are the pins of the LIN physical interface. Device contains zero or 1 LIN interfaces.

The MC34903P, and MC34904 do not have a LIN interface. However, the MC34903S/5S (S = Single) contains 1 interface.

LIN and LIN1 pins are the connection to the LIN sub buses.

LIN interfaces are connected to the MCU via the TXD, TXD-L1, RXD, RXD-L1 pins.

The device also includes one or two HS switches to VSUP/ 2 pin which can be used as a LIN master termination switch. Pins LINT and LINT-1 pins are the same as I/O-2 and I/O-3.

FUNCTIONAL DEVICE OPERATION

MODE AND STATE DESCRIPTION

The device has several operation modes. The transitions and conditions to enter or leave each mode are illustrated in the state diagram.

INIT RESET

This mode is automatically entered after the device is "powered on". In this mode, the RST pin is asserted low, for a duration of typically 1.0 ms. Control bits and flags are "set" to their default reset condition. The BATFAIL is set to indicate the device is coming from an unpowered condition, and all previous device configurations are lost and "reset" the default value. The duration of the INIT reset is typically 1.0 ms.

INIT reset mode is also entered from INIT mode if the expected SPI command does not occur in due time (Ref. INIT mode), and if the device is not in the debug mode.

INIT

This mode is automatically entered from the INIT Reset mode. In this mode, the device must be configured via SPI within a time of 256 ms max.

Four registers called INIT Wdog, INIT REG, INIT LIN I/O and INIT MISC must be, and can only be configured during INIT mode.

Other registers can be written in this and other modes.

Once the INIT register configuration is done, a SPI Watchdog Refresh command must be sent in order to set the device into Normal mode. If the SPI watchdog refresh does not occur within the 256 ms period, the device will return into INIT Reset mode for typically 1.0 ms, and then re enter into INIT mode.

Register read operation is allowed in INIT mode to collect device status or to read back the INIT register configuration.

When INIT mode is left by a SPI watchdog refresh command, it is only possible to re-enter the INIT mode using a secured SPI command. In INIT mode, the CAN, LIN1, VAUX, I/O_x and Analog MUX functions are not operating. The 5 V-CAN is also not operating, except if the Debug mode is detected.

RESET

In this mode, the $\overline{\text{RST}}$ pin is asserted low. Reset mode is entered from Normal mode, Normal Request mode, LP V_{DD} on mode and from the Flash mode when the watchdog is not triggered, or if a V_{DD} low condition is detected.

The duration of reset is typically 1.0 ms by default. You can define a longer Reset pulse activation only when the Reset mode is entered following a V_{DD} low condition. Reset pulse is always 1.0 ms, when reset mode is entered due to wrong watchdog refresh command.

Reset mode can be entered via the secured SPI command.

NORMAL REQUEST

This mode is automatically entered after RESET mode, or after a Wake-up from LP V_{DD} ON mode.

A watchdog refresh SPI command is necessary to transition to NORMAL mode. The duration of the Normal request mode is 256 ms when Normal Request mode is entered after RESET mode. Different durations can be selected by SPI when normal request is entered from LP V_{DD} ON mode.

If the watchdog refresh SPI command does not occur within the 256 ms (or the shorter user defined time out), then the device will enter into RESET mode for a duration of typically 1.0 ms.

Note: in init reset, init, reset and normal request modes as well as in LP modes, the V_{DD} external PNP is disabled.

NORMAL

In this mode, all device functions are available. This mode is entered by a SPI watchdog refresh command from Normal Request mode, or from INIT mode.

During Normal mode, the device watchdog function is operating, and a periodic watchdog refresh must occur. When an incorrect or missing watchdog refresh command is initiated, the device will enter into Reset mode.

While in Normal mode, the device can be set to LP modes (LP V_{DD} ON or LP V_{DD} OFF) using the SPI command. Dedicated, secured SPI commands must be used to enter from Normal mode to Reset mode, INIT mode or Flash mode.

FLASH

In this mode, the software watchdog period is extended up to typically 32 seconds. This allow programming of the MCU flash memory while minimizing the software over head to refresh the watchdog. The flash mode is entered by Secured SPI command and is left by SPI command. Device will enter into Reset mode. When an incorrect or missing watchdog refresh command device will enter into Reset mode. An interrupt can be generated at 50% of the watchdog period.

CAN interface operates in Flash mode to allow flash via CAN bus, inside the vehicle.

DEBUG

Debug is a special operation mode of the device which allows for easy software and hardware debugging. The debug operation is detected after power up if the DBG pin is set to 8.0 to 10 V range.

When debug is detected, all the software watchdog operations are disabled: 256 ms of INIT mode, watchdog refresh of Normal mode and Flash mode, Normal Request time out (256 ms or user defined value) are not operating and will not lead to transition into INIT reset or Reset mode.

When the device is in Debug mode, the SPI command can be sent without any time constraints with respect to the watchdog operation and the MCU program can be "halted" or "paused" to verify proper operation.



Debug can be left by removing 8 to 10 V from the DEBUG pin, or by the SPI command (Ref. to MODE register).

The 5 V-CAN regulator is ON by default in Debug mode.

LP MODES

The device has two main LP modes: LP mode with $\rm V_{DD}$ OFF, and LP mode with $\rm V_{DD}$ ON.

Prior to entering into LP mode, I/O and CAN Wake-up flags must be cleared (Ref. to mode register). If the Wake-up flags are not cleared, the device will not enter into LP mode. In addition, the CAN failure flags (i.e. CAN_F and CAN_UF) must be cleared, in order to meet the LP current consumption specification.

LP - V_{DD} OFF

In this mode, V_{DD} is turned OFF and the MCU connected to VDD is unsupplied. This mode is entered using SPI. It can also be entered by an automatic transition due to fail-safe management. 5 V-CAN and V_{AUX} regulators are also turned OFF.

When the device is in LP V_{DD} OFF mode, it monitors external events to Wake-up and leave the LP mode. The Wake-up events can occur from:

- CAN
- · LIN interface, depending upon device part number
- · Expiration of an internal timer
- I/O-0, and I/O-1 inputs, and depending upon device part number and configuration, I/O-2 and/or -3 input
- Cyclic sense of I/O-1 input, associated by I/O-0 activation, and depending upon device part number and configuration, cyclic sense of I/O-2 and -3 input, associated by I/O-0 activation

When a Wake-up event is detected, the device enters into Reset mode and then into Normal Request mode. The Wake-up sources are reported to the device SPI registers. In summary, a Wake-up event from LP V_{DD} OFF leads to the V_{DD} regulator turned ON, and the MCU operation restart.

LP - V_{DD} ON

In this mode, the voltage at the VDD pin remains at 5.0 V (or 3.3 V, depending upon device part number). The objective is to maintain the MCU powered, with reduced consumption. In such mode, the DC output current is expected to be limited to 100 μA or a few mA, as the ECU is in reduced power operation mode.

During this mode, the 5 V-CAN and V_{AUX} regulators are OFF. The optional external PNP at VDD will also be automatically disabled when entering this mode.

The same Wake-up events as in LP $\rm V_{DD}$ OFF mode (CAN, LIN, I/O, timer, cyclic sense) are available in LP $\rm V_{DD}$ on mode.

In addition, two additional Wake-up conditions are available.

- Dedicated SPI command. When device is in LP V_{DD} ON mode, the Wake-up by SPI command uses a write to "Normal Request mode", 0x5C10.
- Output current from VDD exceeding L_{P-ITH} threshold.

In LP V_{DD} ON mode, the device is able to source several tenths of mA DC. The current source capability can be time limited, by a selectable internal timer. Timer duration is up to 32 ms, and is triggered when the output current exceed the output current threshold typically 1.5 mA.

This allows for instance, a periodic activation of the MCU, while the device remains in LP V_{DD} on mode. If the duration exceed the selected time (ex 32 ms), the device will detect a Wake-up.

Wake-<u>up</u> events are reported to the MCU via a low level pulse at INT pulse. The MCU will detect the INT pulse and resume operation.

Watchdog Function in LP V_{DD} ON Mode

It is possible to enable the watchdog function in LP V_{DD} ON mode. In this case, the principle is timeout.

Refresh of the watchdog is done either by:

- a dedicated SPI command (different from any other SPI command or simple CS activation which would Wakeup - Ref. to the previous paragraph)
- or by a temporary (less than 32 ms max) V_{DD} over current Wake-up (I_{DD} > 1.5 mA typically).

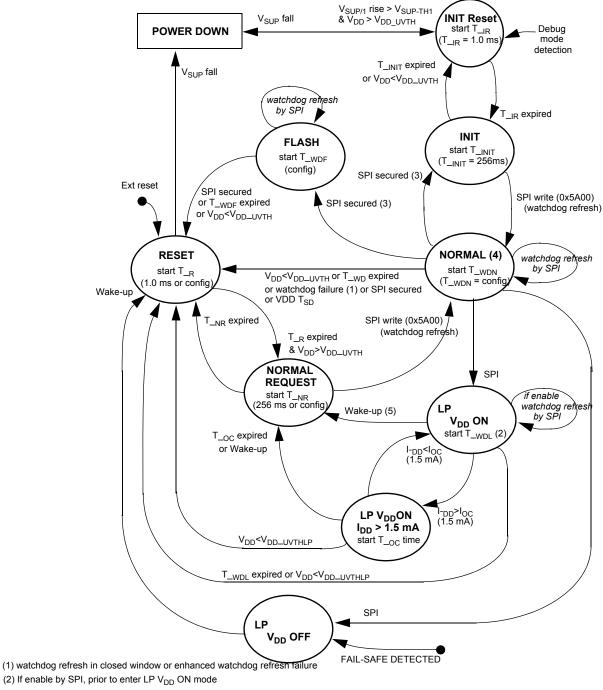
As long as the watchdog refresh occurs, the device remains in LP $\rm V_{\rm DD}$ on mode.

Mode Transitions

Mode transitions are either done automatically (i.e. after a timeout expired or voltage conditions), or via a SPI command, or by an external event such as a Wake-up. Some mode changes are performed using the Secured SPI commands.



STATE DIAGRAM



(3) Ref. to "SPI secure" description

(4) V_{DD} external PNP is disable in all mode except Normal and Flash modes. (5) Wake-up from LP V_{DD} ON mode by SPI command is done by a SPI mode change: 0X5C10

Figure 19. State Diagram



MODE CHANGE

"SECURED SPI" DESCRIPTION:

A request is done by a SPI command, the device provide on MISO an unpredictable "random code". Software must perform a logical change on the code and return it to the device with the new SPI command to perform the desired action.

The "random code" is different at every exercise of the secured procedure and can be read back at any time.

The secured SPI uses the Special MODE register for the following transitions:

- from Normal mode to INT mode

- from Normal mode to Flash mode

from Normal mode to Reset mode (reset request).
 "Random code" is also used when the "advance

watchdog" is selected.

CHANGING OF DEVICE CRITICAL PARAMETERS

Some critical parameters are configured one time at device power on only, while the batfail flag is set in the INIT mode. If a change is required while device is no longer in INIT mode, device must be set back in INIT mode using the "SPI secure" procedure.

WATCHDOG OPERATION

IN NORMAL REQUEST MODE

In Normal Request mode, the device expects to receive a watchdog configuration before the end of the normal request time out period. This period is reset to a long (256 ms) after power on and when BATFAIL is set.

The device can be configured to a different (shorter) time out period which can be used after Wake-up from LP $\rm V_{DD}$ on mode.

After a software watchdog reset, the value is restored to 256 ms, in order to allow for a complete software initialization, similar to a device power up.

In Normal Request mode the watchdog operation is "timeout" only and can be triggered/observed any time within the period.

WATCHDOG TYPE SELECTION

Three types of watchdog operation can be used:

- Window watchdog (default)
- Timeout operation
- Advanced

The selection of watchdog is performed in INIT mode. This is done after device power up and when the BATFAIL flag is set. The Watchdog configuration is done via the SPI, then the Watchdog mode selection content is locked and can be changed only via a secured SPI procedure.

Window Watchdog Operation

The window watchdog is available in Normal mode only. The watchdog period selection can be kept (SPI is selectable in INIT mode), while the device enters into LP V_{DD} ON mode. The watchdog period is reset to the default long period after BATFAIL.

The period and the refresh of watchdog are done by the SPI. A refresh must be done in the open window of the period, which starts at 50% of the selected period and ends at the end of the period.

If the watchdog is triggered before 50%, or not triggered before end of period, a reset has occurred. The device enters into Reset mode.

Watchdog in Debug Mode

When the device is in Debug mode (entered via the DBG pin), the watchdog continues to operate but does not affect the device operation by asserting a reset. For the user, operation appears without the watchdog.

When Debug mode is set by software (SPI mode reg), the watchdog period starts at the end of the SPI command.

When Debug mode is set by hardware (DBG pin below 8-10 V), the device enters into Reset mode.

Watchdog in Flash Mode

During Flash mode, watchdog can be set to a long timeout period. Watchdog is timeout only and an $\overline{\text{INT}}$ pulse can be generated at 50% of the time window.

Advance Watchdog Operation

When the Advance watchdog is selected (at INIT mode), the refresh of the watchdog must be done using a random number and with 1, 2, or 4 SPI commands. The number for the SPI command is selected in INIT mode.

The software must read a random byte from the device, and then must return the random byte inverted to clear the watchdog. The random byte write can be performed in 1, 2, or 4 different SPI commands.

If one command is selected, all eight bits are written at once.

If two commands are selected, the first write command must include four of the eight bits of the inverted random byte. The second command must include the next four bits. This completes the watchdog refresh.

If four commands are selected, the first write command must include two of the eight bits of the inverted random byte. The second command must include the next two bits, the 3rd command must include the next two, and the last command,



must include the last two. This completes the watchdog refresh.

When multiple writes are used, the most significant bits are sent first. The latest SPI command needs to be done inside the open window time frame, if window watchdog is selected.

DETAIL SPI OPERATION AND SPI COMMANDS FOR ALL WATCHDOG TYPES.

All SPI commands and examples do not use parity functions.

In INIT mode, the watchdog type (window, timeout, advance and number of SPI commands) is selected using the register Init watchdog, bits 1, 2 and 3. The watchdog period is selected using the TIM_A register. The watchdog period selection can also be done in Normal mode or in Normal Request mode.

Transition from INIT mode to Normal mode or from Normal Request mode to Normal mode is done using a single watchdog refresh command (SPI 0x 5A00).

While in Normal mode, the Watchdog Refresh Command depends upon the watchdog type selected in INIT mode. They are detailed in the paragraph below:

Simple Watchdog

The Refresh command is 0x5A00. It can be send any time within the watchdog period, if the timeout watchdog operation is selected (INIT-watchdog register, bit 1 WD N/Win = 0). It must be send in the open window (second half of the period) if the Window Watchdog operation was selected (INIT-watchdog register, bit 1 WD N/Win = 1).

Advance Watchdog

The first time the device enters into Normal mode (entry on Normal mode using the 0x5A00 command), Random (RNDM) code must be read using the SPI command, 0x1B00. The device returns on MISO second byte the RNDM code. The full 16 bits MISO is called 0x XXRD. RD is the complement of the RD byte.

Advance Watchdog, Refresh by 1 SPI Command

The refresh command is 0x5ARD. During each refresh command, the device will return on MISO, a new Random Code. This new Random Code must be inverted and send

along with the next refresh command. It must be done in an open window, if the Window operation was selected.

Advance Watchdog, Refresh by two SPI Commands:

The refresh command is split in two SPI commands.

The first partial refresh command is 0x5Aw1, and the second is 0x5Aw2. Byte w1 contains the first four inverted bits of the RD byte plus the last four bits equal to zero. Byte w2 contains four bits equal to zero plus the last four inverted bits of the RD byte.

During this second refresh command the device returns on MISO a new Random Code. This new random code must be inverted and send along with the next two refresh commands and so on.

The second command must be done in an open window if the Window operation was selected.

Advance Watchdog, Refresh by four SPI Commands

The refresh command is split into four SPI commands.

The first partial refresh command is 0x5Aw1, the second is 0x5Aw2, the third is 0x5Aw3, and the last is 0x5Aw4.

Byte w1 contains the first two inverted bits of the RD byte, plus the last six bits equal to zero.

Byte w2 contains two bits equal to zero, plus the next two inverted bits of the RD byte, plus four bits equal to zero.

Byte w3 contains four bits equal to zero, plus the next two inverted bits of the RD byte, plus two bits equal to zero.

Byte w4 contains six bits equal to zero, plus the next two inverted bits of the RD byte.

During this fourth refresh command, the device will return, on MISO, a new Random Code. This new Random Code must be inverted and send along with the next four refresh commands.

The fourth command must be done in an open window if the Window operation was selected.

PROPER RESPONSE TO INT

During a device detect upon an INT, the software handles the INT in a timely manner: Access of the INT register is done within two watchdog periods. This feature must be enabled by SPI using the INIT watchdog register bit 7.



FUNCTIONAL BLOCK OPERATION VERSUS MODE

Table 8. Device Block Operation for Each State

State	V _{DD}	5 V-CAN	I/O-X	V _{AUX}	CAN	LIN1
Power down	OFF	OFF	OFF	OFF	High-impedance	High-impedance
Init Reset	ON	OFF	HS/LS off	OFF	OFF:	OFF:
			Wake-up disable		CAN termination 25 k to GND Transmitter / receiver /Wake-up OFF	internal 30 k pull-up active. Transmitter: receiver / Wake-up OFF.
						LIN term OFF
INIT	ON	OFF ⁽²⁸⁾	WU disable (29)(30)(31)	OFF	OFF	OFF
Reset	ON	Keep SPI config	WU disable (29)(30)(31)	OFF	OFF	OFF
Normal Request	ON	Keep SPI config	WU disable (29)(30)(31)	OFF	OFF	OFF
Normal	ON	SPI config	SPI config WU SPI config	SPI config	SPI config	SPI config
LPV_DDOFF	OFF	OFF	user defined WU SPI config	OFF	OFF + Wake-up en/dis	OFF + Wake-up en/dis
LP V _{DD} ON	ON ⁽²⁷⁾	OFF	user defined WU SPI config	OFF	OFF + Wake-up en/dis	OFF + Wake-up en/dis
SAFE output low:	safe case	A: Keep SPI	HS/LS off	OFF	OFF + Wake-up enable	OFF + Wake-up enable
Safe case A	A:ON safe case B: OFF	config, B: OFF	Wake-up by change state			
FLASH	ON	SPI config	SPI config	OFF	SPI config	OFF

Notes

27. With limited current capability

28. 5 V-CAN is ON in Debug mode.

29. I/O-0 and I/O-1, configured as an output high-side switch and ON in Normal mode will remain ON in RESET, INIT or Normal Request.

30. I/O-0, configured as an output low-side switch and ON in Normal mode will turn OFF when entering Reset mode, resume operation in Normal mode.

31. I/O-1, configured as an output low-side switch and ON in Normal mode will remain ON in RESET, INIT or Normal Request.

The 5 V-CAN default is ON when the device is powered-up and set in Debug mode. It is fully controllable via the SPI command.



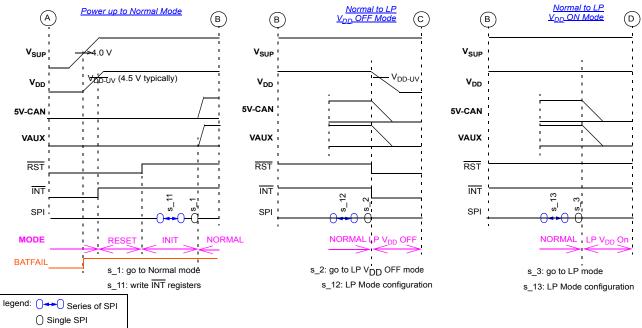


ILLUSTRATION OF DEVICE MODE TRANSITIONS.





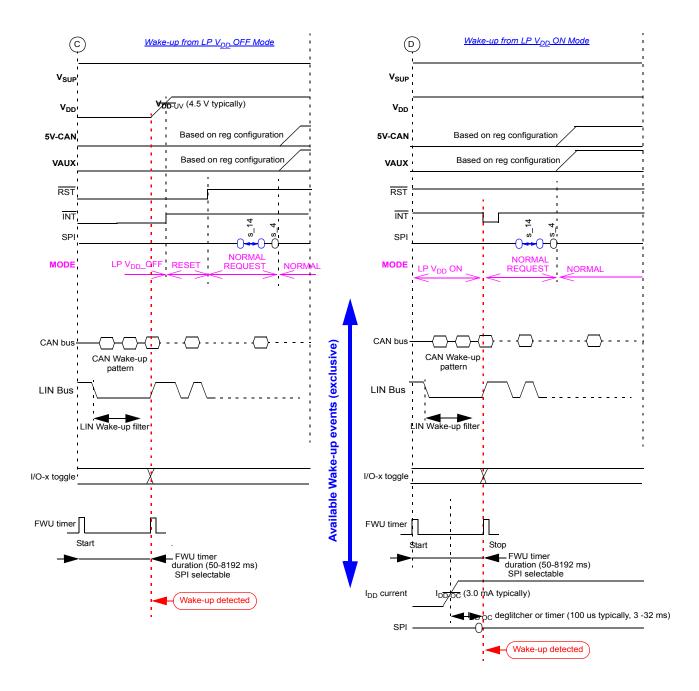


Figure 21. Wake-up from LP Modes





CYCLIC SENSE OPERATION DURING LP MODES

This function can be used in both LP modes: $V_{DD}\, \text{OFF}$ and $V_{DD}\, \text{ON}.$

Cyclic sense is the periodic activation of I/O-0 to allow biasing of external contact switches. The contact switch state can be detected via I/O-1, -2, and -3, and the device can Wake-up from either LP mode.

Cyclic sense is optimized and designed primarily for closed contact switch in order to minimize consumption via the contact pull-up resistor.

Principle

A dedicated timer provides an opportunity to select a cyclic sense period from 3.0 to 512 ms (selection in timer B).

At the end of the period, the I/O-0 will be activated for a duration of T_{CSON} (SPI selectable in INIT register, to 200 μ s, 400 μ s, 800 μ s, or 1.6 ms). The I/O-0 HS transistor or LS

transistor can be activated. The selection is done by the state of I/O-0 prior to entering in LP mode.

During the T_{-CSON} duration, the I/O-x's are monitored. If one of them is high, the device will detect a Wake-up. (Figure 22).

Cyclic sense period is selected by the SPI configuration prior to entering LP mode. Upon entering LP mode, the I/O-0 should be activated.

The level of I/O-1 is sense during the I/O-0 active time, and is deglitched for a duration of typically 30 μ s. This means that I/O-1 should be in the expected state for a duration longer than the deglitch time.

The diagram below (Figure 22) illustrates the cyclic sense operation, with I/O-0 HS active and I/O-1 Wake-up at high level.

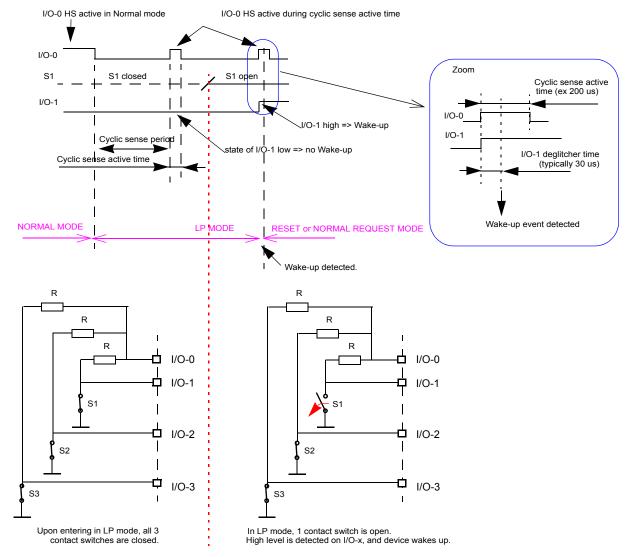


Figure 22. Cyclic Sense Operation - Switch to GND, Wake-up by Open Switch

CYCLIC INT OPERATION DURING LP VDD ON MODE

Principle

This function can be used only in LP $V_{DD}\,ON$ mode (LP $V_{DD}\,ON).$

When Cyclic INT is selected and device is in LP V_{DD} ON mode, the device will generate a periodic INT pulse.

Upon reception of the INT pulse, the MCU must acknowledge the INT by sending SPI commands before the end of the next INT period in order to keep the process going.

When Cyclic INT is selected and operating, the device remains in LP V_{DD} ON mode, assuming the SPI commands are issued properly. When no/improper SPI commands are sent, the device will cease Cyclic INT operation and leave LP V_{DD} ON mode by issuing a reset. The device will then enter into Normal Request mode.

VDD current capability and VDD regulator behavior is similar as in LP V_{DD} ON mode.

Operation

Cyclic INT period selection: register timer B

SPI command in hex 0x56xx [example; 0x560E for 512ms cyclic Interrupt period (SPI command without parity bit)].

This command must be send while the device is in Normal mode.

SPI commands to acknowledge INT: (2 commands)

- read the Random code via the watchdog register address using the following command: MOSI 0x1B00 device report on MISO second byte the RNDM code (MISO bit 0-7).

- write watchdog refresh command using the random code inverted: 0x5A RNDb.

These commands can occur at any time within the period.

<u>Initial entry in LP mode with Cyclic INT</u>: after the device is set in LP V_{DD} ON mode, with cyclic INT enable, no SPI command is necessary until the first INT pulse occurs. The acknowledge process must start only after the 1st INT pulse.

Leave LP mode with Cyclic INT:

This is done by a SPI Wake-up command, similar to SPI Wake-up from LP V_{DD} ON mode: 0x5C10. The device will enter into Normal Request mode.

Improper SPI command while Cyclic INT operates:

When no/improper SPI commands are sent, while the device is in LP V_{DD} ON mode with Cyclic INT enable, the device will cease Cyclic INT operation and leave LP V_{DD} ON mode by issuing a reset. The device will then enter into Normal Request mode.

The figure below (Figure 23) describes the complete Cyclic Interrupt operation.

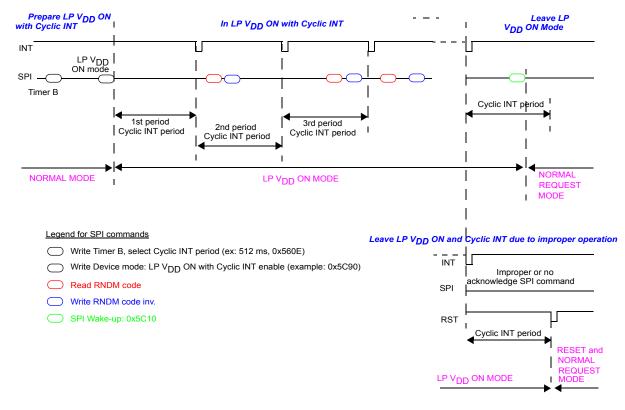


Figure 23. Cyclic Interrupt Operation



BEHAVIOR AT POWER UP AND POWER DOWN

DEVICE POWER UP

This section describe the device behavior during ramp up, and ramp down of V_{SUP/1}, and the flexibility offered mainly by the Crank bit and the two V_{DD} undervoltage reset thresholds.

The figures below illustrate the device behavior during $V_{SUP/1}$ ramp up. As the Crank bit is by default set to 0, V_{DD} is enabled when $V_{SUP/1}$ is above $V_{SUP TH 1}$ parameters.

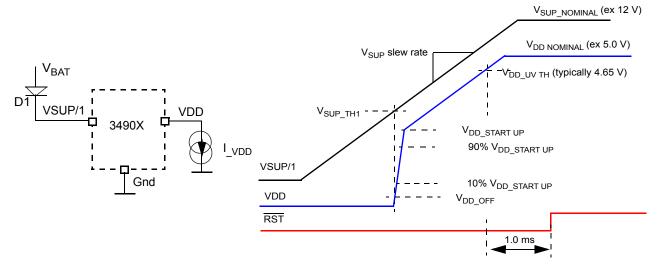


Figure 24. V_{DD} Start-up Versus V_{SUP/1} Tramp

DEVICE POWER DOWN

The figures below illustrate the device behavior during $V_{SUP/1}$ ramp down, based on Crank bit configuration, and V_{DD} undervoltage reset selection.

Crank Bit Reset (INIT Watchdog Register, Bit 0 =0)

Bit 0 = 0 is the default state for this bit.

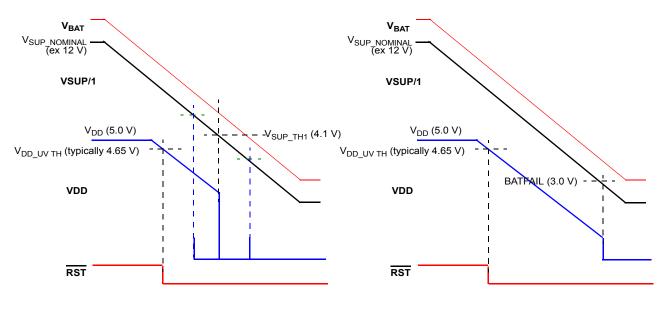
During $V_{SUP/1}$ ramp down, V_{DD} remain ON until device enters in Reset mode due to a V_{DD} undervoltage condition

$(V_{DD} < 4.6 \text{ V or } V_{DD} < 3.2 \text{ V typically, threshold selected by the SPI})$. When device is in Reset, if $V_{SUP/1}$ is below " $V_{SUP TH1}$ ", V_{DD} is turned OFF.

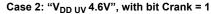
Crank Bit Set (INIT Watchdog Register, Bit 0 =1)

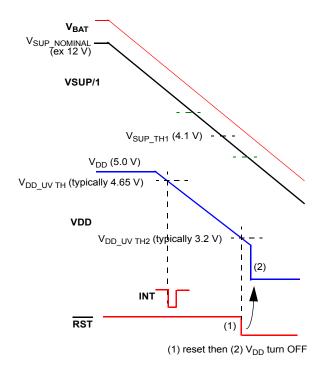
The bit 0 is set by SPI write. During V_{SUP/1} ramp down, V_{DD} remains ON until device detects a POR and set BATFAIL. This occurs for a V_{SUP/1} approx 3.0 V.



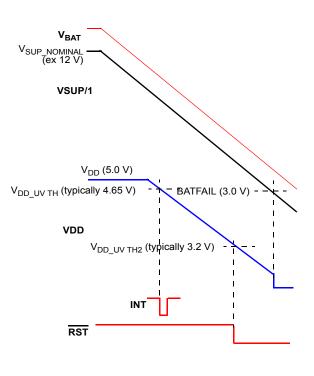


Case 1: "V_{DD UV TH} 4.6V", with bit Crank = 0 (default value)

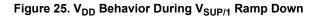




Case 1: "V_{DD UV TH} 3.2V", with bit Crank = 0 (default value)



Case 2: "V_{DD UV} 3.2V", with bit Crank = 1





FAIL-SAFE OPERATION

OVERVIEW

Fail-safe mode is entered when specific fail conditions occur. The "Safe state" condition is defined by the resistor connected at the DGB pin. Safe mode is entered after additional event or conditions are met: time out for CAN communication and state at I/O-1 pin.

Exiting the safe state is always possible by a Wake-up event: in the safe state, the device can automatically be awakened by CAN and I/O (if configured as inputs). Upon Wake-up, the device operation is resumed: enter in Reset mode.

FAIL-SAFE FUNCTIONALITY

Upon dedicated event or issue detected at a device pin (i.e. RST short to VDD), the Safe mode can be entered. In this mode, the SAFE pin is active low.

Description

Upon activation of the SAFE pin, and if the failure condition that make the SAFE pin activated have not recovered, the device can help to reduce ECU consumption, assuming that the MCU is not able to set the whole ECU in LP mode. Two main cases are available:

Mode A

Upon SAFE activation, the MCU remains powered (V_{DD} stays ON), until the failure condition recovers (i.e. S/W is able

Table 9. Fail-safe Options

to properly control the device and properly refresh the watchdog).

Modes B1, B2 and B3

Upon SAFE activation, the system continues to monitor external event, and disable the MCU supply (turn V_{DD} OFF). The external events monitored are: CAN traffic, I/O-1 low level or both of them. 3 sub cases exist, B1, B2 and B3.

Note: no CAN traffic indicates that the ECU of the vehicle are no longer active, thus that the car is being parked and stopped. The I/O low level detection can also indicate that the vehicle is being shutdown, if the I/O-1 pin is connected for instance to a switched battery signal (ignition key on/off signal).

The selection of the monitored events is done by hardware, via the resistor connected at DBG pin, but can be over written by software, via a specific SPI command.

By default, after power up the device detect the resistor value at DBG pin (upon transition from INIT to Normal mode), and, if no specific SPI command related to Debug resistor change is send, operates according to the detected resistor.

The INIT MISC register allow you to verify and change the device behavior, to either confirm or change the hardware selected behavior. Device will then operate according to the SAFE mode configured by the SPI.

Table 9 illustrates the complete options available:

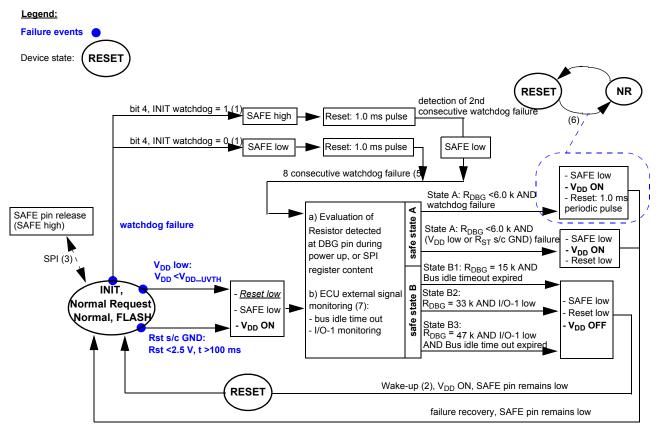
Resistor at DBG pin	SPI coding - register INIT MISC bits [2,1,0] (higher priority that Resistor coding)	Safe mode code	V _{DD} status		
<6.0 k	bits [2,1,0) = [111]: verification enable: resistor at DBG pin is typically 0 kohm (RA) - Selection of SAFE mode A	А	remains ON		
typically 15 k	bits [2,1,0) = [110]: verification enable: resistor at DBG pin is typically 15 kohm (RB1) - Selection of SAFE mode B1	B1	Turn OFF 8.0 s after CAN traffic bus idle detection.		
typically 33 k	bits [2,1,0) = [101]: verification enable: resistor at DBG pin is typically 33 kohm (RB2 - Selection of SAFE mode B2	B2	Turn OFF when I/O-1 low level detected.		
typically 68 k	bits [2,1,0) = [100]: verification enable: resistor at DBG pin is typically 68 kohm (RB3) - Selection of SAFE mode B3	B3	Turn OFF 8.0 s after CAN traffic bus idle detection AND when I/O-1 low level detected.		

Exit of Safe Mode

Exit of the safe state with V_{DD} OFF is always possible by a Wake-up event: in this safe state the device can automatically awakened by CAN and I/O (if I/O Wake-up was enable by the SPI prior to enter into SAFE mode). Upon Wake-up, the device operation is resumed, and device enters in Reset mode. The SAFE pin remains active, until there is a proper read and clear of the SPI flags reporting the SAFE conditions.



SAFE Operation Flow Chart



1) bit 4 of INIT Watchdog register

2) Wake-up event: CAN, LIN or I/O-1 high level (if I/O-1 Wake-up previously enabled)

3) SPI commands: 0xDD00 or 0xDD80 to release SAFE pin

4) Recovery: reset low condition released, V_{DD} low condition released, correct SPI watchdog refresh

5) detection of 8 consecutive watchdog failures: no correct SPI watchdog refresh command occurred for duration of 8 x 256 ms.

6) Dynamic behavior: 1.0 ms reset pulse every 256 ms, due to no watchdog refresh SPI command, and device state transition

between RESET and NORMAL REQUEST mode, or INIT RESET and INIT modes.

7) 8 second timer for bus idle timeout. I/O-1 high to low transition.

Figure 26. Safe Operation Flow Chart

Conditions to Set SAFE Pin Active Low

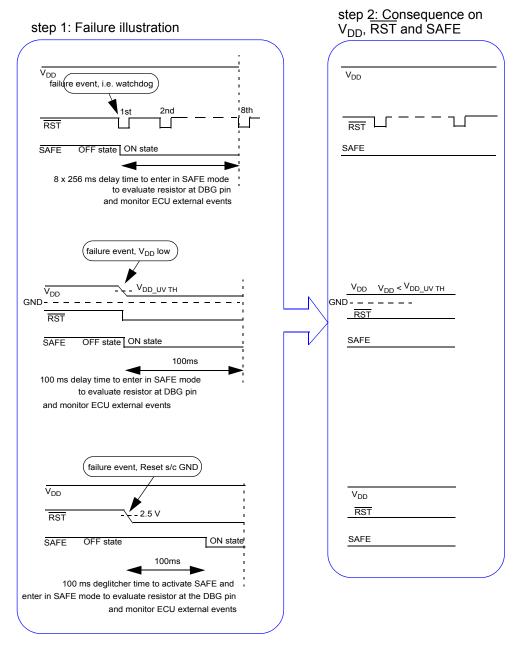
Watchdog refresh issue: SAFE activated at 1st reset pulse or at the second consecutive reset pulse (selected by bit 4, INIT watchdog register). V_{DD} low: V_{DD} < R_{ST-TH} . SAFE pin is set low at the same time as the RST pin is set low.

The $\overline{\text{RST}}$ pin is monitored to verify that reset is not clamped to a low level preventing the MCU to operate. If this is the case, the Safe mode is entered.



SAFE Mode A Illustration

Figure 27 illustrates the event and consequences when SAFE mode A is selected via the appropriate debug resistor or SPI configuration.



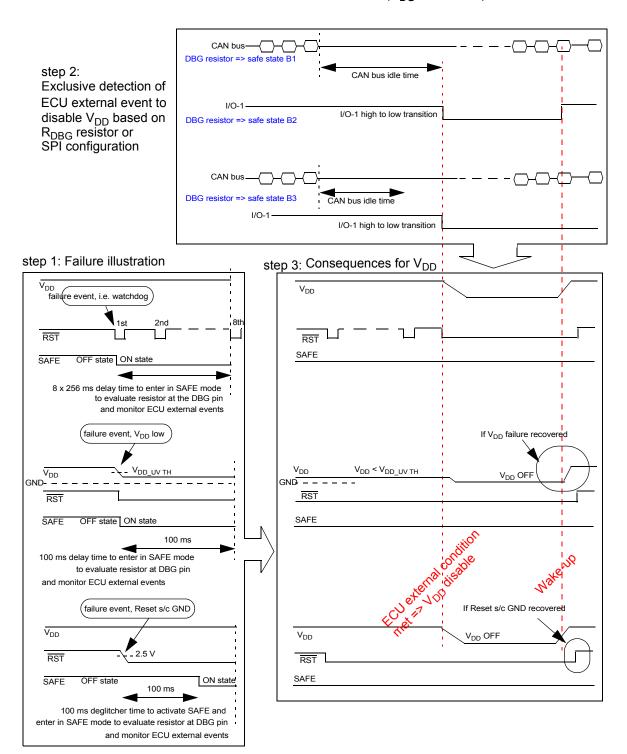
Behavior Illustration for Safe State A (R_{DG} < 6.0 kohm), or Selection by the SPI

Figure 27. SAFE Mode A Behavior Illustration

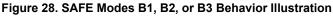


SAFE Mode B1, B2 and B3 Illustration

Figure 28 illustrates the event, and consequences when SAFE mode B1, B2, or B3 is selected via the appropriate debug resistor or SPI configuration.



Behavior illustration for the safe state B (R_{DG} > 10 kohm)



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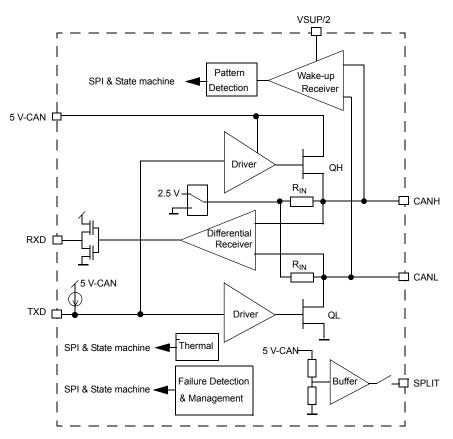


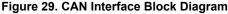
CAN INTERFACE

CAN INTERFACE DESCRIPTION

The figure below is a high level schematic of the CAN interface. It exist in a LS driver between CANL and GND, and a HS driver from CANH to 5 V-CAN. Two differential receivers are connected between CANH and CANL to detect a bus state and to Wake-up from CAN Sleep mode. An

internal 2.5 V reference provides the 2.5 V recessive levels via the matched R_{IN} resistors. The resistors can be switched to GND in CAN Sleep mode. A dedicated split buffer provides a low-impedance 2.5 V to the SPLIT pin, for recessive level stabilization.





Can Interface Supply

The supply voltage for the CAN driver is the 5 V-CAN pin. The CAN interface also has a supply pass from the battery line through the VSUP/2 pin. This pass is used in CAN Sleep mode to allow Wake-up detection.

During CAN communication (transmission and reception), the CAN interface current is sourced from the 5 V-CAN pin. During CAN LP mode, the current is sourced from the VSUP/ 2 pin.

TXD/RXD Mode

In TXD/RXD mode, both the CAN driver and the receiver are ON. In this mode, the CAN lines are controlled by the TXD pin level and the CAN bus state is reported on the RXD pin. The 5 V-CAN regulator must be ON. It supplies the CAN driver and receiver. The SPLIT pin is active and a 2.5 V biasing is provided on the SPLIT output pin.

Receive Only Mode

This mode is used to disable the CAN driver, but leave the CAN receiver active. In this mode, the device is only able to report the CAN state on the RXD pin. The TXD pin has no effect on CAN bus lines. The 5 V-CAN regulator must be ON. The SPLIT pin is active and a 2.5 V biasing is provided on the SPLIT output pin.

Operation in TXD/RXD Mode

The CAN driver will be enabled as soon as the device is in Normal mode and the TXD pin is recessive.



When the CAN interface is in Normal mode, the driver has two states: recessive or dominant. The driver state is controlled by the TXD pin. The bus state is reported through the RXD pin.

When TXD is high, the driver is set in the recessive state, and CANH and CANL lines are biased to the voltage set with 5 V-CAN divided by 2, or approx. 2.5 V.

When TXD is low, the bus is set into the dominant state, and CANL and CANH drivers are active. CANL is pulled low and CANH is pulled high.

The RXD pin reports the bus state: CANH minus the CANL voltage is compared versus an internal threshold (a few hundred mV).

If "CANH minus CANL" is below the threshold, the bus is recessive and RXD is set high.

If "CANH minus CANL" is above the threshold, the bus is dominant and RXD is set low.

The SPLIT pin is active and provides a 2.5 V biasing to the SPLIT output.

TXD/RXD Mode and Slew Rate Selection

The CAN signal slew rate selection is done via the SPI. By default and if no SPI is used, the device is in the fastest slew rate. Three slew rates are available. The slew rate controls the recessive to dominant, and dominant to recessive transitions. This also affects the delay time from the TXD pin

to the bus and from the bus to the RXD. The loop time is thus affected by the slew rate selection.

Minimum Baud Rate

The minimum baud rate is determined by the shortest TXD permanent dominant timing detection. The maximum number of consecutive dominant bits in a frame is 12 (6 bits of active error flag and its echo error flag).

The shortest TXD dominant detection time of 300 μ s lead to a single bit time of: 300 μ s / 12 = 25 μ s.

So the minimum Baud rate is $1/25 \,\mu s = 40 \,kBaud$.

Sleep Mode

Sleep mode is a reduced current consumption mode. CANH and CANL drivers are disabled and CANH and CANL lines are terminated to GND via the R_{IN} resistor, the SPLIT pin is high-impedance. In order to monitor bus activities, the CAN Wake-up receiver can be enabled. It is supplied internally from $V_{SUP/2}$.

Wake-up events occurring on the CAN <u>bus</u> pin are reporting by dedicated flags in SPI and by INT pulse, and results in a device Wake-up if the device was in LP mode.

When the device is set back into Normal mode, CANH and CANL are set back into the recessive level. This is illustrated in Figure 30.

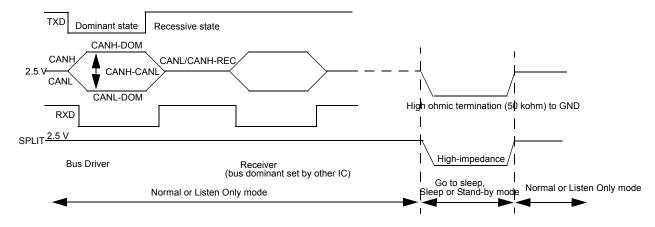


Figure 30. Bus Signal in TXD/RXD and LP Mode

Wake-up

When the CAN interface is in Sleep mode with Wake-up enabled, the CAN bus traffic is detected. The CAN bus Wake-

up is a pattern Wake-up. The Wake-up by the CAN is enabled or disabled via the SPI.



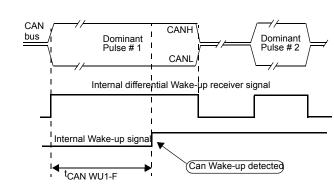
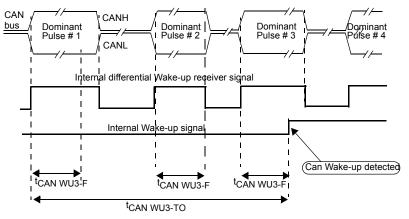


Figure 31. Single Dominant Pulse Wake-up

Pattern Wake-up

In order to Wake-up the CAN interface, the Wake-up receiver must receive a series of three consecutive valid dominant pulses, by default when the CANWU bit is low. CANWU bit can be set high by SPI and the Wake-up will occur after a single pulse duration of 2.0 μ s (typically).

A valid dominant pulse should be longer than 500 ns. The three pulses should occur in a time frame of 120 μ s, to be considered valid. When three pulses meet these conditions, the wake signal is detected. This is illustrated by the following figure.



Dominant Pulse # n: duration 1 or multiple dominant bits

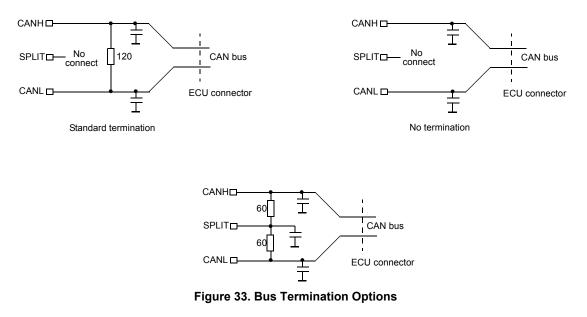
Figure 32. Pattern Wake-up - Multiple Dominant Detection

BUS TERMINATION

The device supports the two main types of bus terminations:

- Differential termination resistors between CANH and CANL lines.
- SPLIT termination concept, with the mid point of the differential termination connected to GND through a capacitor and to the SPLIT pin.
- In application, the device can also be used without termination.
- Figure 33 illustrates some of the most common terminations.





CAN BUS FAULT DIAGNOSTIC

The device includes diagnostic of bus short-circuit to GND, VBAT, and internal ECU 5.0 V. Several comparators are implemented on CANH and CANL lines. These comparators

monitor the bus level in the recessive and dominant states. The information is then managed by a logic circuitry to properly determine the failure and report it.

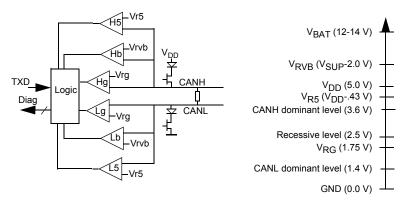


Figure 34. CAN Bus Simplified Structure Truth Table for Failure Detection

The following table indicates the state of the comparators when there is a bus failure, and depending upon the driver state.

Table 10. Failure Detection Truth Table

Failure Description	Driver Rece	essive State	Driver Dominant State			
	Lg (threshold 1.75 V)	Hg (threshold 1.75 V)	Lg (threshold 1.75 V)	Hg (threshold 1.75 V)		
No failure	1	1	0	1		
CANL to GND	0	0	0	1		
CANH to GND	0	0	0	0		
	Lb (threshold V _{SUP} -2.0 V)	Hb (threshold V _{SUP} -2.0 V)	Lb (threshold V _{SUP} -2.0 V)	Hb (threshold V _{SUP} -2.0 V)		
No failure	0	0	0	0		
CANL to VBAT	1	1	1	1		
CANH to VBAT	1	1	0	1		

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Table 10. Failure Detection Truth Table

Failure Description	Driver Rec	essive State	Driver Dominant State			
	Lg (threshold 1.75 V)	Hg (threshold 1.75 V)	Lg (threshold 1.75 V)	Hg (threshold 1.75 V)		
	L5 (threshold V _{DD} -0.43 V)	H5 (threshold V _{DD} -0.43 V)	L5 (threshold V _{DD} -0.43 V)	H5 (threshold V _{DD} -0.43 V)		
No failure	0	0	0	0		
CANL to 5.0 V	1	1	1	1		
CANH to 5.0 V	1	1	0	1		

DETECTION PRINCIPLE

In the recessive state, if one of the two bus lines are shorted to GND, VDD (5.0 V), or VBAT, the voltage at the other line follows the shorted line, due to the bus termination resistance. For example: if CANL is shorted to GND, the CANL voltage is zero, the CANH voltage measured by the Hg comparator is also close to zero.

In the recessive state, the failure detection to GND or VBAT is possible. However, it is not possible with the above implementation to distinguish which of the CANL or CANH lines are shorted to GND or VBAT. A complete diagnostic is possible once the driver is turned on, and in the dominant state.

Number of Samples for Proper Failure Detection

The failure detector requires at least one cycle of the recessive and dominant states to properly recognize the bus failure. The error will be fully detected after five cycles of the recessive-dominant states. As long as the failure detection circuitry has not detected the same error for five recessive-dominant cycles, the error is not reported.

BUS CLAMPING DETECTION

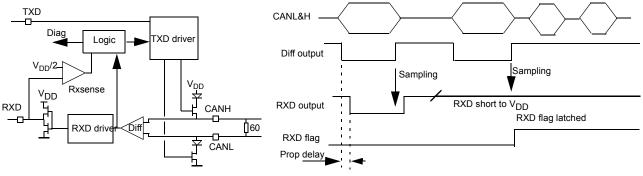
If the bus is detected to be in dominant for a time longer than (T_{DOM}) , the bus failure flag is set and the error is reported in the SPI.

This condition could occur when the CANH line is shorted to a high-voltage. In this case, current will flow from the high-voltage short-circuit, through the bus termination resistors (60 Ω), into the SPLIT pin (if used), and into the device CANH and CANL input resistors, which are terminated to internal 2.5 V biasing or to GND (Sleep mode).

Depending upon the high-voltage short-circuit, the number of nodes, usage of the SPLIT pin, R_{IN} actual resistor and mode state (Sleep or Active) the voltage across the bus termination can be sufficient to create a positive dominant voltage between CANH and CANL, and the RXD pin will be low. This would prevent start of any CAN communication and thus, proper failure identification requires five pulses on TXD. The bus dominant clamp circuit will help to determine such failure situation.

RXD Permanent Recessive Failure (does not apply to "C version")

The aim of this detection is to diagnose an external hardware failure at the RXD output pin and ensure that a permanent failure at RXD does not disturb the network communication. If RXD is shorted to a logic high signal, the CAN protocol module within the MCU will not recognize any incoming message. In addition, it will not be able to easily distinguish the bus idle state and can start communication at any time. In order to prevent this, RXD failure detection is necessary. When a failure is detected, the RXD high flag is set and CAN switches to receive only mode.



The RXD flag is not the RXPR bit in the LPC register, and neither is the CANF in the INTR register.

Figure 35. RXD Path Simplified Schematic, RXD Short to V_{DD} Detection

Implementation for Detection

The implementation senses the RXD output voltage at each low to high transition of the differential receiver. Excluding the internal propagation delay, the RXD output should be low when the differential receiver is low. When an external short to VDD at the RXD output, RXD will be tied to a high level and can be detected at the next low to high transition of the differential receiver.

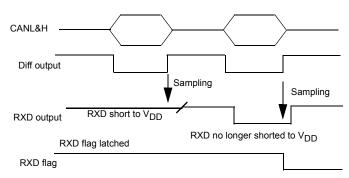
As soon as the RXD permanent recessive is detected, the RXD driver is deactivated.



Once the error is detected the driver is disabled and the error is reported via SPI in CAN register.

Recovery Condition

The internal recovery is done by sampling a correct low level at TXD as shown in the following illustration.



The RXD flag is not the RXPR bit in the LPC register, and neither is the CANF in the INTR register.

Figure 36. RXD Path Simplified Schematic, RXD Short to V_{DD} Detection

TXD PERMANENT DOMINANT

Principle

If the TXD is set to a permanent low level, the CAN bus is set into dominant level, and no communication is possible. The device has a TXD permanent timeout detector. After the timeout (T_{DOUT}), the bus driver is disabled and the bus is released into a recessive state. The TXD permanent flag is set.

Recovery

The TXD permanent dominant is used and activated when there is a TXD short to RXD. The recovery condition for a TXD permanent dominant (recovery means the re-activation of the CAN drivers) is done by entering into a Normal mode controlled by the MCU or when TXD is recessive while RXD change from recessive to dominant.

TXD TO RXD SHORT-CIRCUIT

Principle

When TXD is shorted to RXD during incoming dominant information, RXD is set to low. Consequently, the TXD pin is

low and drives CANH and CANL into a dominant state. Thus the bus is stuck in dominant. No further communication is possible.

Detection and Recovery

The TXD permanent dominant timeout will be activated and release the CANL and CANH drivers. However, at the next incoming dominant bit, the bus will then be stuck in dominant again. The recovery condition is same as the TXD dominant failure

IMPORTANT INFORMATION FOR BUS DRIVER REACTIVATION

The driver stays disabled until the failure is/are removed (TXD and/or RXD is no longer permanent dominant or recessive state or shorted) and the failure flags cleared (read). The CAN driver must be set by SPI in TXD/RXD mode in order to re enable the CAN bus driver.

LIN BLOCK

LIN INTERFACE DESCRIPTION

The physical interface is dedicated to automotive LIN subbus applications.

The interface has 20 kbps and 10 kbps baud rates, and includes as well as a fast baud rate for test and programming modes. It has excellent ESD robustness and immunity against disturbance, and radiated emission performance. It has safe behavior when a LIN bus short-to-ground, or a LIN bus leakage during LP mode.

Digital inputs are related to the device VDD pin.

POWER SUPPLY PIN (VSUP/2)

The VSUP/2 pin is the supply pin for the LIN interface. To avoid a false bus message, an undervoltage on VSUP/2 disables the transmission path (from TXD to LIN) when $V_{SUP/2}$ falls below 6.1 V.

GROUND PIN (GND)

When there is a ground disconnection at the module level, the LIN interface do not have significant current consumption on the LIN bus pin when in the recessive state.

LIN BUS PIN (LIN AND LIN1)

The LIN pin represents the single-wire bus transmitter and receiver. It is suited for automotive bus systems, and is compliant to the LIN bus specification 2.1 and SAEJ2602-2.

The LIN interface is only active during Normal mode.

Driver Characteristics

The LIN driver is a LS MOSFET with internal overcurrent thermal shutdown. An internal pull-up resistor with a serial diode structure is integrated so no external pull-up components are required for the application in a slave node. An additional pull-up resistor of 1.0 k Ω must be added when the device is used in the master node. The 1.0 k Ω pull-up resistor can be connected to the LIN pin or to the ECU battery supply.

The LIN pin exhibits no reverse current from the LIN bus line to VSUP/2, even in the event of a GND shift or VSUP/2 disconnection.

The transmitter has a 20 kbps, 10 kbps and fast baud rate, which are selected by SPI.

Receiver Characteristics

The receiver thresholds are ratiometric with the device $V_{\mbox{\scriptsize SUP/2}}$ voltage.

If the $V_{SUP/2}$ voltage goes below typically 6.1 V, the LIN bus enters into a recessive state even if communication is sent on TXD.

If LIN driver temperature reaches the overtemperature threshold, the transceiver and receiver are disabled. When the temperature falls below the overtemperature threshold, LIN driver and receiver will be automatically enabled.

DATA INPUT PIN (TXD-L, TXD-L1)

The TXD-L and TXD-L1 input pin are the MCU interface to control the state of the LIN output. When TXD-L is LOW (dominant), LIN output is LOW. When TXD-L is HIGH (recessive), the LIN output transistor is turned OFF.

This pin has an internal pull-up current source to V_{DD} to force the recessive state if the input pin is left floating.

If the pin stays low (dominant sate) more than t_{TXDDOM} , the LIN transmitter goes automatically in recessive state. This is reported by flag in LIN register.

DATA OUTPUT PIN (RXD-L AND RXD-L1)

This output pin is the MCU interface, which reports the state of the LIN bus voltage.

LIN HIGH (recessive) is reported by a high voltage on RXD, LIN LOW (dominant) is reported by a low voltage on RXD.

LIN OPERATIONAL MODES

The LIN interface have two operational modes, Transmit receiver and LIN disable modes.

TRANSMIT RECEIVE

In the TXD/RXD mode, the LIN bus can transmit and receive information.

When the 20 kbps baud rate is selected, the slew rate and timing are compatible with LIN protocol specification 2.1.

When the 10 kbps baud rate is selected, the slew rate and timing are compatible with J2602-2.

When the fast baud rate is selected, the slew rate and timing are much faster than the above specification and allow fast data transition. The LIN interface can be set by the SPI command in TXD/RXD mode, only when TXD-L is at a high level. When the SPI command is send while TXD-L is low, the command is ignored.

SLEEP MODE

This mode is selected by SPI, and the transmission path is disabled. Supply current for LIN block from $V_{SUP/2}$ is very low (typically 3.0 μ A). LIN bus is monitor to detect Wake-up



event. In the Sleep mode, the internal 725 kOhm pull-up resistor is connected and the 30 kOhm disconnected.

The LIN block can be awakened from Sleep mode by detection of LIN bus activity.

LIN Bus Activity Detection

The LIN bus Wake-up is recognized by a recessive to dominant transition, followed by a dominant level with a duration greater than 70 μ s, followed by a dominant to

Table 11. LIN Block Failure

recessive transition. This is illustrated in <u>Figures 16</u> and <u>17</u>. Once the Wake-up is detected, the event is reported to the device state machine. An INT is generated if the device is in LP V_{DD} ON mode, or V_{DD} will restart if the device was in LP V_{DD}OFF mode.

The Wake-up can be enable or disable by the SPI. Fail-safe Features

Table 11 describes the LIN block behavior when there is a failure.

FAULT	FUNCTIONNAL MODE	CONDITION	CONSEQUENCE	RECOVERY
LIN supply undervoltage		LIN supply voltage < 6.0 V (typically)	LIN transmitter in recessive State	Condition gone
TXD Pin Permanent Dominant	TXD RXD	TXD pin low for more than t_{TXDDOM}	LIN transmitter in recessive State	Condition gone
LIN Thermal Shutdown	TXD RXD	LIN driver temperature > 160 °C (typically)	LIN transmitter and receiver disabled HS turned off	Condition gone



SERIAL PERIPHERAL INTERFACE

HIGH LEVEL OVERVIEW

The device uses a 16 bits SPI, with the following arrangements:

MOSI, Master Out Slave In bits:

- bits 15 and 14 (called C1 and C0) are control bits to select the SPI operation mode (write control bit to device register, read back of the control bits, read of device flag).
- bit 13 to 9 (A4 to A0) to select the register address.
- bit 8 (P/N) has two functions: parity bit in write mode (optional, = 0 if not used), Next bit (= 1) in read mode.

• bit 7 to 0 (D7 to D0): control bits

MISO, Master In Slave Out bits:

- bits 15 to 8 (S15 to S8) are device status bits
- bits 7 to 0 (Do7 to Do0) are either extended device status bits, device internal control register content or device flags.

The SPI implementation does not support daisy chain capability.

Figure 37 is an overview of the SPI implementation.

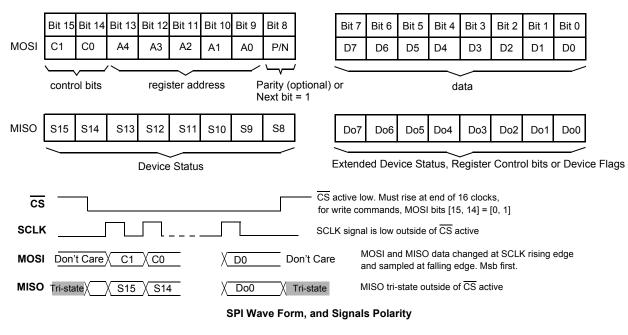


Figure 37. SPI Overview



DETAIL OPERATION

SPI Operation Deviation (does not apply to "C" version)

In some cases, the SPI write command is not properly interpreted by the device. This results in either a "non received SPI command" or a "corrupted SPI command". *Important:* Due to this, the t_{LEAD} and t_{CSLOW} parameters must be carefully acknowledged.

Only SPI write commands (starting with bits 15,14 = 01) are affected. The SPI read commands (starting with bits 15,14 = 00 or 11) are not affected.

The occurrence of this issue is extremely low and is caused by the synchronization between internal and external signals. In order to guarantee proper operation, the following steps must be taken.

 Ensure the duration of the Chip Select Low (t_{CSLOW}) state is >5.5 μs.

<u>Note:</u> In data sheet revisions prior to 7.0, this parameter is not specified and is indirectly defined by the sum of 3 parameters, t_{LEAD} + 16 x t_{PCLK} + t_{LAG} (sum = 4.06 µs).

 Ensure SPI timing parameter t_{LEAD} is a min. of 550 ns.

<u>Note:</u> In data sheet revisions prior to 7.0, the $t_{\mbox{LEAD}}$ parameter is a min of 30 ns.

3. Make sure to include a SPI read command after a SPI write command.

In case a series of SPI write commands is used, only one additional SPI read is necessary. The recommended SPI read command is "device ID read: 0x2580" so device operation is not affected (ex: clear flag). Other SPI **read** commands may also be used.

When the previous steps are implemented, the device will operate as follows:

For a given SPI write command (named SPI write 'n'):

- In case the SPI write command 'n' is not accepted, the following SPI command (named SPI 'n+1') will finish the write process of the SPI write 'n', thanks to step 2 (t_{LAG} > 550 ns) and step 3 (which is the additional SPI command 'n+1').
- By applying steps 1, 2, and 3, no SPI command is ignored. Worst case, the SPI write 'n' is executed at the time the SPI 'n+1' is sent. This will lead to a delay in device operation (delay between SPI command 'n' and 'n+1').

Note: Occurrence of an incorrect command is reduced,

thanks to step 1 (extension of t_{CSLOW} duration to >5.5 µs). Sequence examples:

Example 1:

- 0x60C0 (CAN interface control) in case this command is missed, next write command will complete it
- 0x66C0 (LIN interface control) in case this command is missed, next read command will complete it
- 0x2580 (read device ID) Additional command to complete previous LIN command, in case it was missed <u>Example 2:</u>
- 0x60C0 (CAN interface control) in case this command is missed, next write command will complete it
- 0x66C0 (LIN interface control) in case this command is missed, next read command will complete it
- 0x2100 (read CAN register content) this command will complete previous one, in case it was missed
- 0x2700 (read LIN register content)

BITS 15, 14, AND 8 FUNCTIONS

Table 12 summarizes the various SPI operation, depending upon bit 15, 14, and 8.

Control Bits MOSI[15-14], C1-C0	Type of Command	Parity/Next MOSI[8] P/N	Note for Bit 8 P/N
00	Read back of register content and block (CAN, I/O, INT, LINs) real time state. See <u>Table 38</u> .	1	Bit 8 must be set to 1, independently of the parity function selected or not selected.
01	Write to register address, to control the device operation	0	If bit 8 is set to "0": means parity not selected OR parity is selected AND parity = 0
		1	if bit 8 is set to "1": means parity is selected AND parity = 1
10	Reserved		1
11	Read of device flags form a register address	1	Bit 8 must be set to 1, independently of the parity function selected or not selected.





BITS 13-9 FUNCTIONS

The device contains several registers coded on five bits (bits 13 to 9).

Each register controls or reports part of the device's function. Data can be written to the register to control the device operation or to set the default value or behavior.

Every register can also be read back in order to ensure that it's content (default setting or value previously written) is correct.

In addition, some of the registers are used to report device flags.

Device Status on MISO

When a write operation is performed to store data or control bits into the device, the MISO pin reports a 16 bit fixed device status composed of 2 bytes: Device Fixed Status (bits 15 to 8) + extended Device Status (bits 7 to 0). In a read operation, MISO will report the Fixed device status (bits 15 to 8) and the next eight bits will be the content of the selected register.

REGISTER ADRESS TABLE

Table 13 is a list of device registers and addresses, coded with bits 13 to 9.

Address MOSI[13-9] A4A0	-9] Description		Functionality
0_000	Analog Multiplexer	MUX	 Write "device control bits" to register address. Read back register "control bits"
0_0001	Memory byte A	RAM_A	1) Write "data byte" to register address.
0_0010	Memory byte B	RAM_B	2) Read back "data byte" from register address
0_0011	Memory byte C	RAM_C	
0_0100	Memory byte D	RAM_D	
0_0101	Initialization Regulators	Init REG	1) Write "device initialization control bits" to register address.
0_0110	Initialization Watchdog	Init watchdog	2) Read back "initialization control bits" from register address
0_0111	Initialization LIN and I/O	Init LIN I/O	
0_1000	Initialization Miscellaneous functions	Init MISC	
0_1001	Specific modes	SPE_MODE	 Write to register to select device Specific mode, using "Inverted Random Code". Read "Random Code"
0_1010	Timer_A: watchdog & LP MCU consumption	TIM_A	1) Write "timing values" to register address.
0_1011	Timer_B: Cyclic Sense & Cyclic Interrupt	TIM_B	2) Read back register "timing values"
0_1100	Timer_C: watchdog LP & Forced Wake-up	TIM_C	
0_1101	Watchdog Refresh	watchdog	Watchdog Refresh Commands
0_1110	Mode register	MODE	1) Write to register to select LP mode, with optional "Inverted Random code" and select Wake-up functionality 2) Read operations: Read back device "Current mode" Read "Random Code", Leave "Debug mode"
0_1111	Regulator Control	REG	
1_0000	CAN interface control	CAN	1) Write "device control bits" to register address, to select device
1_0001	Input Output control	I/O	operation. 2) Read back register "control bits".
1_0010	Interrupt Control	Interrupt	3) Read device flags from each of the register addresses.
1_0011	LIN1 interface control	LIN1	

Table 13. Device Registers with Corresponding Address



COMPLETE SPI OPERATION

<u>Table 14</u> is a compiled view of all the SPI capabilities and options. Both MOSI and MISO information are described.

Table 14. SPI Capabilities with Options

Type of Command	MOSI/ MISO	Control bits [15-14]	Address [13-9]	Parity/Next bits [8]	Bit 7	Bits [6-0]			
Read back of "device control bits" (MOSI bit 7 = 0)	MOSI	00	address	1	0	000 0000			
OR Read specific device information (MOSI bit 7 = 1)	MISO	Device	Fixed Status	s (8 bits)		Register control bits content			
	MOSI	00	address	1	1	000 0000			
	MISO	Device Fixed Status (8 bits)			Device ID and I/Os state				
Write device control bit to address selected by bits	MOSI	01	address	(note)		Control bits			
(13-9). MISO return 16 bits device status	MISO	Device Fixed Status (8 bits)				Device Extended Status (8 bits)			
Reserved	MOSI	10			Reserved				
	MISO			ed					
Read device flags and Wake-up flags, from register address (bit 13-9), and sub address (bit 7).	MISO	11	address	Reserved	0	Read of device flags form a register address, and sub address LOW (bit 7)			
MISO return fixed device status (bit 15-8) + flags from the selected address and sub-address.	MOSI	Device	evice Fixed Status (8 bits)			Flags			
	MISO	11	address	1	1	Read of device flags form a register address, and sub address HIGH (bit 7)			
	MOSI	Device Fixed Status (8 bits)				Flags			

Note: P = 0 if parity bit is not selected or parity = 0. P = 1 if parity is selected and parity = 1.

PARITY BIT 8

Calculation

The parity is used for the write-to-register command (bit 15,14 = 01). It is calculated based on the number of logic one contained in bits 15-9,7-0 sequence (this is the entire 16 bits of the write command except bit 8).

Bit 8 must be set to 0 if the number of 1 is odd.

Bit 8 must be set to 1if the number of 1 is even.

Examples 1:

MOSI [bit 15-0] = 01 00 011 \mathbf{P} 01101001, P should be 0, because the command contains 7 bits with logic 1.

Thus the Exact command will then be: MOSI [bit 15-0] = 01 00 011 **0** 01101001

Examples 2:

MOSI [bit 15-0] = 01 00 011 P 0100 0000, P should be 1, because the command contains 4 bits with logic 1.

Thus the Exact command will then be: MOSI [bit 15-0] = 01 00 011 **1** 0100 0000

Parity Function Selection

All SPI commands and examples do not use parity functions.

The parity function is optional. It is selected by bit 6 in INIT MISC register.

If parity function is not selected (bit 6 of INIT MISC = 0), then Parity bits in all SPI commands (bit 8) must be "0".



DETAIL OF CONTROL BITS AND REGISTER MAPPING

The following tables contain register bit meaning arranged by register address, from address 0_000 to address 1_0100

MUX AND RAM REGISTERS

Table 15. MUX Register⁽³²⁾

MOSI F	irst Byte [15-8]		MOSI Second Byte, bits 7-0									
[b_15 b_	14] 0_0000 [P/N]	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0			
01	00_000 P	MUX_2	MUX_2 MUX_1 MUX_0 Int 2K I/O-att 0 0									
De	efault state	0 0 0 0 0 0 0							0			
Condi	tion for default	on for default POR, 5 V-CAN off, any mode different from Normal					_!	1				
Bits				C	escription							
b7 b6 b5	MUX_	MUX_2, MUX_1, MUX_0 - Selection of external input signal or internal signal to be measured at MUX-OUT pin										
000		All functions disable. No output voltage at MUX-OUT pin										
001	V _{DD} regi	V _{DD} regulator current recopy. Ratio is approx 1/97. Requires an external resistor or selection of Internal 2.0 K (bit 3)										
010		Device internal voltage reference (approx 2.5 V)										
011		Device internal temperature sensor voltage										
100		Voltage at I/O-0. Attenuation or gain is selected by bit 3.										
101			Voltage	at I/O-1. Attenu	uation or gain	is selected by b	oit 3.					
110		Volta	ge at VSUP/1	pin. Refer to e	lectrical table	for attenuation	ratio (approx 5))				
111		Volta	ge at VSENSE	pin. Refer to e	electrical table	for attenuation	ratio (approx 5	i)				
b4	INT 2k - Select dev	ice internal 2.0 I	kohm resistor t		and GND. Th		s the measure	ment of a voltag	ge proportior			
0	li	nternal 2.0 kohr	n resistor disal	ole. An externa	I resistor mus	t be connected	between AMU	X and GND.				
1				Internal 2.0	kohm resistor	r enable.						
b3	1/	'O-att - When I/	()	is selected with etween I/O-0 (c		00 (or 101), b3 /IUX-OUT pin	selects attenua	ation or gain				
0					-	electrical table	-	-				
		Gain is app	rox 1.3 for dev	vice with V _{DD} =	3.3 V (Ref. to	o electrical table	for exact gain	value)				
1						electrical table						
	A	ttenuation is ap	prox 6 for devi	ce with V _{DD} =	3.3 V (Ref. to	electrical table	for exact attenu	uation value)				

Notes

32. The MUX register can be written and read only when the 5V-CAN regulator is ON. If the MUX register is written or read while 5V-CAN is OFF, the command is ignored, and the MXU register content is reset to default state (all control bits = 0).

Table 16.	Internal Memory	Registers A,	, B, C, and D	D, RAM_A, RAM	/_B, RAM_C, a	ind RAM_D
-----------	-----------------	--------------	---------------	---------------	---------------	-----------

MOSI First Byte [15-8]	MOSI Second Byte, bits 7-0									
[b_15 b_14] 0_0xxx [P/N]	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0		
01 00 _ 001 P	Ram a7	Ram a6	Ram a5	Ram a4	Ram a3	Ram a2	Ram a1	Ram a0		
Default state	0	0	0	0	0	0	0	0		
Condition for default		POR								
01 00 _ 010 P	Ram b7	Ram b6	Ram b5	Ram b4	Ram b3	Ram b2	Ram b1	Ram b0		
Default state	0	0	0	0	0	0	0	0		
Condition for default		1	1	P	OR	1	1	1		
01 00 _ 011 P	Ram c7	Ram c6	Ram c5	Ram c4	Ram c3	Ram c2	Ram c1	Ram c0		
Default state	0	0	0	0	0	0	0	0		
Condition for default		1	1	P	OR	1	1	1		
01 00 _ 100 P	Ram d7	Ram d6	Ram d5	Ram d4	Ram d3	Ram d2	Ram d1	Ram d0		
Default state	0	0	0	0	0	0	0	0		
Condition for default		1	1	P	OR	1	1	1		

INIT REGISTERS

Note: these registers can be written only in INIT mode

Table 17. Initialization Regulator Registers, INIT REG (note: register can be written only in INIT mode)

MOSI First Byte [15-8] [b_15 b_14] 0_0101 [P/N]		MOSI Second Byte, bits 7-0								
		bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0	
01 00	_ 101 P	I/O-x sync	V _{DDL} rst[1]	V _{DDL} rst[0]	V _{DD} rstD[1]	V _{DD} rstD[0]	V _{AUX} 5/3	Cyclic on[1]	Cyclic on[0]	
Defa	ult state	1	0	0	0	0	0	0	0	
Condition	n for default					POR				
Bit					Descriptio	n				
b7		I/O-x sync	Determine if I/	O-1 is sensed	during I/O-0 act	ivation, when cyc	lic sense function	on is selected		
0				I	/O-1 sense any	time				
1		I/O-1 sense during I/O-0 activation								
b6, b5		$V_{DDL RST}$ [1] $V_{DDL RST}$ [0] - Select the V_{DD} undervoltage threshold, to activate \overline{RST} pin and/or INT								
00				Re	set at approx 0.	.9 V _{DD} .				
01				INT at approx	0.9 V _{DD} , Reset	at approx 0.7 V _D	D			
10				Re	eset at approx 0	.7 V _{DD}				
11				Re	set at approx 0.	.9 V _{DD} .				
b4, b3	V _{DD RS}	_{ST} D[1] V _{DD RST} [D[0] - Select th	e RST pin low	lev duration, a	after V _{DD} rises al	bove the V _{DD} u	indervoltage thre	eshold	
00					1.0 ms					
01					5.0 ms					
10					10 ms					
11		20 ms								
b2				[V _{AUX} 5/3] -	Select Vauxilar	y output voltage				
0					V _{AUX} = 3.3 \	/				



Bit	Description
1	V _{AUX} = 5.0 V
b1, b0	Cyclic on[1] Cyclic on[0] - Determine I/O-0 activation time, when cyclic sense function is selected
00	200 μ s (typical value. Ref. to dynamic parameters for exact value)
01	400 μ s (typical value. Ref. to dynamic parameters for exact value)
10	800 μ s (typical value. Ref. to dynamic parameters for exact value)
11	1600 μ s (typical value. Ref. to dynamic parameters for exact value)

Table 18. Initialization Watchdog Registers, INIT watchdog (note: register can be written only in INIT mode)

MOSI First Byte [15-8] [b_15 b_14] 0_0110 [P/N]		MOSI Second Byte, bits 7-0									
		bit 7	bit 7 bit 6 bit 5 bit 4 bit 3 bit 2								
01 00	_ 110 P	WD2INT	MCU_OC	OC-TIM	WD Safe	WD_spi[1]	WD_spi[0]	WD N/Win	Crank		
Defa	ult state	0	1	0		0	0	1	0		
Condition	n for default					POR					
Bit		Description									
b7		WD2INT - S	Select the maxin	num time delay	between INT o	ccurrence and IN	IT source read S	PI command			
0			Function disab	le. No constrai	nt between INT	occurrence and	INT source read.				
1	IN	T source read r	nust occur befor	e the remainin	g of the current	watchdog period	plus 2 complete	watchdog period	S.		
	1										
b6, b5	MCU_OC, OC-T	FIM - In LP V _{DD}	ON, select wate	chdog refresh a electrical	nd V _{DD} current parameters (ap	monitoring functi prox 1.5 mA)	onality. V _{DD_OC}	_{LP} threshold is de	fined in devic		
		In LP mode, when watchdog is not selected									
no watchdog + 00		In LP V_{DD} ON mode, V_{DD} overcurrent has no effect									
no watchdog + 01		In LP V_{DD} ON mode, V_{DD} overcurrent has no effect									
no watchdog + 10		In LP V _{DD} O	N mode, V _{DD} cu	rrent > V _{DD_OC}	C_LP threshold f	or a time > 100 μ	s (typically) is a v	wake-up event			
no watchdog + 11	In LP V _{DD} ON m	iode, V _{DD} currei	$ht > V_{DD_OC_LP}$	threshold for a total (selection	time > I_mcu_O on range from 3	C is a wake-up e .0 to 32 ms)	vent. I_mcu_OC	time is selected ir	i Timer regist		
				In LP mod	le when watchd	og is selected					
watchdog + 00	In Li	P V _{DD} ON mod	e, V _{DD} current >	V _{DD_OC_LP} th	reshold has no	effect. watchdog	refresh must occ	cur by SPI comma	nd.		
watchdog + 01	In Li	P V _{DD} ON mod	e, V _{DD} current >	V _{DD_OC_LP} th	reshold has no	effect. watchdog	refresh must occ	cur by SPI comma	nd.		
watchdog + 10		In L	.P V _{DD} ON mod	e, V _{DD} overcur	rent for a time >	· 100 μs (typically	ι) is a wake-up e	vent.			
watchdog + 11	In LP V _{DD} ON threshold fo	I mode, V _{DD} cui or a time > I_mo	rrent > V _{DD_OC} cu_OC is a wake	_{LP} threshold fo e-up event. I_m	r a time < I_mci ncu_OC time is	u_OC is a watcho selected in Timer	log refresh cond register (selecti	ition. V _{DD} current on range from 3.0	> V _{DD_OC_LP} to 32 ms)		
b4		WD Saf	e - Select the ad	ctivation of the	SAFE pin low, a	at first or second	consecutive RES	SET pulse			
0			SAFE	pin is set low	at the time of th	e RST pin low ac	tivation				
1			SAFE	pin is set low a	t the second co	nsecutive time R	ST pulse				
	1										
b3, b2			WD_spi[1] WD_spi[0] -	Select the Wat	chdog (watchdog) Operation				



Bit	Description
00	Simple Watchdog selection: watchdog refresh done by a 8 bits or 16 bits SPI
01	Enhanced 1: Refresh is done using the Random Code, and by a single 16 bits.
10	Enhanced 2: Refresh is done using the Random Code, and by two 16 bits command.
11	Enhanced 4: Refresh is done using the Random Code, and by four 16 bits command.
b1	WD N/Win - Select the Watchdog (watchdog) Window or Timeout operation
0	Watchdog operation is TIMEOUT, watchdog refresh can occur anytime in the period
1	Watchdog operation is WINDOW, watchdog refresh must occur in the open window (second half of period)
b0	Crank - Select the $V_{SUP/1}$ threshold to disable V_{DD} , while V_{SUP1} is falling toward GND
0	V_{DD} disable when $V_{SUP/1}$ is below typically 4.0 V (parameter $V_{SUP-TH1}$), and device in Reset mode
1	V_{DD} kept ON when $V_{\text{SUP/1}}$ is below typically 4.0 V (parameter $V_{\text{SUP}_{\text{TH1}}})$

Table 19. Initialization LIN and I/O Registers, INIT LIN I/O (note: register can be written only in INIT mode)

MOSI First Byte [15-8]	MOSI Second Byte, bits 7-0										
[b_15 b_14] 0_0111 [P/N]	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0			
01 00 _ 111 P	I/O-1 ovoff	LIN_T2[1]	LIN_T2[0]	LIN_T/1[1]	LIN_T/1[0]	I/O-1 out-en	I/O-0 out-en	Cyc_Inv			
Default state	0	0	0		0	0	0	0			
Condition for default					POR						

Bit	Description
b7	I/O-1 ovoff - Select the deactivation of I/O-1 when V_{DD} or V_{AUX} overvoltage condition is detected
0	Disable I/O-1 turn off.
1	Enable I/O-1 turn off, when V _{DD} or V _{AUX} overvoltage condition is detected.
b6, b5	LIN_T2[1], LIN_T2[0] - Select pin operation for I/O
00	pin is OFF
01	Reserved configuration. Do not use
10	pin operation as I/O: HS switch and Wake-up input
11	N/A
b4, b3	LIN_T/1[1], LIN_T/1[0] - Select pin operation as LIN Master pin switch or I/O
00	pin is OFF
01	pin operation as LIN Master pin switch
10	pin operation as I/O: HS switch and Wake-up input
11	N/A
b2	I/O-1 out-en- Select the operation of the I/O-1 as output driver (HS, LS)
0	Disable HS and LS drivers of pin I/O-1. I/O-1 can only be used as input.
1	Enable HS and LS drivers of pin I/O-1. Pin can be used as input and output driver.
b1	I/O-0 out-en - Select the operation of the I/O-0 as output driver (HS, LS)

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Bit	Description
0	Disable HS and LS drivers of I/O-0 can only be used as input.
1	Enable HS and LS drivers of the I/O-0 pin. Pin can be used as input and output drivers.
b0	Cyc_Inv - Select I/O-0 operation in device LP mode, when cyclic sense is selected
0	During cyclic sense active time, I/O is set to the same state prior to entering in to LP mode. During cyclic sense off time, I/O-0 is disable (HS and LS drivers OFF).
1	During cyclic sense active time, I/O is set to the same state prior to entering in to LP mode. During cyclic sense off time, the opposite driver of I/ O_0 is actively set. Example: If I/O_0 HS is ON during active time, then I/O_O LS is turned ON at expiration of the active time, for the duration of the cyclic sense period.

Table 20. Initialization Miscellaneous Functions, INIT MISC (Note: Register can be written only in INIT mode)

MOSI First Byte [15-8] [b_15 b_14] 0_1000 [P/N]		MOSI Second Byte, bits 7-0									
		bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0		
01 01_000 P		LPM w RNDM	SPI parity	INT pulse	INT width	INT flash	Dbg Res[2]	Dbg Res[1]	Dbg Res[0]		
Defa	ult state	0	0	0		0	0	0	0		
Condition	n for default					POR		·			
Bit		Description									
b7	LPM w F	RNDM - This enab	oles the usage	of random bits	2, 1 and 0 of the	e MODE register	to enter into LP	VDD OFF or LP	VDD ON.		
0			Function disat	le: the LP mode	e can be entere	d without usage	of Random Code	1			
1			Function	enabled: the L	P mode is enter	red using the Ra	ndom Code				
b6			SPI pa	rity - Select us	age of the parity	y bit in SPI write	operation				
0		F	unction disabl	e: the parity is i	not used. The p	arity bit must alw	ays set to logic 0	l.			
1			Function	n enable: the pa	arity is used, and	d parity must be	calculated.				
b5			INT pu	Ise -Select INT	pin operation: I	ow level pulse of	low level				
0			INT pin	will assert a lo	w level pulse, d	uration selected	by bit [b4]				
1				INT pin assert	a permanent lo	ow level (no pulse	e)				
	1										
b4				INT width	- Select the INT	pulse duration					
0		INT	pulse duration	is typically 100	μs. Ref. to dyn	amic parameter	table for exact va	lue.			
1		INT	pulse duration	n is typically 25	μs. Ref. to dyna	amic parameter I	able for exact val	ue.			
b3		INT	flash - Select	INT pulse gene			Period in Flash m	ode			
		Function or			Function disat		when dovice in F	loop mode			
						valenuog Peniod	when device in F	10011 11100E.			
o2, b1, b0	Dbg Res[2], Db	og Res[1], Dbg R	es[0] - Allow v	erification of the	external resisto value. ⁽³³⁾	or connected at E	BG pin. Ref. to p	arametric table f	or resistor rang		
0xx					Function disat	ole					
100		100 verifica	ation enable: r	esistor at DBG	pin is typically 6	8 kohm (RB3) -	Selection of SAFI	E mode B3			
101		101 verific	ation enable: r	esistor at DBG	pin is typically 3	33 kohm (RB2 - \$	Selection of SAFE	E mode B2			
110		110 verification enable: resistor at DBG pin is typically 15 kohm (RB1) - Selection of SAFE mode B1									

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Bit	Description
111	111 verification enable: resistor at DBG pin is typically 0 kohm (RA) - Selection of SAFE mode A

Notes

33. Bits b2,1 and 0 allow the following operation:

First, check the resistor device has detected at the DEBUG pin. If the resistor is different, bit 5 (Debug resistor) is set in INTerrupt register (Ref. to device flag table).

Second, over write the resistor decoded by device, to set the SAFE mode operation by SPI. Once this function is selected by bit 2 = 1, this selection has higher priority than "hardware", and device will behave according to b2,b1 and b0 setting

SPECIFIC MODE REGISTER

Table 21. Specific Mode Register, SPE_MODE

MOSI First Byte [15-8]	MOSI Second Byte, bits 7-0										
[b_15 b_14] 01_001 [P/N]	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0			
01 01_001 P	Sel_Mod[1]	Sel_Mod[0]	Rnd_C5b	Rnd_C4b	Rnd_C3b	Rnd_C2b	Rnd_C1b	Rnd_C0b			
Default state	0	0	0		0	0	0	0			
Condition for default		POR									

Bit	Description
b7, b6	Sel_Mod[1], Sel_Mod[0] - Mode selection: these 2 bits are used to select which mode the device will enter upon a SPI command.
00	RESET mode
01	INIT mode
10	FLASH mode
11	N/A

b5....b0 [Rnd_C4b... Rnd_C0b] - Random Code inverted, these six bits are the inverted bits obtained from the SPE MODE Register read command.

The SPE MODE Register is used for the Following Operation

- Set the device in RESET mode, to exercise or test the RESET functions.

- Go to INIT mode, using the Secure SPi command.

- Go to FLASH mode (in this mode the watchdog timer can be extended up to 32 s).

- Activate the SAFE pin by S/W.

This mode (called Special mode) is accessible from the secured SPI command, which consist of 2 commands:

1) reading a random code and

2) then write the inverted random code plus mode selection or SAFE pin activation:

Return to INIT mode is done as follow (this is done from Normal mode only):

1) Read random code:

MOSI : 0001 0011 0000 0000 [Hex:0x 13 00]

MISO report 16 bits, random code are bits (5-0)

miso = xxxx xxxx xxR5 R4 R3 R2 R1 R0 (RXD = 6 bits random code)

2) Write INIT mode + random code inverted

MOSI : 0101 0010 01 Ri5 Ri4 Ri3 Ri2 Ri1 Ri0 [Hex 0x 52 HH] (R_{IX} = random code inverted)

MISO : xxxx xxxx xxxx (don't care)

SAFE pin activation: SAFE pin can be set low, only in INIT mode, with following commands:

1) Read random code:

MOSI: 0001 0011 0000 0000 [Hex:0x 13 00]

MISO report 16 bits, random code are bits (5-0)

miso = xxxx xxxx xxR5 R4 R3 R2 R1 R0 (RXD = 6 bits random code)

2) Write INIT mode + random code bits 5:4 not inverted and random code bits 3:0 inverted

MOSI : 0101 0010 01 R5 R4 Ri3 Ri2 Ri1 Ri0 [Hex 0x 52 HH] (R_{IX} = random code inverted)

MISO : xxxx xxxx xxxx xxxx (don't care)

Return to Reset or Flash mode is done similarly to the go to INIT mode, except that the b7 and b6 are set according to the table above (b7, b6 = 00 - go to reset, b7, b6 = 10 - go to Flash).



TIMER REGISTERS

MOSI First Byte [15-8]	MOSI Second Byte, bits 7-0									
[b_15 b_14] 01_010 [P/N]	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0		
01 01_010 P	I_mcu[2]	I_mcu[1]	I_mcu[1]	watchdog Nor[4]	W/D_N[4]	W/D_Nor[3]	W/D_N[2]	W/D_Nor[0]		
Default state	0	0	0	1	1	1	1	0		
Condition for default					POR					

Table 22. Timer Register A, LP V_{DD} Overcurrent & Watchdog Period Normal mode, TIM_A

LP V _{DD} Overcurrent (ms)							
b7	b6, b5						
57	00	01	10	11			
0	3 (def)	6	12	24			
1	4	8	16	32			

		Wat	chdog Peric	d in Device	Normal Mod	de (ms)		
b4, b3	b2, b1, b0							
54, 50	000	001	010	011	100	101	110	111
00	2.5	5	10	20	40	80	160	320
01	3	6	12	24	48	96	192	384
10	3.5	7	14	28	56	112	224	448
11	4	8	16	32	64	128	256 (def)	512

Table 23. Timer Register B, Cyclic Sense and Cyclic INT, in Device LP Mode, TIM_B

MOSI First Byte [15-8]	MOSI Second Byte, bits 7-0								
[b_15 b_14] 01_011 [P/N]	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0	
01 01_011 P	Cyc-sen[3]	Cyc-sen[2]	Cyc-sen[1]	Cyc-sen[0]	Cyc-int[3]	Cyc-int[2]	Cyc-int[1]	Cyc-int[0]	
Default state	0	0	0	0	0	0	0	0	
Condition for default					POR				

			(Cyclic Sense (ms)					
b7	b6, b5, b4									
57	000	001	010	011	100	101	110	111		
0	3	6	12	24	48	96	192	384		
1	4	8	16	32	64	128	256	512		
			C	yclic Interrupt	(ms)					
b3				b2,	b1, b0					
55	000	001	010	011	100	101	110	111		
0	6 (def)	12	24	48	96	192	384	768		
1	8	16	32	64	128	258	512	1024		

MOSI First Byte [15-8] [b_15 b_14] 01_100 [P/N]	MOSI Second Byte, bits 7-0								
	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0	
01 01_ 100 P	WD-LP-F[3]	WD-LP-F[2]	WD-LP-F[1]	WD-LP-F[0]	FWU[3]	FWU[2]	FWU[1]	FWU[0]	
Default state	0	0	0	0	0	0	0	0	
Condition for default					POR				

Table 24. Timer Register C, Watchdog LP Mode or Flash Mode and Forced Wake-up Timer, TIM_C

Table 25. Typical Timing Values

			Watchdog	in LP V _{DD} C	ON Mode (ms)			
b6, b5, b4								
57	000	001	010	011	100	101	110	111
0	12	24	48	96	192	384	768	1536
1	16	32	64	128	256	512	1024	2048
			Watchd	log in Flash	Mode (ms)			
b7				b6,	b5, b4			
57	000	001	010	011	100	101	110	111
0	48 (def)	96	192	384	768	1536	3072	6144
1	256	512	1024	2048	4096	8192	16384	32768

	Forced Wake-up (ms)							
b3	b2, b1, b0							
	000	001	010	011	100	101	110	111
0	48 (def)	96	192	384	768	1536	3072	6144
1	64	128	258	512	1024	2048	4096	8192

WATCHDOG AND MODE REGISTERS

Table 26. Watchdog Refresh Register, watchdog⁽³⁴⁾

MOSI First Byte [15-8] [b_15 b_14] 01_101 [P/N]	MOSI Second Byte, bits 7-0								
	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0	
01 01_ 101 P	0	0	0	0	0	0	0	0	
Default state	0	0	0	0	0	0	0	0	
Condition for default		I			POR	1	1		

The Simple Watchdog Refresh command is in hexadecimal: 5A00. This command is used to refresh the watchdog and also to transition from INIT mode to Normal mode, and from Normal Request mode to Normal mode (after a wake-up of a reset)

Table 27. MODE Register, MODE

MOSI First Byte [15-8]	MOSI Second Byte, bits 7-0							
[b_15 b_14] 01_110 [P/N]	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
01 01_ 110 P	mode[4]	mode[3]	mode[2]	mode[1]	mode[0]	Rnd_b[2]	Rnd_b[1]	Rnd_b[0]
Default state	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A



Table 28. LP V _D	D OFF Selection and I	FWU / Cyclic Sense Selection
-----------------------------	-----------------------	------------------------------

b7, b6, b5, b4, b3	FWU	Cyclic Sense
0 1100	OFF	OFF
0 1101	OFF	ON
0 1110	ON	OFF
0 1111	ON	ON

Table 29. LP V_{DD} ON Selection and Operation Mode

b7, b6, b5, b4, b3	FWU	Cyclic Sense	Cyclic INT	Watchdog
1 0000	OFF	OFF	OFF	OFF
1 0001	OFF	OFF	OFF	ON
1 0010	OFF	OFF	ON	OFF
1 0011	OFF	OFF	ON	ON
1 0100	OFF	ON	OFF	OFF
1 0101	OFF	ON	OFF	ON
1 0110	OFF	ON	ON	OFF
1 0111	OFF	ON	ON	ON
1 1000	ON	OFF	OFF	OFF
1 1001	ON	OFF	OFF	ON
1 1010	ON	OFF	ON	OFF
1 1011	ON	OFF	ON	ON
1 1100	ON	ON	OFF	OFF
1 1101	ON	ON	OFF	ON
1 1110	ON	ON	ON	OFF
1 1111	ON	ON	ON	ON
b2, b1, b0		ed, these 3bits are the inve its are optional and must b in <u>Table 20]</u>		

Prior to enter in LP V_{DD} ON or LP V_{DD} OFF, the Wake-up flags must be cleared or read.

This is done by the following SPI commands (See Table <u>38, Device Flag, I/O Real Time and Device Identification</u>):

- 0xE100 for CAN Wake-up clear
- 0xE380 for I/O Wake-up clear
- 0xE700 for LIN1 Wake-up clear

If Wake-up flags are not cleared, the device will enter into the selected LP mode and immediately Wake-up. In addition, the CAN failure flags (i.e. CAN_F and CAN_UF) must be cleared in order to meet the low power current consumption specification. This is done by the following SPI command:

0xE180 (read CAN failure flags)

When the device is in LP V_{DD} ON mode, the Wake-up by a SPI command uses a write to "Normal Request mode", 0x5C10.

Mode Register Features

The mode register includes specific functions and a "global SPI command" that allow the following:

- read device current mode
- read device Debug status
- read state of SAFE pin
- leave Debug state
- release or turn off SAFE pin
- read a 3 bit Random Code to enter in LP mode

These global commands are built using the MODE register address bit [13-9], along with several combinations of bit [15-14] and bit [7]. Note, bit [8] is always set to 1.



Entering into LP Mode Using Random Code

- LP mode using Random Code must be selected in INIT mode via bit 7 of the INIT MISC register.

- In Normal mode, read the Random Code using 0x1D00 or 0x1D80 command. The 3 Random Code bits are available on MISO bits 2,1 and 0.

- Write LP mode by inverting the 3 random bits.

Example - Select LP VDD OFF without cyclic sense and FWU:

1. in hex: 0x5C60 to enter in LP VDD OFF mode without using the 3 random code bits.

2. if Random Code is selected, the commands are:

- Read Random Code: 0x1D00 or 0x1D80,

MISO report in binary: bits 15-8, bits 7-3, Rnd_[2], Rnd_[1], Rnd_[0].

- Write LP VDD OFF mode, using Random Code inverted: in binary: 0101 1100 0110 0 Rnd_b[2], Rnd_b[1], Rnd_b[0]. <u>Table 30</u> summarizes these commands

Table 30. Device Modes

Global commands and effects								
Read device current mode, Leave debug mode. Keep SAFE pin as is. MOSI in hexadecimal: 1D 00	MOSI	bits 15-14	bits 13-9	bit 8	bit 7	bits 6-0		
		00	01 110	1	0		000 0000	
	MISO	bit 15-8		bit 7-3		bit 2-0		
		Fix Status		device current mode		Random code		
Read device current mode Release SAFE pin (turn OFF). MOSI in hexadecimal: 1D 80	MOSI	bits 15-14	bits 13-9	bit 8	bit 7	bits 6-0		
		00	01 110	1	1		000 0000	
	MISO	bit 15-8		bit 7-3		bit 2-0		
		Fix Status device current mode		Random code				
Read device current mode, Leave debug mode. Keep SAFE pin as is. MOSI in hexadecimal: DD 00 MISO reports Debug and SAFE state (bits 1,0)	MOSI	bits 15-14	bits 13-9	bit 8	bit 7	bits 6-0		
		11	01 110	1	0	000 0000		
	MISO	bit 15-8		bit	7-3	bit 2	bit 1	bit 0
		Fix Status		device current mode		Х	SAFE	DEBU
Read device current mode, Keep DEBUG mode Release SAFE pin (turn OFF). MOSI in hexadecimal: DD 80 MISO reports Debug and SAFE state (bits 1,0)	MOSI	bits 15-14	bits 13-9	bit 8	bit 7	bits 6-0		
		11	01 110	1	1	000 0000		
	MISO	bit 15-8		bit 7-3		bit 2	bit 1	bit C
		Fix Status		device current mode		х	SAFE	DEBU

<u>Table 31</u> describes MISO bits 7-0, used to decode the device's current mode.

Table 31. MISO bits 7-3

Device current mode, any of the above commands					
b7, b6, b5, b4, b3	MODE				
0 0000	INIT				
0 0001	FLASH				
0 0010	Normal Request				
0 0011	Normal mode				
1 XXXX	Low Power mode (Table 29)				

Table 32 describes the SAFE and DEBUG bit decoding.

Table 32. SAFE and DEBUG status

SAFE and DEBUG bits				
b1	description			
0	SAFE pin OFF, not activated			
1	SAFE pin ON, driver activated.			
b0	description			
0	Debug mode OFF			
1	Debug mode Active			



REGULATOR, CAN, I/O, INT AND LIN REGISTERS Table 33. Regulator Register

MOSI Fir	st Byte [15-8]				MOSI Seco	nd Byte, bits 7-	0		
	4] 01_111 [P/N]	bit 7	bit 7 bit 6 bit 5 bit 4 bit 3 bi						bit 0
01 0	01_111 P	V _{AUX} [1]	V _{AUX} [0]	-	5V-can[1]	5V-can[0]	V _{DD} bal en	V _{DD} bal auto	V _{DD} OFF er
Defa	ault state	0	0	N/A	0	0	N/A	N/A	N/A
Conditio	on for default	P	OR		Р	OR			
Bits			4		Descriptio	n	4	-H	L
b7 b6	V _{AUX} [1], V _{AU}	x[0] - Vauxila	ry regulator co	ntrol					
00	Regulator OF	F							
01	Regulator ON detected after			vercurrent (OC) monitoring	I flags not repo	orted. V _{AUX} is c	lisabled when I	JV or OC
10	Regulator ON 1.0 ms blanki		e (UV) and ove	ercurrent (O	C) monitoring f	lags active. V _A	_{UX} is disabled v	when UV or OC	detected aft
11	Regulator ON 25 µs blanking		e (UV) and ove	ercurrent (O	C) monitoring f	lags active. V _A	_{UX} is disabled v	when UV or OC	detected aft
b4 b3	5 V-can[1], 5 V-can[0] - 5V-CAN regulator control								
00	Regulator OF	F							
01	-	•			ge (UV) and ov ault when in De	•	;) monitoring fla	ags not reporte	d. 1.0 ms
10	Regulator ON for UV and O		tection active.	Undervoltag	je (UV) and ove	ercurrent (OC)	monitoring flag	s active. 1.0 ms	s blanking tin
11	Regulator ON time.	l. Thermal pro	tection active.	Undervolta	ge (UV) and ov	ercurrent (OC)) monitoring fla	gs active after 2	25 μs blankir
b2	V _{DD} bal en -	Control bit to	Enable the V_D	_D external b	allast transisto	r			
0	External V _{DD}	ballast disable	e						
1	External V _{DD}	ballast Enable	9						
b1	V _{DD} bal auto	- Control bit t	o automaticall	y Enable the	e V _{DD} external	ballast transis	tor, if V_{DD} is >	typically 60 mA	<u>۱</u>
0	Disable the au	utomatic activ	ation of the ex	ternal balla	st				
1					st, if V _{DD} > typic				
b0	V _{DD} OFF en	- Control bit to	allow transition	on into LP V	DD OFF mode	(to prevent V _C	_{DD} turn OFF)		
0	Disable Usag	e of LP V _{DD} C	OFF mode						
	Enable Usage								



Table 34. CAN Register⁽³⁵⁾

MOSI Fir	st byte [15-8]				MOSI Sec	ond Byte, bits 7-0					
b_15 b_14	10_000 [P/N]	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0		
01 1	0_000P	CAN mod[1]	CAN mod[0]	Slew[1]	Slew[0]	Wake-up 1/3	-	-	CAN int		
Default state		1	0	0	0	0	-	-	0		
Conditio	on for default	nc	note POR POR POR POI								
Bits					Descriptio	n					
b7 b6	CAN mod[1]	, CAN mod[0]	- CAN interfa	ce mode cor	ntrol, Wake-u	p enable / disable	9				
00	CAN interfac	e in Sleep moo	de, CAN Wake	e-up disable.							
01	CAN interfac	N interface in receive only mode, CAN driver disable.									
10		e is in Sleep m p is reported b				-P mode, lode, CAN Wake-	up reported t	by INT.			
11	CAN interfac	e in transmit a	e in transmit and receive mode.								
b5 b4	Slew[1] Slev	v[0] - CAN driv	ver slew rate s	election							
00/11	FAST										
01	MEDIUM										
10	SLOW										
b3	Wake-up 1/3	- Selection of	CAN Wake-u	p mechanisn	n						
0	3 dominant p	ulses Wake-u	p mechanism								
1	Single domin	ant pulse Wak	e-up mechani	sm							
b0	CAN INT - S	elect the CAN	failure detecti	on reporting							
0	Select INT ge	eneration whe	n a bus failure	is fully ident	ified and dec	oded (i.e. after 5	dominant pul	ses on TxCAN	1)		
1	Select INT generation as soon as a bus failure is detected, event if not fully identified										

Notes

35. The first time the device is set to Normal mode, the CAN is in Sleep Wake-up enabled (bit7 = 1, bit 6 =0). The next time the device is set in Normal mode, the CAN state is controlled by bits 7 and 6.



Table 35. I/O Register

	MOSI First byte [15-8]				MOSI Seco	nd Byte, bits 7-	0					
[b_15 b_14	10_001 [P/N]	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0			
01 1	0_001P	I/O-3 [1]	I/O-3 [0]	I/O-2 [1]	I/O-2 [0]	I/O-1 [1]	I/O-1 [0]	I/O-0 [1]	I/O-0 [0]			
Defa	ault state	0	0	0	0	0	0	0	0			
Conditio	on for default		POR									
Bits					Description	1						
b7 b6	I/O-3 [1], I/O-	3 [0] - I/O-3 pi	n operation									
00	I/O-3 driver d	isable, Wake-	up capability	disable								
01	I/O-3 driver di	O-3 driver disable, Wake-up capability enable.										
10	I/O-3 HS drive	/O-3 HS driver enable.										
11	I/O-3 HS drive	I/O-3 HS driver enable.										
b5 b4	I/O-2 [1], I/O-2	I/O-2 [1], I/O-2 [0] - I/O-2 pin operation										
00	I/O-2 driver d	I/O-2 driver disable, Wake-up capability disable										
01	I/O-2 driver di	isable, Wake-	up capability	enable.								
10	I/O-2 HS drive	er enable.										
11	I/O-2 HS drive	er enable.										
b3 b2	I/O-1 [1], I/O-	1 [0] - I/O-1 pi	n operation									
00	I/O-1 driver d	isable, Wake-	up capability	disable								
01	I/O-1 driver di	isable, Wake-	up capability	enable.								
10	I/O-1 LS drive	er enable.										
11	I/O-1 HS drive	er enable.										
b1 b0	I/O-0 [1], I/O-	0 [0] - I/O-0 pi	n operation									
00	I/O-0 driver d	isable, Wake-	up capability	disable								
01	I/O-0 driver di	isable, Wake-	up capability	enable.								
10	I/O-0 LS drive	er enable.										
11	I/O-0 HS drive	er enable.										



Table 36. INT Register

MOSI Fir	rst byte [15-8]				MOSI Secor	nd Byte, bits 7-	0				
	4] 10_010 [P/N]	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0		
01 1	10_010P	CAN failure	MCU req	0	LIN1fail	I/O	SAFE	-	Vmon		
Defa	ault state	0	0	0	0	0	0	0	0		
Conditio	on for default				· · ·	POR		L	·		
Bits					Description						
b7		- control bit for 2HIGH, and C				or VSUP, CA	N overcurrent,	Driver Overter	mp, TXD-PD		
0	INT disable	INT disable									
1	INT enable.										
b6	MCU req - C	ontrol bit to rec	uest an INT.	INT will occu	ur once when t	he bit is enabl	e				
0	INT disable										
1	INT enable.										
b4	LIN/1 fail - C	control bit to en	able INT wher	n of failure o	n LIN1 interfac	e					
0	INT disable										
1	INT enable.										
b3	I/O - Bit to co	ontrol I/O interru	uption: I/O fail	ure							
0	INT disable										
1	INT enable.										
b2	SAFE - Bit to resistor mism	enable INT wh natch, RST terr	nen of: Vaux o ninal short to '	vervoltage, ^v VDD, MCU	VDD overvoltac request INT. ⁽³⁷	ge, VDD Temp)	o pre-warning, \	/DD undervolt	age ⁽³⁶⁾ , SAF		
0	INT disable										
1	INT enable.										
b0		le interruption b _{ELOW} , 5V-CAN					_{AUX} , 5 V-CAN, ' ent	V _{DD} (I _{DD} Over	current, V _{SU}		
0	INT disable										

Notes

36. If VDD undervoltage is set to 70% of VDD, see bits b6 and b5 in Table 15 on page 64.

37. Bit 2 is used in conjunction with bit 6. Both bit 6 and bit 2 must be set to 1 to activate the MCU INT request.



Table 37. LIN/1 Register⁽³⁹⁾

MOSI Firs	st byte [15-8]	MOSI Second Byte, bits 7-0							
[b_15 b_14] 10_010 [P/N]	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
01 10	0_011P	LIN mode[1]	LIN mode[0]	Slew rate[1]	Slew rate[0]	-	LIN T/1 on	-	V _{SUP} ext
Defa	ult state	0	0	0	0	0	0	0	0
Conditio	n for default		L	L		POR	·		
Bits					Description				
b7 b6	LIN mode [1]], LIN mode [0]	- LIN/1 interf	ace mode co	ntrol, Wake-u	p enable / dis	able		
00	LIN/1 disable	e, Wake-up ca	pability disabl	е					
01	not used								
10	LIN/1 disable	e, Wake-up ca	pability enable	e					
11	LIN/1 Transr	nit Receive mo	ode ⁽³⁸⁾						
	4								
b5 b4	Slew rate[1],	Slew rate[0] L	IN/1 slew rate	e selection					
00	Slew rate for	20 kbit/s bauc	l rate						
01	Slew rate for	10 kbit/s bauc	l rate						
10	Slew rate for	fast baud rate	•						
11	Slew rate for	fast baud rate	•						
	1								
b2	LIN T/1 on								
0	LIN/1 termina	ation OFF							
1	LIN/1 termina	ation ON							
b0	V _{SUP} ext								
0	LIN goes rec	essive when d	levice V _{SUP/2}	is below typic	cally 6.0 V. Th	is is to meet	J2602 specificatio	on	
1	LIN continues operation below V _{SUP/2} 6.0 V, until 5 V-CAN is disabled.								

Notes

38. The LIN interface can be set in TXD/RXD mode only when the TXD-L input signal is in recessive state. An attempt to set TXD/RXD mode, while TXD-L is low, will be ignored and the LIN interface remains disabled.

39. In order to use the LIN interface, the 5V-CAN regulator must be set to ON.



FLAGS AND DEVICE STATUS

DESCRIPTION

The table below is a summary of the device flags, I/O real time level, device Identification, and includes examples of SPI commands (SPI commands do not use parity functions). They are obtained using the following commands.

This command is composed of the following:

bits 15 and 14:

• [1 1] for failure flags

- - [0 0] for I/O real time status, device identification and CAN LIN driver receiver real time state.
- bit 13 to 9 are the register address from which the flags is to be read.
- bit 8 = 1 (this is not parity bit function, as this is a read command).

When a failure event occurs, the respective flag is set and remains latched until it is cleared by a read command (provided the failure event has recovered).

Bits	15-14	13-9	8		7	6	5	4	3	2	1	0
		MOSI bits	15-7			I	1	I		I	I	
MOSI	bits [15, 14]	Address [13-9]	bit 8	bit 7	-		Next 7 MC	OSI bits (bits 6.	0) should be "(000_0000"		
	8 Bits	Device Fix	ed Stat	us			MISO bits	[7-0], device	response on	MISO pin		
MISO		(bits 15			bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
REG	11	0_1111 REG	1	0	V _{AUX_LOW}	V _{AUX_overCUR} RENT	5V _{-CAN} _ THERMAL SHUTDOWN	5V _{-CAN} _ UV	5V _{-CAN} _ overCURRENT	V _{SENSE} _ LOW	V _{SUP_} underVOLTAGE	I _{DD-OC-} NORMAL MODE
	11			1	-	-	-	V _{DD} THERMAL SHUTDOWN		R _{ST_LOW} (<100 ms)	V _{SUP_} BATFAIL	I _{DD-OC-LP} V _{DD} ON MODE
					Hexa SPI com	nmands to get \	/reg Flags: MC	DSI 0x DF 00, a	and MOSI Ox I	DF 80		
CAN	11	1_0000 CAN	1	0	CAN Wake-up	-	CAN Overtemp	RXD low ⁽⁴⁰⁾	Rxd high	TXD dom	Bus Dom clamp	CAN Overcurrent
				1	CAN_UF	CAN_F	CANL to V _{BAT}	CANL to V _{DD}	CANL to GND	CANH to V _{BAT}	CANH to V _{DD}	CANH to GND
			I		Hexa SPI con	nmands to get	CAN Flags: M	OSI 0x E1 00,	and MOSI 0x E	E1 80	1	
	00	1_0000 CAN	1	1	CAN Driver State	CAN Receiver State	CAN WU en/dis	-	-	-	-	-
			1I		Hexa S	PI commands to	o get CAN rea	l time status: N	1OSI 0x 21 80	I	1	
I/O	11	1_0001 I/O	1	0	HS3 short to GND	HS2 short to GND	SPI parity error	CSB low >2.0 ms	V _{SUP/2-UV}	V _{SUP/1-OV}	I/O_O thermal	watchdog flash mode 50%
				1	I/O_1-3 Wake-up	I/O_0-2 Wake-up	SPI Wake-up	FWU	INT service Timeout	LP V _{DD} OFF	Reset request	Hardware Leave Debug
				Hexa S	PI commands	to get I/O Flag	s and I/O Wak	e-up: MOSI 0x	E3 00, and M	OSI 0x E3 80		
	00	1_0001 I/O	1	1		I/O_3 state		I/O_2 state		I/O_1 state		I/O_0 state
					Hexa	SPI commands	to get I/O rea	time level: MC	OSI 0x 23 80			
SAFE	11	1_0010 SAFE	1	0	INT request	RST high	DBG resistor	V _{DD} temp Pre-warning	V _{DD} UV	V _{DD} Overvoltage	V _{AUX_overVOL} TAGE	-
				1	-	-	-	V _{DD} low >100 ms	V _{DD} low RST	RST low >100 ms	multiple Resets	watchdog refresh failure
		-	•	He	xa SPI comma	nds to get INT a	and RST Flag	s: MOSI 0x E5	00, and MOSI	0x E5 80		
	00	1_0010 SAFE	1	1	V _{DD} (5.0 V or 3.3 V)	device p/n 1	device p/n 0	id4	id3	id2	id1	id0
			·	exam		SPI commands [7-0] = 1011 01	•			(Pass 3.3)		

Table 38. Device Flag, I/O Real Time and Device Identification



Table 38. Device Flag, I/O Real Time and Device Identification (continued)

LIN/1	11	1_0011 LIN 1	1	0	-	LIN1 Wake-up	LIN1 Term short to GND	LIN 1 Overtemp	RXD1 low	RXD1 high	TXD1 dom	LIN1 bus dom clamp
		Hexa SPI commands to get LIN 2 Flags: MOSI 0x E7 00										
	00	1_0011 LIN 1	1	1	LIN1 State	LIN1 WU en/dis	-	-	-	-	-	-
		Hexa SPI commands to get LIN1 real time status: MOSI 0x 27 80										

Notes

40. Not available on "C" versions

	Flag	Description
REG		
V _{AUX_LOW}	Description	Reports that V_{AUX} regulator output voltage is lower than the V_{AUX_UV} threshold.
	Set / Reset condition	Set: V_{AUX} below threshold for t >100 μ s typically. Reset: V_{AUX} above threshold and flag read (SPI)
V _{AUX_overCUR}	Description	Report that current out of V _{AUX} regulator is above V _{AUX_OC} threshold.
RENT	Set / Reset condition	Set: Current above threshold for t >100 μ s. Reset: Current below threshold and flag read by SPI.
5 V _{-CAN} _	Description	Report that the 5 V-CAN regulator has reached overtemperature threshold.
THERMAL SHUTDOWN	Set / Reset condition	Set: 5 V-CAN thermal sensor above threshold. Reset: thermal sensor below threshold and flag read (SPI)
5V _{-CAN_UV}	Description	Reports that 5 V_CAN regulator output voltage is lower than the 5 V_CAN UV threshold.
	Set / Reset condition	Set: 5V-CAN below 5V-CAN UV for t >100 µs typically. Reset: 5V-CAN > threshold and flag read (SPI)
5V-can_	Description	Report that the CAN driver output current is above threshold.
overcurrent	Set / Reset condition	Set: 5V-CAN current above threshold for t>100 $\mu s.$ Reset: 5V-CAN current below threshold and flag read (SPI)
V _{SENSE} _	Description	Reports that VSENSE pin is lower than the V _{SENSE LOW} threshold.
LOW	Set / Reset condition	Set: VSENSE below threshold for t >100 μs typically. Reset: V_{SENSE} above threshold and flag read (SPI)
V _{SUP} _	Description	Reports that VSUP/1 pin is lower than the V _{S1_LOW} threshold.
underVOLTAGE	Set / Reset condition	Set: $V_{SUP/1}$ below threshold for t >100 μ s typically. Reset: $V_{SUP/1}$ above threshold and flag read (SPI)
I _{DD-OC-}	Description	Report that current out of VDD pin is higher that I _{DD-OC} threshold, while device is in Normal mode.
NORMAL MODE	Set / Reset condition	Set: current above threshold for t>100 μ s typically. Reset; current below threshold and flag read (SPI)
V _{DD} _	Description	Report that the V _{DD} has reached overtemperature threshold, and was turned off.
THERMAL SHUTDOWN	Set / Reset condition	Set: V_{DD} OFF due to thermal condition. Reset: V_{DD} recover and flag read (SPI)
R _{ST_LOW}	Description	Report that the RST pin has detected a low level, shorter than 100 ms
(<100 ms)	Set / Reset condition	Set: after detection of reset low pulse. Reset: Reset pulse terminated and flag read (SPI)
V _{SUP} _	Description	Report that the device voltage at VSUP/1 pin was below BATFAIL threshold.
BATFAIL	Set / Reset condition	Set: $V_{SUP/1}$ below BATFAIL. Reset: $V_{SUP/1}$ above threshold, and flag read (SPI)
$\begin{array}{l} I_{DD\text{-}OC\text{-}LP} \\ V_{DD}ON \text{ mode} \end{array}$	Description	Report that current out of VDD pin is higher that I_{DD-OC} threshold LP, while device is in LP V_{DD} ON mode.
	Set / Reset condition	Set: current above threshold for t>100 μ s typically. Reset; current below threshold and flag read (SPI)



	Flag	Description
CAN		
CAN driver	Description	Report real time CAN bus driver state: 1 if Driver is enable, 0 if driver disable
state	Set / Reset condition	Set: CAN driver is enable. Reset: CAN driver is disable. Driver can be disable by SPI command (ex CAN set in RXD only mode) or following a failure event (ex: TXD Dominant). Flag read SPI command (0x2180) do not clear the flag, as it is "real time" information.
CAN receiver	Description	Report real time CAN bus receiver state: 1 if Enable, 0 if disable
state	Set / Reset condition	Set: CAN bus receiver is enable. Reset: CAN bus receiver is disable. Receiver disable by SPI command (ex: CAN set in sleep mode). Flag read SPI command (0x2180) do not clear the flag, as it is "real time" information.
CAN WU	Description	Report real time CAN bus Wake-up receiver state: 1 if WU receiver is enable, 0 if disable
enable	Set / Reset condition	Set: CAN Wake-up receiver is enable. Reset: CAN Wake-up receiver is disable. Wake-up receiver is controlled by SPI, and is active by default after device Power ON. SPI command (0x2180) do not change flag state.
CAN	Description	Report that Wake-up source is CAN
Wake-up	Set / Reset condition	Set: after CAN wake detected. Reset: Flag read (SPI)
CAN	Description	Report that the CAN interface has reach overtemperature threshold.
Overtemp	Set / Reset condition	Set: CAN thermal sensor above threshold. Reset: thermal sensor below threshold and flag read (SPI)
RXD low ⁽⁴¹⁾	Description	Report that RXD pin is shorted to GND.
	Set / Reset condition	Set: RXD low failure detected. Reset: failure recovered and flag read (SPI)
Rxd high	Description	Report that RXD pin is shorted to recessive voltage.
	Set / Reset condition	Set: RXD high failure detected. Reset: failure recovered and flag read (SPI)
TXD dom	Description	Report that TXD pin is shorted to GND.
	Set / Reset condition	Set: TXD low failure detected. Reset: failure recovered and flag read (SPI)
Bus Dom	Description	Report that the CAN bus is dominant for a time longer than t _{DOM}
clamp	Set / Reset condition	Set: Bus dominant clamp failure detected. Reset: failure recovered and flag read (SPI)
CAN	Description	Report that the CAN current is above CAN overcurrent threshold.
Overcurrent	Set / Reset condition	Set: CAN current above threshold. Reset: current below threshold and flag read (SPI)
CAN_UF	Description	Report that the CAN failure detection has not yet identified the bus failure
	Set / Reset condition	Set: bus failure pre detection. Reset: CAN bus failure recovered and flag read
CAN_F	Description	Report that the CAN failure detection has identified the bus failure
	Set / Reset condition	Set: bus failure complete detetction.Reset: CAN bus failure recovered and flag read
CANL	Description	Report CAN L short to V _{BAT} failure
to V _{BAT}	Set / Reset condition	Set: failure detected. Reset failure recovered and flag read (SPI)
CANL to VDD	Description	Report CANL short to VDD
	Set / Reset condition	Set: failure detected. Reset failure recovered and flag read (SPI)
CANL to GND	Description	Report CAN L short to GND failure
	Set / Reset condition	Set: failure detected. Reset failure recovered and flag read (SPI)
CANH	Description	Report CAN H short to V _{BAT} failure
to V_{BAT}	Set / Reset condition	Set: failure detected. Reset failure recovered and flag read (SPI)
CANH to VDD	Description	Report CANH short to VDD
	Set / Reset condition	Set: failure detected. Reset failure recovered and flag read (SPI)
CANH to	Description	Report CAN H short to GND failure
GND	Set / Reset condition	Set: failure detected. Reset failure recovered and flag read (SPI)

Notes

41. Not available on "C" versions



	Flag	Description						
I/O								
HS3 short to	Description	Report I/O-3 HS switch short to GND failure						
GND	Set / Reset condition	Set: failure detected. Reset failure recovered and flag read (SPI)						
HS2 short to	Description	Report I/O-2 HS switch short to GND failure						
GND	Set / Reset condition	Set: failure detected. Reset failure recovered and flag read (SPI)						
SPI parity	Description	Report SPI parity error was detected.						
error	Set / Reset condition	Set: failure detected. Reset: flag read (SPI)						
CSB low	Description	Report SPI CSB was low for a time longer than typically 2.0 ms						
>2.0 ms	Set / Reset condition	Set: failure detected. Reset: flag read (SPI)						
V _{SUP/2-UV}	Description	Report that $V_{SUP/2}$ is below V_{S2_LOW} threshold.						
	Set / Reset condition	Set $V_{SUP/2}$ below V_{S2}_{LOW} thresh. Reset $V_{SUP/2} > V_{S2}_{LOW}$ thresh and flag read (SPI)						
V _{SUP/1-OV}	Description	Report that $V_{SUP/1}$ is above V_{S_HIGH} threshold.						
	Set / Reset condition	Set $V_{SUP/1}$ above $V_{S_{HIGH}}$ threshold. Reset $V_{SUP/1} < V_{S_{HIGH}}$ thresh and flag read (SPI)						
I/O-0 thermal	Description	Report that the I/O-0 HS switch has reach overtemperature threshold.						
	Set / Reset condition	Set: I/O-0 HS switch thermal sensor above threshold. Reset: thermal sensor below threshold and flag read (SPI)						
watchdog	Description	Report that the watchdog period has reach 50% of its value, while device is in Flash mode.						
flash mode 50%	Set / Reset condition	Set: watchdog period > 50%. Reset: flag read						
I/O-1-3 Wake-	Description	Report that Wake-up source is I/O-1 or I/O-3						
up	Set / Reset condition	Set: after I/O-1 or I/O-3 wake detected. Reset: Flag read (SPI)						
I/O-0-2 Wake-	Description	Report that Wake-up source is I/O-0 or I/O-2						
up	Set / Reset condition	Set: after I/O-0 or I/O-2 wake detected. Reset: Flag read (SPI)						
SPI Wake-up	Description	Report that Wake-up source is SPI command, in LP V _{DD} ON mode.						
	Set / Reset condition	Set: after SPI Wake-up detected. Reset: Flag read (SPI)						
FWU	Description	Report that Wake-up source is forced Wake-up						
	Set / Reset condition	Set: after Forced Wake-up detected. Reset: Flag read (SPI)						
INT service	Description	Report that INT timeout error detected.						
Timeout	Set / Reset condition	Set: INT service timeout expired. Reset: flag read.						
LPV_DDOFF	Description	Report that LP V _{DD} OFF mode was selected, prior Wake-up occurred.						
	Set / Reset condition	Set: LP V _{DD} OFF selected. Reset: Flag read (SPI)						
Reset request	Description	Report that RST source is an request from a SPI command (go to RST mode).						
	Set / Reset condition	Set: After reset occurred due to SPI request. Reset: flag read (SPI)						
Hardware Leave Debug	Description	Report that the device left the Debug mode due to hardware cause (voltage at DBG pin lower than typically 8.0 V).						
	Set / Reset condition	Set: device leave debug mode due to hardware cause. Reset: flag read.						
		I						



INT		·
INT request	Description	Report that INT source is an INT request from a SPI command.
	Set / Reset condition	Set: INT occurred. Reset: flag read (SPI)
RST high	Description	Report that RST pin is shorted to high voltage.
	Set / Reset condition	Set: RST failure detection. Reset: flag read.
DBG resistor	Description	Report that the resistor at DBG pin is different from expected (different from SPI register content).
	Set / Reset condition	Set: failure detected. Reset: correct resistor and flag read (SPI).
V _{DD TEMP PRE-}	Description	Report that the V _{DD} has reached overtemperature pre-warning threshold.
WARNING	Set / Reset condition	Set: V_{DD} thermal sensor above threshold. Reset: V_{DD} thermal sensor below threshold and flag read (SPI)
V _{DD UV}	Description	Reports that VDD pin is lower than the V _{DDUV} threshold.
	Set / Reset condition	Set: VDD below threshold for t >100 μ s typically. Reset: V _{DD} above threshold and flag read (SPI)
V _{DD} overVOLTAGE	Description	Reports that VDD pin is higher than the typically V_{DD} + 0.6 V threshold. I/O-1 can be turned OFF if this function is selected in INIT register.
	Set / Reset condition	Set: VDD above threshold for t >100 μ s typically. Reset: V _{DD} below threshold and flag read (SPI)
V _{AUX_overVOL} TAGE	Description	Reports that VAUX pin is higher than the typically V_{AUX} + 0.6 V threshold. I/O-1 can be turned OFF if this function is selected in INIT register.
	Set / Reset condition	Set: V_{AUX} above threshold for t >100 μ s typically. Reset: V_{AUX} below threshold and flag read (SPI)
V _{DD LOW}	Description	Reports that VDD pin is lower than the VDD_{UV} threshold for a time longer than 100 ms
>100 ms	Set / Reset condition	Set: VDD below threshold for t >100 ms typically. Reset: V _{DD} above threshold and flag read (SPI)
V _{DD LOW}	Description	Report that V _{DD} is below V _{DD} undervoltage threshold.
	Set / Reset condition	Set: V _{DD} below threshold. Reset: fag read (SPI)
$V_{DD}(5.0$ V or	Description	0: mean 3.3 V V _{DD} version
3.3 V)		1: mean 5.0 V V _D D version
	Set / Reset condition	N/A
Device P/N1	Description	Describe the device part number:
and 0		00: MC34903
		01: MC34904
		10: MC34905S
		11: MC343905D
	Set / Reset condition	N/A
Device id 4 to 0	Description	Describe the silicon revision number
0		10010: silicon revision A (Pass 3.1)
		10011: silicon revision B (Pass 3.2)
	Sat / Depart condition	10100: silicon revision C (Pass 3.3)
RST low	Set / Reset condition Description	N/A
>100 ms	•	Report that the RST pin has detected a low level, longer than 100 ms (Reset permanent low)
	Set / Reset condition	Set: after detection of reset low pulse. Reset: Reset pulse terminated and flag read (SPI)
Multiple Resets	Description	Report that the more than 8 consecutive reset pulses occurred, due to missing or wrong watchdog refresh.
	Set / Reset condition	Set: after detection of multiple reset pulses. Reset: flag read (SPI)
watchdog refresh failure	Description	Report that a wrong or missing watchdog failure occurred.
	Set / Reset condition	Set: failure detected. reset: flag read (SPI)



LIN/1 State Description Report real time LIN interface TXD/RXD RXD mode. Set / Reset condition Set: LIN in TXD RXD mode. Reset: LIN in command (ex LIN set in Sleep mode) or for command (0x2780) do not clear it, as it is LIN/1 WU Description Report real time LIN Wake-up receiver state (means LIN signal will not be detected ar Set / Reset condition Set: LIN WU enable (LIN interface set in State)	
dom clamp Set / Reset condition Set: Bus dominant clamp failure detected LIN/1 State Description Report real time LIN interface TXD/RXD in RXD mode. Set / Reset condition Set: LIN in TXD RXD mode. Reset: LIN in command (ex LIN set in Sleep mode) or factor and (0x2780) do not clear it, as it is command (0x2780) do not	
LIN/1 State Description Report real time LIN interface TXD/RXD in RXD mode. Set / Reset condition Set: LIN in TXD RXD mode. Set / Reset condition Set: LIN in TXD RXD mode. Reset: LIN in command (ex LIN set in Sleep mode) or the command (ox2780) do not clear it, as it is command (0x2780) do not clear it, as it is (means LIN signal will not be detected and the flag, as it is "real time" information. LIN/1 Description Set: LIN WU enable (LIN interface set in Sleep mode) or the flag, as it is "real time" information. LIN/1 Description Report real time LIN Wake-up receiver state (means LIN signal will not be detected and the flag, as it is "real time" information.	a time longer than t _{DOM}
RXD mode. Set / Reset condition Set: LIN in TXD RXD mode. Reset: LIN in command (ex LIN set in Sleep mode) or in command (ex LIN set in Sleep mode) or in command (0x2780) do not clear it, as it is LIN/1 WU Description Report real time LIN Wake-up receiver static (means LIN signal will not be detected and Set / Reset condition) Set / Reset condition Set: LIN WU enable (LIN interface set in Sleep mode Wake-up the flag, as it is "real time" information. LIN/1 Description	I. Reset: failure recovered and flag read (SPI)
LIN/1 WU Description Report real time LIN Wake-up receiver structure (means LIN signal will not be detected and Set / Reset condition) Set / Reset condition Set: LIN WU enable (LIN interface set in Sleep mode Wake-up the flag, as it is "real time" information. LIN/1 Description	mode. 1 if LIN is in TXD/RXD mode. 0 is LIN is not in TXD/
Set / Reset condition Set: LIN WU enable (LIN interface set in S (LIN interface set in Sleep mode Wake-u) the flag, as it is "real time" information. LIN/1 Description Report that Wake-up source is LIN/1	not in TXD/RXD mode. LIN not in TXD/RXD mode by SPI following a failure event (ex: TxL Dominant). Flag read SPI s "real time" flag.
LIN/1 Description Report that Wake-up source is LIN/1	ate. 1 if LIN Wake-up is enable, 0 if LIN Wake-up is disable ad will not Wake-up the device).
	Sleep mode Wake-up enable). Reset: LIN Wake-up disable p disable). Flag read SPI command (0x2780) do not clear
Wake-up Set / Poset condition Set: after LIN/1 wake detected Poset: El	
Set / Reset condition Set. after Ein/1 wake delected. Reset. In	ag read (SPI)
LIN/1 Term Description Report LIN/1 short to GND failure	
short to GND Set / Reset condition Set: failure detected. Reset failure recover	ered and flag read (SPI)
LIN/1 Description Report that the LIN/1 interface has reach	overtemperature threshold.
Overtemp Set / Reset condition Set: LIN/1 thermal sensor above threshold	ld. Reset: sensor below threshold and flag read (SPI)
RXD-L/1 low Description Report that RXD/1 pin is shorted to GND	
Set / Reset condition Set: RXD low failure detected. Reset: fail	ure recovered and flag read (SPI)
RXD-L/1 high Description Report that RXD/1 pin is shorted to reces	ssive voltage.
Set / Reset condition Set: RXD high failure detected. Reset: fail	ilure recovered and flag read (SPI)
TXD-L/1 dom Description Report that TXD/1 pin is shorted to GND.	
Set / Reset condition Set: TXD low failure detected. Reset: failure	ure recovered and flag read (SPI)



FIX AND EXTENDED DEVICE STATUS

For every SPI command, the device response on MISO is fixed status information. This information is either:

12

11

10

9

Two Bytes

15

Bits

Fix Status + Extended Status: when a device write command is used (MOSI bits 15-14, bits C1 C0 = 01)

13

Table 40. Status Bits Description 14

One Byte

7

6

5

Fix Status: when a device read operation is performed (MOSI bits 15-14, bits C1 C0 = 00 or 11).

4

3

2

1

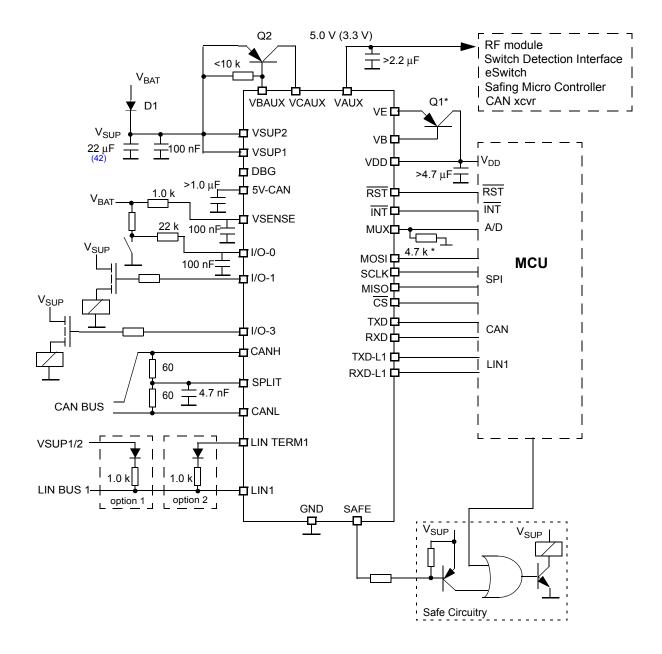
0

MISO	INT	WU	RST	CAN-G	LIN-G	I/O-G	SAFE-G	VREG-G	CAN-BUS	CAN-LOC	0	LIN1	I/O-1	I/O-0	VREG-1	VREG-0
			1.01	0/110		1/0 0	0,120	11120 0	0, 11 200	0,11 200	Ů	2			THEO I	111200
E	Bits		Description													
INT		In	Indicates that an INT has occurred and that INT flags are pending to be read.													
WU		In	Indicates that a Wake-up has occurred and that Wake-up flags are pending to be read.													
F	RST		Indicates that a reset has occurred and that the flags that report the reset source are pending to be read.													
CA	CAN-G		The INT, WU, or RST source is CAN interface. CAN local or CAN bus source.													
LI	LIN-G		The INT, WU, or RST source is LIN1 interface													
1/	I/O-G		The INT, WU, or RST source is I/O interfaces.													
SAFE-G		Tł	The INT, WU, or RST source is from a SAFE condition													
VREG-G		Tł	The INT, WU, or RST source is from a Regulator event, or voltage monitoring event													
CAN-LOC		Tł	The INT, WU, or RST source is CAN interface. CAN local source.													
CAN-BUS The INT, WU, or RST source is CAN interface. CAN bus source.																
LIN	/LIN1	The INT, WU, or RST source is LIN1 interface														
۱/	I/O-0 The INT, WU, or RST source is I/O interface, flag from I/O sub adress Low (bit 7 = 0)															
1/	0-1	Tł	The INT, WU, or RST source is I/O interface, flag from I/O sub adress High (bit 7 = 1)													
VREG-1 The INT, WU, or RST source is from a Regulator event, flag from REG register sub adress high (bit 7 =				: 1)												
VREG-0 The INT, WU, or RST source is from a Regulator event, flag from REG register sub adress low (bit 7 = 0)					0)											

8



TYPICAL APPLICATIONS

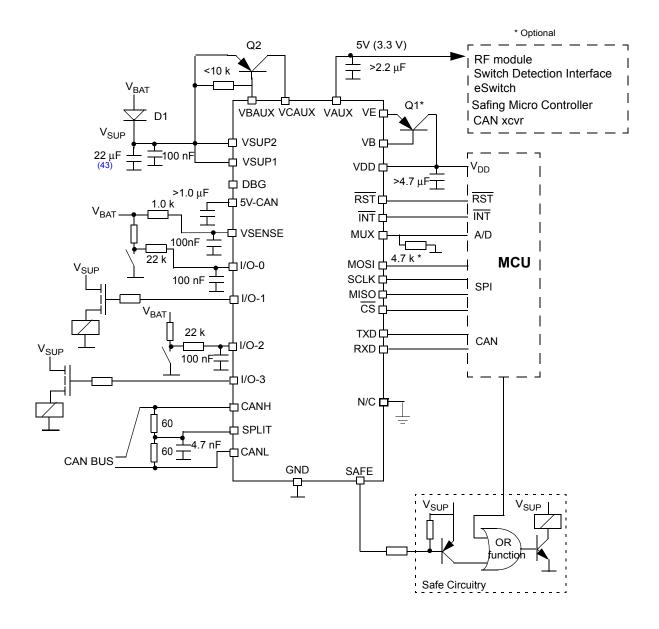


Notes

42. Tested per specific OEM EMC requirements for CAN and LIN with additional capacitor > 10 μF on VSUP1/VSUP2 pins

Figure 38. 34905S Typical Application Schematic



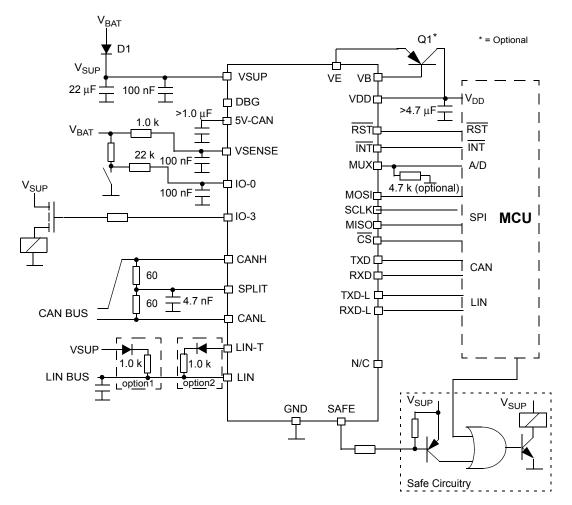


Notes

43. Tested per specific OEM EMC requirements for CAN and LIN with additional capacitor > 10 μ F on VSUP1/VSUP2 pins

Figure 39. 34904 Typical Application Schematic



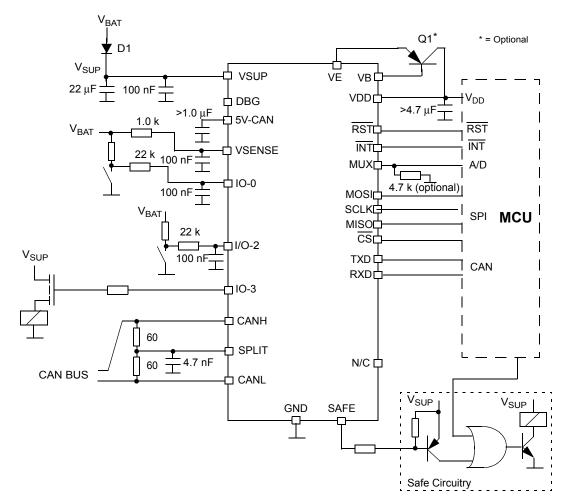


Notes

- 44. Tested per specific OEM EMC requirements for CAN and LIN with additional capacitor > 10 μF on VSUP pin
- 45. Leave N/C pins open.

Figure 40. 34903S Typical Application Schematic





Notes

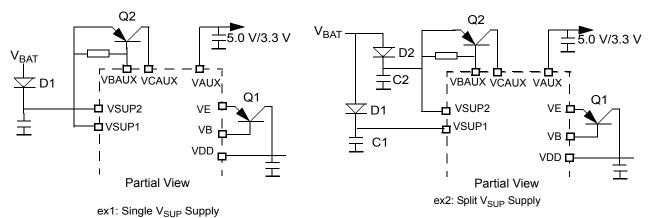
- 46. Tested per specific OEM EMC requirements for CAN and LIN with additional capacitor > 10 μF on VSUP pin
- 47. Leave N/C pins open.

Figure 41. 34903P Typical Application Schematic

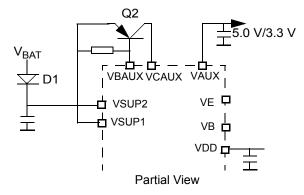


The following figure illustrates the application case where two reverse battery diodes can be used for optimization of the filtering and buffering capacitor at the VDD pin. This allows using a minimum value capacitor at the VDD pin to guarantee reset-free operation of the MCU during the cranking pulse and temporary (50 ms) loss of the V_{BAT} supply.

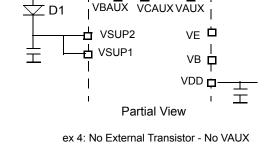
Applications without an external ballast on V_{DD} and without using the VAUX regulator are illustrated as well.



Optimized solution for cranking pulses. C1 is sized for MCU power supply buffer only.



ex 3: No External Transistor, V_{DD} ~100 mA Capability delivered by internal path transistor.



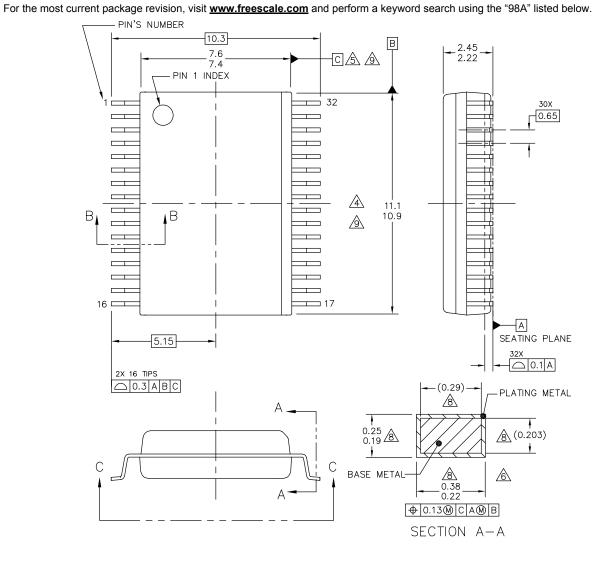


V_{BAT}



PACKAGING

SOIC 32 PACKAGE DIMENSIONS

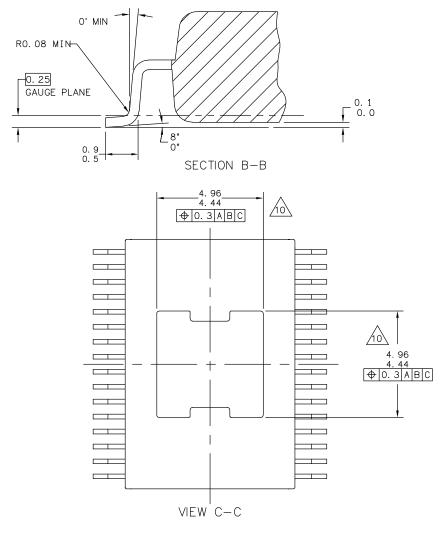


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TITLE: 32LD SOIC W/B, 0.6	5 PITCH	DOCUMENT NO	: 98ASA10556D	REV: D		
4.7 X 4.7 EXPOSE		CASE NUMBER	2: 1454–04	20 JUN 2008		
CASE-OUTLIN	NE	STANDARD: NON-JEDEC				

EK SUFFIX (PB-FREE) 32-PIN SOIC WIDE BODY EXPOSED PAD 98ASA10556D REVISION D

34903/4/5





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TITLE: 32LD SOIC W/B, 0.6	5 PITCH	DOCUMENT NO	: 98ASA10556D	REV: D		
4.7 X 4.7 EXPOSE		CASE NUMBER	8: 1454–04	20 JUN 2008		
CASE-OUTLIN	١E	STANDARD: NON-JEDEC				

EK SUFFIX (PB-FREE) 32-PIN SOIC WIDE BODY EXPOSED PAD 98ASA10556D REVISION D



NOTES:

- 1. DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 3. DATUMS B AND C TO BE DETERMINED AT THE PLANE WHERE THE BOTTOM OF THE LEADS EXIT THE PLASTIC BODY.
- THIS DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURRS. MOLD FLASH, PROTRUSION OR GATE BURRS SHALL NOT EXCEED 0.15 MM PER SIDE. THIS DIMENSION IS DETERMINED AT THE PLANE WHERE THE BOTTOM OF THE LEADS EXIT /4. THE PLASTIC BODY.
- 5. THIS DIMENSION DOES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSIONS. INTER-LEAD FLASH AND PROTRUSIONS SHALL NOT EXCEED 0.25 MM PER SIDE. THIS DIMENSION IS DETERMINED AT THE PLANE WHERE THE BOTTOM OF THE LEADS EXIT THE PLASTIC BODY.
- 6. THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED 0.4 mm. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD SHALL NOT LESS THAN 0.07 mm.

- 7. EXACT SHAPE OF EACH CORNER IS OPTIONAL.
- /8.\ THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10 mm AND 0.3 mm FROM THE LEAD TIP.
- THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM. THIS DIMENSION IS DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTER-LEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY. /9.
- 10. THESE DIMENSION RANGES DEFINE THE PRIMARY KEEP-OUT AREA. MOLD LOCKING AND RESIN BLEED CONTROL FEATURES MAY BE VISIBLE AND THEY MAY EXTEND TO 0.34mm FROM MAXIMUM EXPOSED PAD SIZE

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4.7 X 4.7 EXPOSE		CASE NUMBER	8: 1454–04	20 JUN 2008		
CASE-OUTLIN	νE	STANDARD: NON-JEDEC				

EK SUFFIX (PB-FREE)
32-PIN SOIC WIDE BODY
EXPOSED PAD
98ASA10556D
REVISION D



REVISION HISTORY

REVISION	DATE	DESCRIPTION OF CHANGES
1.0	7/2013	Initial Release based on the the MC33903_4_5 data sheet
2.0	8/2013	 Update T_A for industrial market applications. Corrected document title
3.0	9/2013	Added Applications to page oneCorrected blank fields.
4.0	10/2013	 Upgraded temperature to 125 °C to support additional industrial applications.





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